# S29GL-M MirrorBit<sup>™</sup> Flash Family S29GL256M, S29GL128M, S29GL064M, S29GL032M



256 Megabit, 128 Megabit, 64 Megabit, and 32 Megabit, 3.0 Volt-only Page Mode Flash Memory featuring 0.23 µm MirrorBit Process Technology

**Data Sheet** 

This product family has been retired and is not recommended for designs. For new and current designs, S29GL032A, S29GL064A, S29GL128P, and S29GL256P supersede S29GL032M, S29GL064M, S29GL128M, and S29GL256M respectively. These are the factory-recommended migration paths. Please refer to the S29GL-A and S29GL-P Datasheets for specifications and ordering information. Availability of this document is retained for reference and historical purposes only.

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### **Distinctive Characteristics**

### **Architectural Advantages**

### ■ Single power supply operation

- 3 volt read, erase, and program operations
- Manufactured on 0.23 µm MirrorBit process technology

### Secured Silicon Sector region

- 128-word/256-byte sector for permanent, secure identification through an 8-word/16-byte random Electronic Serial Number, accessible through a command sequence
- May be programmed and locked at the factory or by the customer

### ■ Flexible sector architecture

- 256 Mb: 512 32-Kword (64 Kbyte) sectors
- 128 Mb: 256 32-Kword (64 Kbyte) sectors
- 64 Mb (uniform sector models): 128 32-Kword (64-Kbyte) sectors or 128 32 Kword sectors
- 64 Mb (boot sector models): 127 32-Kword
   (64-Kbyte) sectors + 8 4Kword (8Kbyte) boot sectors
- 32 Mb (uniform sector models): 64 32-Kword (64-Kbyte) sectors of 64 32-Kword sectors
- 32 Mb (boot sector models): 63 32-Kword (64 Kbyte) sectors + 8 4-Kword (8-Kbyte) boot sectors

#### ■ Compatibility with JEDEC standards

- Provides pinout and software compatibility for singlepower supply flash, and superior inadvertent write protection
- 100,000 erase cycles typical per sector
- 20-year data retention typical

### **Performance Characteristics**

### ■ High performance

- 90 ns access time (128 Mb, 64 Mb, 32 Mb), 100 ns access time (256 Mb)
- 4-word/8-byte page read buffer
- 25 ns page read times (128 Mb, 64 Mb, 32 Mb)
- 30 ns page read times (256 Mb)
- 16-word/32-byte write buffer

- 16-word/32-byte write buffer reduces overall programming time for multiple-word updates
- Low power consumption (typical values at 3.0 V, 5 MHz)
  - 18 mA typical active read current (64 Mb, 32 Mb)
  - 25 mA typical active read current (256 Mb, 128 Mb)
  - 50 mA typical erase/program current
  - 1 μA typical standby mode current

### Package options

- 40-pin TSOP
- 48-pin TSOP
- 56-pin TSOP
- 64-ball Fortified BGA
- 48-ball fine-pitch BGA
- 63-ball fine-pitch BGA

#### Software & Hardware Features

### ■ Software features

- Program Suspend & Resume: read other sectors before programming operation is completed
- Erase Suspend & Resume: read/program other sectors before an erase operation is completed
- Data# polling & toggle bits provide status
- CFI (Common Flash Interface) compliant: allows host system to identify and accommodate multiple flash devices
- Unlock Bypass Program command reduces overall multiple-word programming time

### ■ Hardware features

- Sector Group Protection: hardware-level method of preventing write operations within a sector group
- Temporary Sector Unprotect: V<sub>ID</sub>-level method of charging code in locked sectors
- WP#/ACC input accelerates programming time (when high voltage is applied) for greater throughput during system production. Protects first or last sector regardless of sector protection settings on uniform sector models
- Hardware reset input (RESET#) resets device
- Ready/Busy# output (RY/BY#) detects program or erase cycle completion



# **General Description**

The S29GL256/128/064/032M family of devices are 3.0 V single power Flash memory manufactured using 0.23  $\mu$ m MirrorBit technology. The S29GL256M is a 256†Mbit, organized as 16,777,216 words or 33,554,432 bytes. The S29GL128M is a 128 Mbit, organized as 8,388,608 words or 16,777,216 bytes. The S29GL064M is a 64 Mbit, organized as 4,194,304 words or 8,388,608 bytes. The S29GL032M is a 32 Mbit, organized as 2,097,152 words or 4,194,304 bytes. Depending on the model number, the devices have an 8-bit wide data bus only, 16-bit wide data bus only, or a 16-bit wide data bus that can also function as an 8-bit wide data bus by using the BYTE# input. The devices can be programmed either in the host system or in standard EPROM programmers.

Access times as fast as 90 ns (S29GL128M, S29GL064M, S29GL032M) or 100 ns (S29GL256M) are available. Note that each access time has a specific operating voltage range ( $V_{CC}$ ) as specified in Product Selector Guide and the Ordering Information sections starting on page 16. Package offerings include 40-pin TSOP, 48-pin TSOP, 56-pin TSOP, 48-ball fine-pitch BGA, 63-ball fine-pitch BGA and 64-ball Fortified BGA, depending on model number. Each device has separate chip enable (CE#), write enable (CE#) and output enable (CE#) controls.

Each device requires only a **single 3.0 volt power supply** for both read and write functions. In addition to a  $V_{CC}$  input, a high-voltage **accelerated program (ACC)** feature provides shorter programming times through increased current on the WP#/ACC input. This feature is intended to facilitate factory throughput during system production, but may also be used in the field if desired.

The device is entirely command set compatible with the **JEDEC single-power-supply Flash standard**. Commands are written to the device using standard microprocessor write timing. Write cycles also internally latch addresses and data needed for the programming and erase operations.

The **sector erase architecture** allows memory sectors to be erased and reprogrammed without affecting the data contents of other sectors. The device is fully erased when shipped from the factory.

Device programming and erasure are initiated through command sequences. Once a program or erase operation starts, the host system need only poll the DQ7 (Data# Polling) or DQ6 (toggle) **status bits** or monitor the **Ready/Busy# (RY/BY#)** output to determine whether the operation is complete. To facilitate programming, an **Unlock Bypass** mode reduces command sequence overhead by requiring only two write cycles to program data instead of four.

**Hardware data protection** measures include a low  $V_{CC}$  detector that automatically inhibits write operations during power transitions. The hardware sector protection feature disables both program and erase operations in any combination of sectors of memory. This can be achieved in-system or via programming equipment.

The **Erase Suspend/Erase Resume** feature allows the host system to pause an erase operation in a given sector to read or program any other sector and then complete the erase operation. The **Program Suspend/Program Resume** feature enables the host system to pause a program operation in a given sector to read any other sector and then complete the program operation.

The **hardware RESET# pin** terminates any operation in progress and resets the device, after which it is then ready for a new operation. The RESET# pin may be tied to the system reset circuitry. A system reset would thus also reset the device, enabling the host system to read boot-up firmware from the Flash memory device.

The device reduces power consumption in the **standby mode** when it detects specific voltage levels on CE# and RESET#, or when addresses are stable for a specified period of time.

The **Write Protect (WP#)** feature protects the first or last sector by asserting a logic low on the WP#/ACC pin or WP# pin, depending on model number. The protected sector is still protected even during accelerated programming.

The **Secured Silicon Sector** provides a 128-word/256-byte area for code or data that can be permanently protected. Once this sector is protected, no further changes within the sector can occur. Spansion MirrorBit flash technology combines years of Flash memory manufacturing experience to produce the highest levels of quality, reliability and cost effectiveness. The device electrically erases all bits within a sector simultaneously via hot-hole assisted erase. The data is programmed using hot electron injection.



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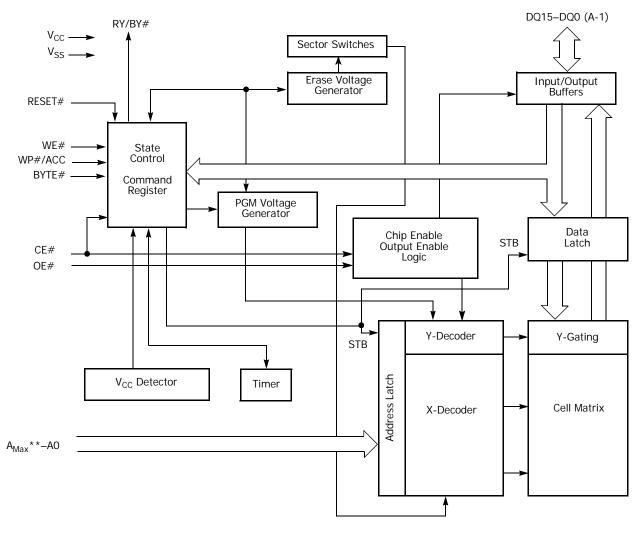
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# **Product Selector Guide**

Part Number	S29GL256M		S29GL128M		S29GL064M			S29GL032M		
Speed Option	10	11	90	10	90	10	11	90	10	11
Max. Access Time (ns)	100	110	90	100	90	100	110	90	100	110
Max. CE# Access Time (ns)	100	110	90	100	90	100	110	90	100	110
Max. Page Access Time (ns)	30	30	25	30	25	30	30	25	30	30
Max. OE# Access Time (ns)	30	30	25	30	25	30	30	25	30	30

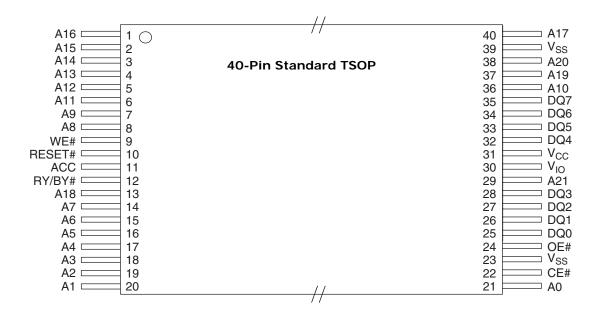
# **Block Diagram**

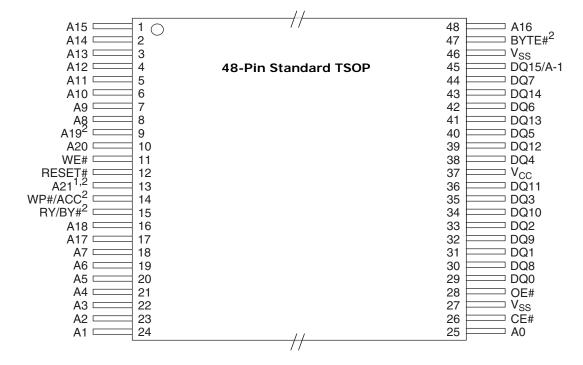


<sup>\*\*</sup>  $A_{Max}$ : GL256M = A23, GL128M = A22, GL064M = A21 (GL064M-00 = A22), GL032M = A20 (GL032M-00 = A21)



# **Connection Diagrams**



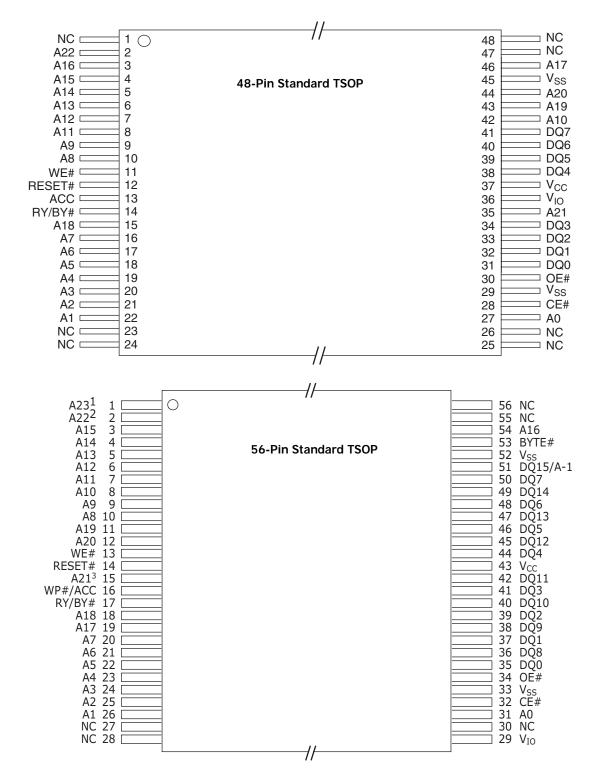


### Notes:

- 1. Pin 13 is NC on S29GL032M.
- 2. Pin 9 is A21, Pin 13 is ACC, Pin 14 is WP#, Pin 15 is A19, and Pin 47 is  $V_{IO}$  on S29GL064M (models R6, R7).



# For S29GL064M (model R0) only



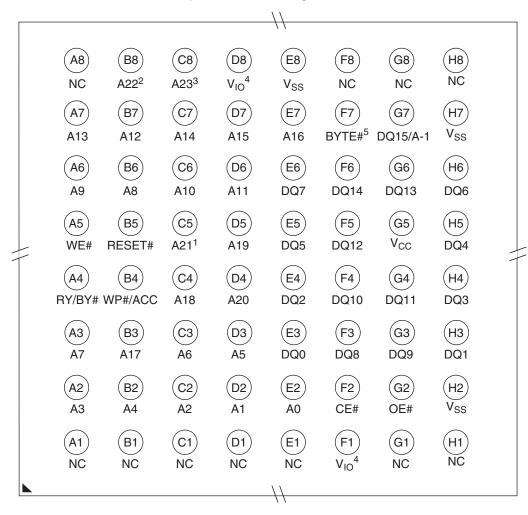
#### Notes:

- Pin 1 is NC on S29GL128M, 29GL064M, and S29GL032M.
- 2. Pin 2 is NC on S29GL064M, and S29GL032M.
- 3. Pin 15 is NC on S29GL032M.



### 64-ball Fortified BGA

Top View, Balls Facing Down

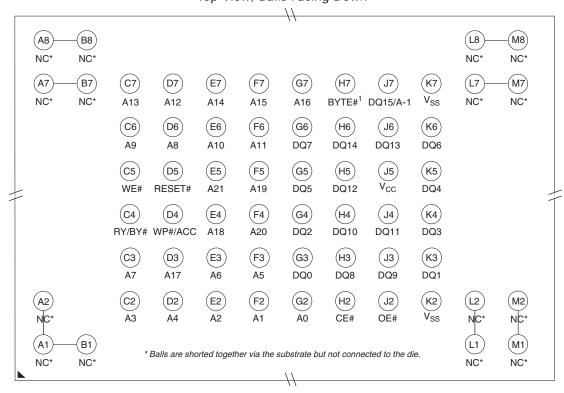


#### Notes:

- 1. Ball C5 is NC on S29GL032M.
- 2. Ball B8 is NC on S29GL064M and S29GL032M.
- 3. Ball C8 is NC on S29GL128M, S29GL064M and S29GL032M.
- 4. Ball D8 and Ball F1 are NC on S29GL064M (models R3, R4) and S29GL032M (models R3, R4, R5, R6).
- 5. Ball F7 is NC on S29GL064M (model R5).



# **63-Ball Fine-Pitch BGA**Top View, Balls Facing Down



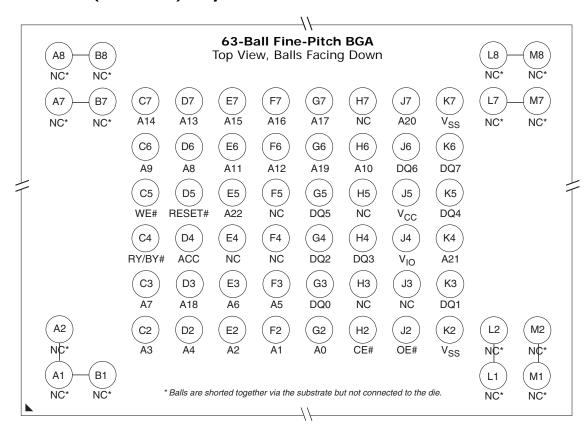
Note: Ball H7 is  $V_{IO}$  on S29GL064M (model R5).

# **Special Package Handling Instructions**

Special handling is required for Flash Memory products in molded packages (TSOP and BGA). The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.



# For S29GL064M (model R0) only



# **Special Package Handling Instructions**

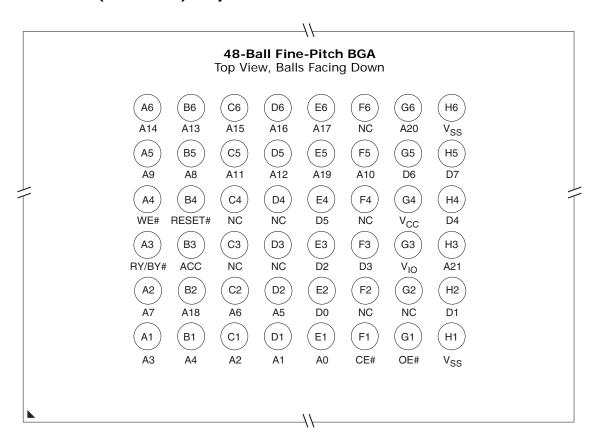
Special handling is required for Flash Memory products in molded packages (TSOP and BGA). The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.



			<b>ball Fin</b> ew, Bal			n		
(A6) A13	(B6) A12	(C6) A14	D6 A15	E6) A16	F6) BYTE#	G6) DQ15/A-1	H6) V <sub>SS</sub>	
(A5) A9	(B5) A8	C5 A10	D5)	E5 DQ7	(F5) DQ14	(G5) DQ13	H5 DQ6	
(A4) WE#	B4 RESET#	C4 NC	D4 A19	E4 DQ5	F4 DQ12	G4) V <sub>CC</sub>	H4) DQ4	
A3 RY/BY#	B3 WP#/ACC	C3 A18	D3 A20	E3 DQ2	F3 DQ10	(G3) DQ11	H3 DQ3	
(A2) A7	B2 A17	C2 A6	D2 A5	E2 DQ0	F2 DQ8	G2 DQ9	H2 DQ1	
(A1) A3	B1 A4	(C1) A2	D1 A1	E1 A0	F1 CE#	G1 OE#	H1 V <sub>SS</sub>	



# For S29GL032M (model R0) only



# **Special Package Handling Instructions**

Special handling is required for Flash Memory products in moulded packages (TSOP and BGA). The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.



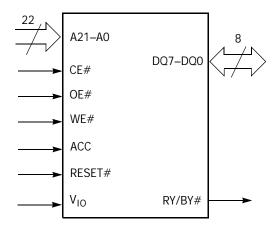
# **Pin Description**

A23-A0	=	24 Address inputs
A22-A0	=	23 Address inputs
A21-A0	=	22 Address inputs
A20-A0	=	21 Address inputs
DQ7-DQ0	=	8 Data inputs/outputs
DQ14-DQ0	=	15 Data inputs/outputs
DQ15/A-1	=	DQ15 (Data input/output, word mode), A-1 (LSB
		Address input, byte mode)
CE#	=	Chip Enable input
OE#	=	Output Enable input
WE#	=	Write Enable input
WP#/ACC	=	Hardware Write Protect input/Programming
		Acceleration input
ACC	=	Acceleration input
WP#	=	Hardware Write Protect input
RESET#	=	Hardware Reset Pin input
RY/BY#	=	Ready/Busy output
BYTE#	=	Selects 8-bit or 16-bit mode
$V_{CC}$	=	3.0 volt-only single power supply
		(see Product Selector Guide for speed options and
		voltage supply tolerances)
$V_{SS}$	=	Device Ground
NC	=	Pin Not Connected Internally
$V_{IO}$	=	Output Buffer Power

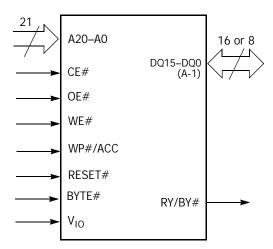


# **Logic Symbols**

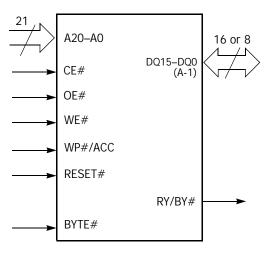
# S29GL032M (Model R0)



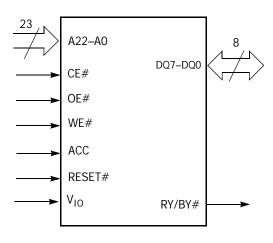
# S29GL032M (Models RI, R2)



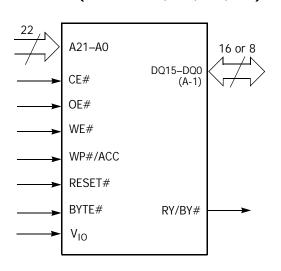
# S29GL032M (Models R3, R4)



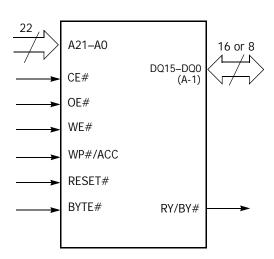
# S29GL064M (Model R0)



# **S29GL064M (Models RI, R2, R8, R9)**



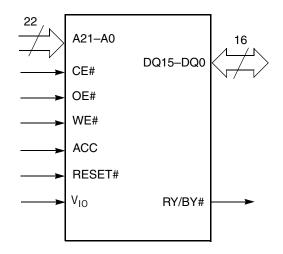
# S29GL064M (Models R3, R4)



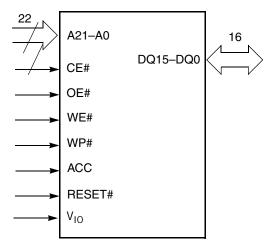


# **Logic Symbols**

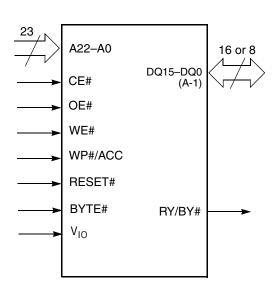
# S29GL064M (Model R5)



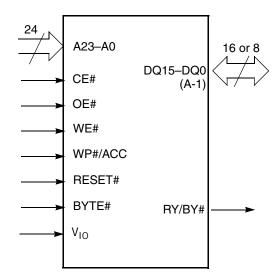
# **\$29GL064M (Model R6, R7)**



### **S29GLI28M**



### S29GL256M



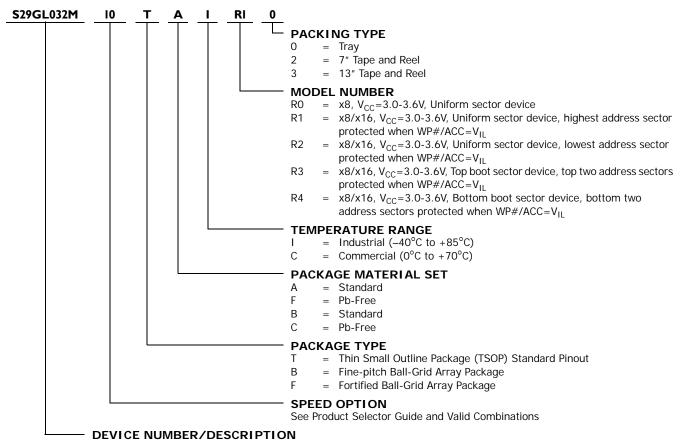


# Ordering Information: S29GL032M

This product has been retired and is not recommended for designs. For new and current designs, S29GL032A supersedes S29GL032M, and is the factory-recommended migration path. Please refer to the S29GL-A Datasheet for specifications and ordering information.

### S29GL032M Standard Products

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



S29GL032M 32 Megabit Page-Mode Flash Memory Manufactured using 0.23 µm MirrorBit™ Process Technology, 3.0 Volt-only Read, Program, and Erase



Table I. S29GL032M Ordering Options

	S2	Deelee De				
Device Number	Speed Option	Package, Material, & Temperature Range	Packing Type	Package De (Note		
		TAC,TFC	D0		TS040 (2, 3, 5)	TSOP
		BAC,BFC	R0		FBC048 (4)	Fine-Pitch BGA
		TAC,TFC	D4 D2		TS056 (2, 3, 5)	TSOP
	90	FAC,FFC	R1,R2		LAA064 (4)	Fortified BGA
		TAC,TFC			TS048 (2, 3, 5)	TSOP
		BAC,BFC	R3,R4		FBC048 (4)	Fine-Pitch BGA
		FAC,FFC			LAA064 (4)	Fortified BGA
S29GL032M		TAI,TFI	RO	0,2,3 (Note 1)	TS040 (2, 3, 5)	TSOP
		BAI,BFI	RU		FBC048 (4)	Fine-Pitch BGA
		TAI,TFI	D4 D2		TS056 (2, 3, 5)	TSOP
	00 10 11	FAI,FFI	R1,R2		LAA064 (4)	Fortified BGA
	90, 10, 11	TAI,TFI			TS048 (2, 3, 5)	TSOP
		BAI,BFI	D2 D4		FBC048 (4)	Fine-Pitch BGA
		FAI,FFI	R3,R4		LAA064 (4)	Fortified BGA
		TBI,TCI			FPT-48P-M19 (3, 6)	TSOP

#### Notes:

- 1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.
- 2. This package is recommended for new designs using TSOPs.
- 3. TSOP package marking omits packing type designator from the ordering part number.
- 4. BGA package marking omits leading "S29" and packing type designator from the ordering part number.
- 5. 100% Matte Sn is used for Pb-free TSOP plating.
- 6. SnBi is used for Pb-free TSOP plating.

### **Valid Combinations**

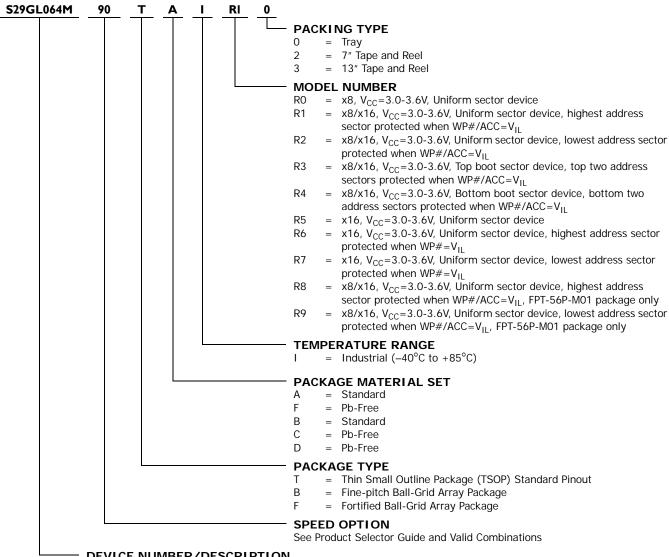


# **Ordering Information: S29GL064M**

This product has been retired and is not recommended for designs. For new and current designs, S29GL064A supersedes S29GL064M, and is the factory-recommended migration path. Please refer to the S29GL-A Datasheet for specifications and ordering information.

### S29GL064M Standard Products

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



**DEVICE NUMBER/DESCRIPTION** 

64 Megabit Page-Mode Flash Memory Manufactured using 0.23 um MirrorBit™ Process Technology, 3.0 Volt-only Read, Program, and Erase



Table 2. S29GL064M Ordering Options

		Package Description							
Device Number					(Notes				
		TAL TEL	R0,R3,R4,R6,R7		TS048 (2, 3, 5)				
		TAI, TFI	R1,R2		TS056 (2, 3, 5)	TCOD			
C20CL 07 4M	90, 10, 11	90, 10, 11	90, 10, 11	90, 10, 11	TBI, TCI	R2,R7 0,2,3		FPT-48P-M19 (3, 6)	TSOP
S29GL064M					90, 10, 11	90, 10, 11	90, 10, 11	TAI, TDI	R9
		BAI, BFI	R0,R3,R4,R5		FBE063 (4, 6)	Fine-Pitch BGA			
		FAI, FFI	R1,R2,R3,R4,R5		LAA064 (4)	Fortified BGA			

#### Notes:

- 1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.
- 2. This package is recommended for new designs using TSOPs.
- 3. TSOP package marking omits packing type designator from the ordering part number.
- 4. BGA package marking omits leading "S29" and packing type designator from the ordering part number.
- 5. 100% Matte Sn is used for Pb-free TSOP plating.
- 6. SnBi is used for Pb-free TSOP plating.

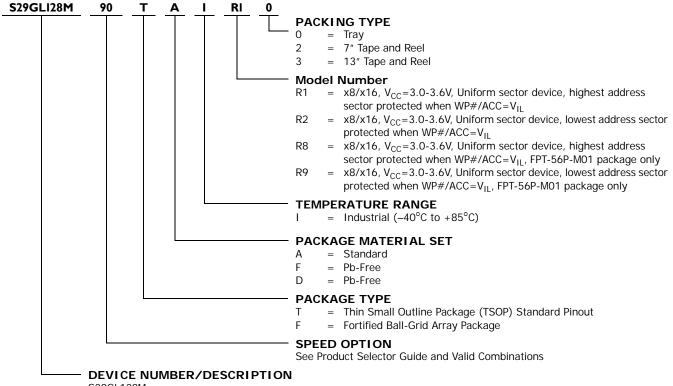
### **Valid Combinations**



# **Ordering Information: S29GLI28M**

This product has been retired and is not recommended for designs. For new and current designs, S29GL128P supersedes S29GL128M, and is the factory-recommended migration path. Please refer to the S29GL-P Datasheet for specifications and ordering information.

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



S29GL128M

128 Megabit Page-Mode Flash Memory Manufactured using 0.23 µm MirrorBit™ Process Technology, 3.0 Volt-only Read, Program, and Erase

Table 3. S29GLI28M Ordering Options

	S29GL128M Valid Combinations									
Base Ordering Part Number						riptions )				
	90, 10, 11 (Note 7)	TAI, TFI	R1, R2		TS056 (2, 3, 5)	TCOD				
S29GL128M		70, 10, 11 (Note 7) TAI, TDI R9 0, 2		0, 2, 3 (Note 1)	FPT-56P-M01 (3, 6)	TSOP				
		FAI, FFI	R1, R2		LAA064 (4)	Fortified-BGA				

#### Notes:

- 1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.
- 2. This package is recommended for new designs using TSOPs.
- 3. TSOP package marking omits packing type designator from the ordering part number.
- 4. BGA package marking omits leading "S29" and packing type designator from the ordering part number.
- 5. 100% Matte Sn is used for Pb-free TSOP plating.
- 6. SnBi is used for Pb-free TSOP plating.
- 7. Contact your Spansion representative for availability of the 90ns speed option for LAA064.

### **Valid Combinations**



# **Ordering Information: S29GL256M**

This product has been retired and is not recommended for designs. For new and current designs, S29GL256P supersedes S29GL256M, and is the factory-recommended migration path. Please refer to the S29GL-P Datasheet for specifications and ordering information.

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:

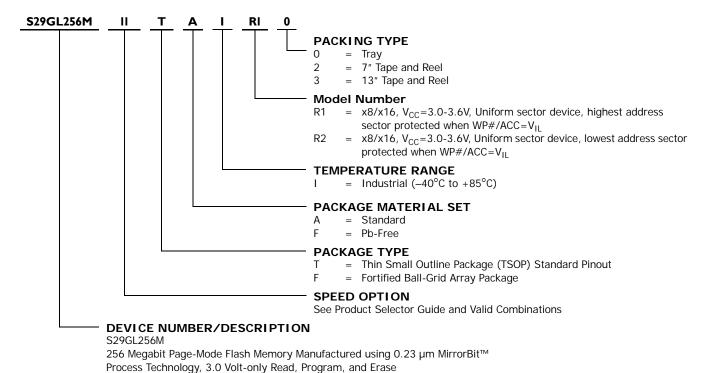


Table 4. S29GL256M Ordering Options

	Package Description					
Device Number	Speed Option	Package, Material, & Temperature Range	Model Number	Packing Type	(Note	
S20CL2E/M	10, 11	TAI,TFI	D1 D2	0,2,3	TS056 (2, 3, 4)	TSOP
S29GL256M (Note 5)	(Note 5)	FAI,FFI	R1,R2	(Note 1)	LAC064 (3)	Fortified BGA

#### Notes:

- 1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.
- 2. TSOP package marking omits the packing type designator from the ordering part number.
- 3. BGA package marking omits leading "S29" and packing type designator from the ordering part number.
- 4. 100% Matte Sn is used for Pb-free TSOP plating.
- 5. Contact your Spansion representative for availability of the 100 ns speed option.

### Valid Combinations



# **Device Bus Operations**

This section describes the requirements and use of the device bus operations, which are initiated through the internal command register. The command register itself does not occupy any addressable memory location. The register is a latch used to store the commands, along with the address and data information needed to execute the command. The contents of the register serve as inputs to the internal state machine. The state machine outputs dictate the function of the device. Table 5 lists the device bus operations, the inputs and control levels they require, and the resulting output. The following subsections describe each of these operations in further detail.

		OE				AC	Addresses	DQ0-	DQ	3-DQ15
Operation	CE#	#	WE#	RESET#	WP#	C	(Note 1)	DQ7	BYTE# = V <sub>IH</sub>	BYTE# = V <sub>IL</sub>
Read	L	L	Н	Н	Х	Χ	A <sub>IN</sub>	D <sub>OUT</sub>	D <sub>OUT</sub>	DQ8-DQ14
Write (Program/Erase)	L	Н	L	Н	(Note 3)	Χ	A <sub>IN</sub>	(Note 4)	(Note 4)	= High-Z,
Accelerated Program	L	Ι	L	Н	(Note 3)	$V_{HH}$	A <sub>IN</sub>	(Note 4)	(Note 4)	DQ15 = A-1
Standby	V <sub>CC</sub> ± 0.3 V	Х	х	V <sub>CC</sub> ± 0.3 V	Х	Η	Х	High-Z	High-Z	High-Z
Output Disable	L	Н	Н	Н	Х	Χ	Х	High-Z	High-Z	High-Z
Reset	Х	Χ	Х	L	Х	Χ	Х	High-Z	High-Z	High-Z
Sector Group Protect (Note 2)	L	Н	L	V <sub>ID</sub>	Н	Х	SA, A6 =L, A3=L, A2=L, A1=H, A0=L	(Note 4)	Х	Х
Sector Group Unprotect (Note 2)	L	Н	L	V <sub>ID</sub>	Н	х	SA, A6=H, A3=L, A2=L, A1=H, A0=L	(Note 4)	Х	Х
Temporary Sector Group Unprotect	Х	Х	Х	V <sub>ID</sub>	Н	Х	A <sub>IN</sub>	(Note 4)	(Note 4)	High-Z

Table 5. Device Bus Operations

**Legend:**  $L = Logic \ Low = V_{IL}$ ,  $H = Logic \ High = V_{IH}$ ,  $V_{ID} = 11.5 - 12.5 \ V$ ,  $V_{HH} = 11.5 \ V - 12.5 \ V$ ,  $X = Don't \ Care$ ,  $SA = Sector \ Address$ ,  $A_{IN} = Address \ In$ ,  $D_{IN} = Data \ In$ ,  $D_{OUT} = Data \ Out$ 

### Notes:

- Addresses are Amax: A0 in word mode; Amax: A-1 in byte mode. Sector addresses are Amax: A15 in both modes.
- The sector protect and sector unprotect functions may also be implemented via programming equipment. See the "Sector Group Protection and Unprotection" section.
- 3. If WP# = V<sub>IL</sub>, the first or last sector remains protected (for uniform sector devices), and the two outer boot sectors are protected (for boot sector devices). If WP# = V<sub>IH</sub>, the first or last sector, or the two outer boot sectors are protected or unprotected as determined by the method described in "Sector Group Protection and Unprotection". All sectors are unprotected when shipped from the factory (The Secured Silicon Sector may be factory protected depending on version ordered.)
- D<sub>IN</sub> or D<sub>OUT</sub> as required by command sequence, data polling, or sector protect algorithm (see Figure 2).

# Word/Byte Configuration

The BYTE# pin controls whether the device data I/O pins operate in the byte or word configuration. If the BYTE# pin is set at logic '1', the device is in word configuration, DQ0–DQ15 are active and controlled by CE# and OE#.

If the BYTE# pin is set at logic '0', the device is in byte configuration, and only data I/O pins DQ0–DQ7 are active and controlled by CE# and OE#. The data I/O pins DQ8–DQ14 are tri-stated, and the DQ15 pin is used as an input for the LSB (A-1) address function.

# Requirements for Reading Array Data

To read array data from the outputs, the system must drive the CE# and OE# pins to  $V_{IL}$ . CE# is the power control and selects the device. OE# is the output control and gates array data to the output pins. WE# should remain at  $V_{IH}$ .



The internal state machine is set for reading array data upon device power-up, or after a hardware reset. This ensures that no spurious alteration of the memory content occurs during the power transition. No command is necessary in this mode to obtain array data. Standard microprocessor read cycles that assert valid addresses on the device address inputs produce valid data on the device data outputs. The device remains enabled for read access until the command register contents are altered.

See Reading Array Data for more information. See AC Characteristics for timing specifications and the timing diagram. See DC Characteristics for the active current specification on reading array data.

### Page Mode Read

The device is capable of fast page mode read and is compatible with the page mode Mask ROM read operation. This mode provides faster read access speed for random locations within a page. The page size of the device is 4 words/8 bytes. The appropriate page is selected by the higher address bits A(max)–A2. Address bits A1–A0 in word mode (A1–A-1 in byte mode) determine the specific word within a page. This is an asynchronous operation; the microprocessor supplies the specific word location.

The random or initial page access is equal to  $t_{ACC}$  or  $t_{CE}$  and subsequent page read accesses (as long as the locations specified by the microprocessor falls within that page) is equivalent to  $t_{PACC}$ . When CE# is deasserted and reasserted for a subsequent access, the access time is  $t_{ACC}$  or  $t_{CE}$ . Fast page mode accesses are obtained by keeping the "read-page addresses" constant and changing the "intra-read page" addresses.

### **Writing Commands/Command Sequences**

To write a command or command sequence (which includes programming data to the device and erasing sectors of memory), the system must drive WE# and CE# to  $V_{II}$ , and OE# to  $V_{IH}$ .

The device features an **Unlock Bypass** mode to facilitate faster programming. Once the device enters the Unlock Bypass mode, only two write cycles are required to program a word, instead of four. Word Program Command Sequence contains details on programming data to the device using both standard and Unlock Bypass command sequences.

An erase operation can erase one sector, multiple sectors, or the entire device. Table 6 and Table 16 indicates the address space that each sector occupies.

See DC Characteristics for the active current specification for the write mode. AC Characteristics contains timing specification tables and timing diagrams for write operations.

### Write Buffer

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. See Write Buffer Programming for more information.

### Accelerated Program Operation

The device offers accelerated program operations through the ACC function. This is one of two functions provided by the WP#/ACC or ACC pin, depending on model number. This function is primarily intended to allow faster manufacturing throughput at the factory.

If the system asserts  $V_{HH}$  on this pin, the device automatically enters the aforementioned Unlock Bypass mode, temporarily unprotects any protected sector groups, and uses the higher voltage on the pin to reduce the time required for program operations. The system would use a two-cycle program command sequence as required by the Unlock Bypass mode. Removing  $V_{HH}$  from the WP#/ACC or ACC pin, depending on model number, returns the device to normal operation. Note that the WP#/ACC or ACC pin must not be at  $V_{HH}$  for operations other than accelerated programming, or device damage may result. WP# has an internal pullup; when unconnected, WP# is at  $V_{IH}$ .

### **Autoselect Functions**

If the system writes the autoselect command sequence, the device enters the autoselect mode. The system can then read autoselect codes from the internal register (which is separate from the memory array) on DQ7–DQ0. Standard read cycle timings apply in this mode. See Autoselect Mode and Autoselect Command Sequence for more information.



### **Standby Mode**

When the system is not reading or writing to the device, it can place the device in the standby mode. In this mode, current consumption is greatly reduced, and the outputs are placed in the high impedance state, independent of the OE# input.

The device enters the CMOS standby mode when the CE# and RESET# pins are both held at  $V_{IO}$   $\pm$  0.3 V. (Note that this is a more restricted voltage range than  $V_{IH}$ .) If CE# and RESET# are held at  $V_{IH}$ , but not within  $V_{IO}$   $\pm$  0.3 V, the device is in the standby mode, but the standby current is greater. The device requires standard access time ( $t_{CE}$ ) for read access when the device is in either of these standby modes, before it is ready to read data.

If the device is deselected during erasure or programming, the device draws active current until the operation is completed.

See DC Characteristics for the standby current specification.

### **Automatic Sleep Mode**

The automatic sleep mode minimizes Flash device energy consumption. The device automatically enables this mode when addresses remain stable for  $t_{ACC} + 30$  ns. The automatic sleep mode is independent of the CE#, WE#, and OE# control signals. Standard address access timings provide new data when addresses are changed. While in sleep mode, output data is latched and always available to the system. See DC Characteristics for the automatic sleep mode current specification.

### **RESET#: Hardware Reset Pin**

The RESET# pin provides a hardware method of resetting the device to reading array data. When the RESET# pin is driven low for at least a period of  $t_{RP}$ , the device immediately terminates any operation in progress, tristates all output pins, and ignores all read/write commands for the duration of the RESET# pulse. The device also resets the internal state machine to reading array data. The operation that was interrupted should be reinitiated once the device is ready to accept another command sequence, to ensure data integrity.

Current is reduced for the duration of the RESET# pulse. When RESET# is held at  $V_{SS}\pm0.3$  V, the device draws CMOS standby current ( $I_{CC5}$ ). If RESET# is held at  $V_{IL}$  but not within  $V_{SS}\pm0.3$  V, the standby current is greater.

The RESET# pin may be tied to the system reset circuitry. A system reset would thus also reset the Flash memory, enabling the system to read the boot-up firmware from the Flash memory.

See AC Characteristics for RESET# parameters and to Figure 15 for the timing diagram.

# **Output Disable Mode**

When the OE# input is at  $V_{IH}$ , output from the device is disabled. The output pins are placed in the high impedance state.



Table 6. S29GL032M (Model R0) Sector Addresses

Sector		,	<b>A21</b> -	-A1	6		8-bit Address Range	Sector	200	12120		A21-	A21–A16	A21–A16	A21–A16
SA0	0	0	0	0	0	0	000000-00FFFF	SA32		1	1 0	1 0 0	1 0 0 0	1 0 0 0 0	1 0 0 0 0 0
	0	0	0	0	0	1	010000-01FFFF	SA33		1	1 0	1 0 0	1 0 0 0	1 0 0 0 0	1 0 0 0 0 1
	0	0	0	0	1	0	020000-02FFFF	SA34	1		0	0 0	0 0 0	0 0 0 1	0 0 0 1 0
A3	0	0	0	0	1	1	030000-03FFFF	SA35	1		0	0 0	0 0 0	0 0 0 1	0 0 0 1 1
SA4	0	0	0	1	0	0	040000-04FFFF	SA36	1		0	0 0	0 0 1	0 0 1 0	0 0 1 0 0
SA5	0	0	0	1	0	1	050000-05FFFF	SA37	1		0	0 0	0 0 1	0 0 1 0	0 0 1 0 1
SA6	0	0	0	1	1	0	060000-06FFFF	SA38	1	I	0	0 0	0 0 1	0 0 1 1	0 0 1 1 0
SA7	0	0	0	1	1	1	070000-07FFFF	SA39	1	Ī	0	0 0	0 0 1	0 0 1 1	0 0 1 1 1
SA8	0	0	1	0	0	0	080000-08FFFF	SA40	1		0	0 1	0 1 0	0 1 0 0	0 1 0 0 0
SA9	0	0	1	0	0	1	090000-09FFFF	SA41	1	0	)	) 1	1 0	1 0 0	1 0 0 1
SA10	0	0	1	0	1	0	0A0000-0AFFFF	SA42	1	0		1	1 0	1 0 1	1 0 1 0
SA11	0	0	1	0	1	1	OBOOOO-OBFFFF	SA43	1	0	İ	1	1 0	1 0 1	1 0 1 1
SA12	0	0	1	1	0	0	OCOOOO-OCFFFF	SA44	1	0		1	1 1	1 1 0	1 1 0 0
SA13	0	0	1	1	0	1	0D0000-0DFFFF	SA45	1	0	1		1	1 0	1 0 1
SA14	0	0	1	1	1	0	0E0000-0EFFFF	SA46	1	0	1		1	1 1	1 1 0
SA15	0	0	1	1	1	1	0F0000-0FFFFF	SA47	1	0	1		1	1 1	1 1 1
SA16	0	1	0	0	0	0	100000-10FFFF	SA48	1	1	0		0	0 0	0 0 0
SA17	0	1	0	0	0	1	110000–11FFFF	SA49	1	1	О	)	0	0 0	0 0 1
SA18	0	1	0	0	1	0	120000–12FFFF	SA50	1	1	0		0	0 1	0 1 0
SA19	0	1	0	0	1	1	130000-13FFFF	SA51	1	1	0		0	0 1	0 1 1
SA20	0	1	0	1	0	0	140000–14FFFF	SA52	1	1	0		1	1 0	1 0 0
SA21	0	1	0	1	0	1	150000-15FFFF	SA53	1	1	0	٦	1	1 0	1 0 1
SA22	0	1	0	1	1	0	160000-16FFFF	SA54	1	1	0		1	1 1	1 1 0
SA23	0	1	0	1	1	1	170000-17FFFF	SA55	1	1	0		1	1 1	1 1 1
SA24	0	1	1	0	0	0	180000–18FFFF	SA56	1	1	1		0	0 0	0 0 0
SA25	0	1	1	0	0	1	190000–19FFFF	SA57	1	1	1		0	0 0	0 0 1
SA26	0	1	1	0	1	0	1A0000-1AFFFF	SA58	1	1	1		0	0 1	0 1 0
SA27	0	1	1	0	1	1	1B0000–1BFFFF	SA59	1	1	İ	1	1 0	1 0 1	1 0 1 1
SA28	0	1	1	1	0	0	1C0000-1CFFFF	SA60	1	1	ı	1	1 1	1 1 0	1 1 0 0
SA29	0	1	1	1	0	1	1D0000-1DFFFF	SA61	1	1		1	1 1	1 1 0	1 1 0 1
SA30	0	1	1	1	1	0	1E0000–1EFFFF	SA62	1	1		1	1 1	1 1 1	1 1 1 0
SA31	0	1	1	1	1	1	1F0000-1FFFFF	SA63	1	1	İ	1	1 1	1 1 1	1 1 1 1



Table 7. S29GL032M (Models RI, R2) Sector Addresses

Sector		Α	20	-A	15		Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector		A2	20-	-Α΄	15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	(	0	0	0	0	0	64/32	000000-00FFFF	000000-007FFF	SA32	1	0	0	0	0 0	64/32	200000-20FFFF	100000-107FFF
SA1	(	0	0	0	0	1	64/32	010000-01FFFF	008000-00FFFF	SA33	1	0	0	0	0 1	64/32	210000-21FFFF	108000-10FFFF
SA2	(	0	0	0	1	0	64/32	020000-02FFFF	010000-017FFF	SA34	1	0	0	0	1 0	64/32	220000-22FFFF	110000–117FFF
SA3	(	0	0	0	1	1	64/32	030000-03FFFF	018000-01FFFF	SA35	1	0	0	0	1 1	64/32	230000-23FFFF	118000–11FFFF
SA4	(	0	0	1	0	0	64/32	040000-04FFFF	020000-027FFF	SA36	1	0	0	1	0 0	64/32	240000-24FFFF	120000-127FFF
SA5	(	0	0	1	0	1	64/32	050000-05FFFF	028000-02FFFF	SA37	1	0	0	1	0 1	64/32	250000-25FFFF	128000-12FFFF
SA6	(	0	0	1	1	0	64/32	060000-06FFFF	030000-037FFF	SA38	1	0	0	1	1 0	64/32	260000-26FFFF	130000–137FFF
SA7	(	0	0	1	1	1	64/32	070000-07FFFF	038000-03FFFF	SA39	1	0	0	1	1 1	64/32	270000-27FFFF	138000–13FFFF
SA8	(	0	1	0	0	0	64/32	080000-08FFFF	040000-047FFF	SA40	1	0	1	0	0 0	64/32	280000-28FFFF	140000-147FFF
SA9	(	0	1	0	0	1	64/32	090000-09FFFF	048000-04FFFF	SA41	1	0	1	0	0 1	64/32	290000-29FFFF	148000–14FFFF
SA10	(	0	1	0	1	0	64/32	OAOOOO-OAFFFF	050000-057FFF	SA42	1	0	1	0	1 0	64/32	2A0000-2AFFFF	150000–157FFF
SA11	(	0	1	0	1	1	64/32	OBOOOO-OBFFFF	058000-05FFFF	SA43	1	0	1	0	1 1	64/32	2B0000-2BFFFF	158000–15FFFF
SA12	(	0	1	1	0	0	64/32	0C0000-0CFFFF	060000-067FFF	SA44	1	0	1	1	0 0	64/32	2C0000-2CFFFF	160000-167FFF
SA13	(	0	1	1	0	1	64/32	0D0000-0DFFFF	068000-06FFFF	SA45	1	0	1	1	0 1	64/32	2D0000-2DFFFF	168000–16FFFF
SA14	(	0	1	1	1	0	64/32	0E0000-0EFFFF	070000-077FFF	SA46	1	0	1	1	1 0	64/32	2E0000-2EFFFF	170000–177FFF
SA15	(	0	1	1	1	1	64/32	OFOOOO-OFFFFF	078000-07FFFF	SA47	1	0	1	1	1 1	64/32	2F0000-2FFFFF	178000–17FFFF
SA16	(	) 1	0	0	0	0	64/32	100000-10FFFF	080000-087FFF	SA48	1	1	0	0	0 0	64/32	300000-30FFFF	180000–187FFF
SA17	(	) 1	0	0	0	1	64/32	110000–11FFFF	088000-08FFFF	SA49	1	1	0	0	0 1	64/32	310000-31FFFF	188000–18FFFF
SA18	(	) 1	0	0	1	0	64/32	120000-12FFFF	090000-097FFF	SA50	1	1	0	0	1 0	64/32	320000-32FFFF	190000-197FFF
SA19	(	) 1	0	0	1	1	64/32	130000–13FFFF	098000-09FFFF	SA51	1	1	0	0	1 1	64/32	330000-33FFFF	198000–19FFFF
SA20	(	) 1	0	1	0	0	64/32	140000-14FFFF	0A0000-0A7FFF	SA52	1	1	0	1	0 0	64/32	340000-34FFFF	1A0000-1A7FFF
SA21	(	) 1	0	1	0	1	64/32	150000–15FFFF	0A8000-0AFFFF	SA53	1	1	0	1	0 1	64/32	350000-35FFFF	1A8000–1AFFFF
SA22	(	) 1	0	1	1	0	64/32	160000-16FFFF	0B0000-0B7FFF	SA54	1	1	0	1	1 0	64/32	360000-36FFFF	1B0000-1B7FFF
SA23	(	) 1	0	1	1	1	64/32	170000–17FFFF	OB8000-OBFFFF	SA55	1	1	0	1	1 1	64/32	370000-37FFFF	1B8000-1BFFFF
SA24	(	) 1	1	0	0	0	64/32	180000–18FFFF	0C0000-0C7FFF	SA56	1	1	1	0	0 0	64/32	380000-38FFFF	1C0000-1C7FFF
SA25	(	) 1	1	0	0	1	64/32	190000–19FFFF	0C8000-0CFFFF	SA57	1	1	1	0	0 1	64/32	390000-39FFFF	1C8000-1CFFFF
SA26	(	) 1	1	0	1	0	64/32	1A0000-1AFFFF	0D0000-0D7FFF	SA58	1	1	1	0	1 0	64/32	3A0000-3AFFFF	1D0000-1D7FFF
SA27	(	) 1	1	0	1	1	64/32	1B0000-1BFFFF	OD8000-ODFFFF	SA59	1	1	1	0	1 1	64/32	3B0000-3BFFFF	1D8000-1DFFFF
SA28	(	) 1	1	1	0	0	64/32	1C0000-1CFFFF	0E0000-0E7FFF	SA60	1	1	1	1	0 0	64/32	3C0000-3CFFFF	1E0000-1E7FFF
SA29	(	) 1	1	1	0	1	64/32	1D0000-1DFFFF	0E8000-0EFFFF	SA61	1	1	1	1	0 1	64/32	3D0000-3DFFFF	1E8000-1EFFFF
SA30	(	) 1	1	1	1	0	64/32	1E0000-1EFFFF	OFOOOO-OF7FFF	SA62	1	1	1	1	1 0	64/32	3E0000-3EFFFF	1F0000-1F7FFF
SA31	(	) 1	1	1	1	1	64/32	1F0000-1FFFFF	0F8000-0FFFFF	SA63	1	1	1	1	1 1	64/32	3F0000-3FFFFF	1F8000–1FFFFF



# Table 8. S29GL032M (Model R3) Top Boot Sector Addresses

Sector	A20-A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A20-A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA0	000000xxx	64/32	000000h-00FFFFh	00000h-07FFFh	SA36	100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh
SA1	000001xxx	64/32	010000h-01FFFFh	08000h-0FFFFh	SA37	100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh
SA2	000010xxx	64/32	020000h-02FFFFh	10000h-17FFFh	SA38	100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh
SA3	000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA39	100111xxx	64/32	270000h-27FFFh	138000h-13FFFFh
SA4	000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA40	101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh
SA5	000101xxx	64/32	050000h-05FFFFh	28000h–2FFFFh	SA41	101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh
SA6	000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA42	101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh
SA7	000111xxx	64/32	070000h-07FFFh	38000h-3FFFFh	SA43	101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh
SA8	001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA44	101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh
SA9	001001xxx	64/32	090000h-09FFFFh	48000h–4FFFFh	SA45	101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh
SA10	001010xxx	64/32	OAOOOOh-OAFFFFh	50000h-57FFFh	SA46	101110xxx	64/32	2E0000h-2EFFFFh	170000h–177FFFh
SA11	001011xxx	64/32	OBOOOOh-OBFFFFh	58000h-5FFFFh	SA47	101111xxx	64/32	2F0000h-2FFFFFh	178000h-17FFFFh
SA12	001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh	SA48	110000xxx	64/32	300000h-30FFFFh	180000h-187FFFh
SA13	001101xxx	64/32	0D0000h-0DFFFFh	68000h-6FFFFh	SA49	110001xxx	64/32	310000h-31FFFFh	188000h-18FFFFh
SA14	001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA50	110010xxx	64/32	320000h-32FFFFh	190000h-197FFFh
SA15	001111xxx	64/32	0F0000h-0FFFFh	78000h–7FFFFh	SA51	110011xxx	64/32	330000h-33FFFFh	198000h-19FFFFh
SA16	010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh	SA52	100100xxx	64/32	340000h-34FFFFh	1A0000h-1A7FFFh
SA17	010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA53	110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh
SA18	010010xxx	64/32	120000h-12FFFFh	90000h-97FFFh	SA54	110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA19	010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh	SA55	110111xxx	64/32	370000h-37FFFFh	1B8000h-1BFFFFh
SA20	010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh	SA56	111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA21	010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh	SA57	111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA22	010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh	SA58	111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA23	010111xxx	64/32	170000h–17FFFFh	B8000h-BFFFFh	SA59	111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA24	011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh	SA60	111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA25	011001xxx	64/32	190000h-19FFFFh	C8000h-CFFFFh	SA61	111101xxx	64/32	3D0000h-3DFFFFh	1E8000h-1EFFFFh
SA26	011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh	SA62	111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh
SA27	011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh	SA63	111111000	8/4	3F0000h-3F1FFFh	1F8000h-1F8FFFh
SA28	011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh	SA64	111111001	8/4	3F2000h-3F3FFFh	1F9000h-1F9FFFh
SA29	011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh	SA65	111111010	8/4	3F4000h-3F5FFFh	1FA000h–1FAFFFh
SA30	011110xxx	64/32	1E0000h–1EFFFFh	F0000h-F7FFFh	SA66	111111011	8/4	3F6000h-3F7FFFh	1FB000h-1FBFFFh
SA31	011111xxx	64/32	1F0000h-1FFFFFh	F8000h–FFFFFh	SA67	111111100	8/4	3F8000h-3F9FFFh	1FC000h-1FCFFFh
SA32	100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA68	111111101	8/4	3FA000h-3FBFFFh	1FD000h–1FDFFFh
SA33	100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA69	111111110	8/4	3FC000h-3FDFFFh	1FE000h-1FEFFFh
SA34	100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA70	111111111	8/4	3FE000h-3FFFFFh	1FF000h-1FFFFFh
SA35	101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh					

<sup>\*</sup> Sector sizes are given in Kbytes/Kwords.



Table 9. S29GL032M (Model R4) Bottom Boot Sector Addresses

Sector	A20-A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A20-A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA0	000000000	8/4	000000h-001FFFh	00000h-00FFFh	SA19	001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh
SA1	00000001	8/4	002000h-003FFFh	01000h-01FFFh	SA20	001101xxx	64/32	0D0000h-0DFFFFh	68000h–6FFFFh
SA2	00000010	8/4	004000h-005FFFh	02000h-02FFFh	SA21	001101xxx	64/32	0E0000h-0EFFFFh	70000h–77FFFh
SA3	00000011	8/4	006000h-007FFFh	03000h-03FFFh	SA22	001111xxx	64/32	0F0000h-0FFFFh	78000h–7FFFFh
SA4	00000100	8/4	008000h-009FFFh	04000h-04FFFh	SA23	010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh
SA5	000000101	8/4	00A000h-00BFFFh	05000h-05FFFh	SA24	010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh
SA6	000000110	8/4	00C000h-00DFFFh	06000h-06FFFh	SA25	010010xxx	64/32	120000h-12FFFFh	90000h-97FFh
SA7	000000111	8/4	00E000h-00FFFFh	07000h-07FFFh	SA26	010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh
SA8	000001xxx	64/32	010000h-01FFFFh	08000h-0FFFFh	SA27	010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh
SA9	000010xxx	64/32	020000h-02FFFFh	10000h-17FFFh	SA28	010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh
SA10	000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA29	010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh
SA11	000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA30	010111xxx	64/32	170000h-17FFFFh	B8000h-BFFFFh
SA12	000101xxx	64/32	050000h-05FFFFh	28000h-2FFFFh	SA31	011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh
SA13	000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA32	011001xxx	64/32	190000h-19FFFFh	C8000h-CFFFFh
SA14	000111xxx	64/32	070000h-07FFFh	38000h-3FFFFh	SA33	011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh
SA15	001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA34	011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh
SA16	001001xxx	64/32	090000h-09FFFFh	48000h–4FFFFh	SA35	011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh
SA17	001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA36	011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh
SA18	001011xxx	64/32	0B0000h-0BFFFFh	58000h-5FFFFh	SA37	011110xxx	64/32	1E0000h-1EFFFFh	F0000h-F7FFFh
SA38	011111xxx	64/32	1F0000h-1FFFFFh	F8000h-FFFFFh	SA55	110000xxx	64/32	300000h-30FFFFh	180000h-187FFFh
SA39	100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA56	110001xxx	64/32	310000h-31FFFFh	188000h–18FFFFh
SA40	100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA57	110010xxx	64/32	320000h-32FFFFh	190000h-197FFFh
SA41	100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA58	110011xxx	64/32	330000h-33FFFFh	198000h-19FFFFh
SA42	101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh	SA59	100100xxx	64/32	340000h-34FFFFh	1A0000h-1A7FFFh
SA43	100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh	SA60	110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh
SA44	100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh	SA61	110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA45	100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh	SA62	110111xxx	64/32	370000h-37FFFFh	1B8000h-1BFFFFh
SA46	100111xxx	64/32	270000h-27FFFh	138000h-13FFFFh	SA63	111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA47	101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh	SA64	111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA48	101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh	SA65	111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA49	101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh	SA66	111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA50	101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh	SA67	111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA51	101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh	SA68	111101xxx	64/32	3D0000h-3DFFFFh	1E8000h–1EFFFFh
SA52	101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh	SA69	111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh
SA53	101110xxx	64/32	2E0000h-2EFFFFh	170000h-177FFFh	SA70	1111111xxx	64/32	3F0000h-3FFFFFh	1F8000h–1FFFFFh
SA54	1011111xxx	64/32	2F0000h–2FFFFFh	178000h-17FFFh		•			

<sup>\*</sup> Sector sizes are given in Kbytes/Kwords.



# Table I0. S29GL064M (Model R0) Sector Addresses

Sector	A22-A16	8-bit Address Range	Sector	A22-A16	8-bit Address Range	Sector	A22–A16	8-bit Address Range
SA0	0000000	000000-00FFFF	SA43	0 1 0 1 0 1 1	2B0000-2BFFFF	SA86	1 0 1 0 1 1 0	560000-56FFFF
SA1	0000001	010000-01FFFF	SA44	0 1 0 1 1 0 0	2C0000-2CFFFF	SA87	1 0 1 0 1 1 1	570000-57FFFF
SA2	0000010	020000-02FFFF	SA45	0 1 0 1 1 0 1	2D0000-2DFFFF	SA88	1 0 1 1 0 0 0	580000-58FFFF
SA3	0000011	030000-03FFFF	SA46	0 1 0 1 1 1 0	2E0000-2EFFFF	SA89	1 0 1 1 0 0 1	590000-59FFFF
SA4	0000100	040000-04FFFF	SA47	0 1 0 1 1 1 1	2F0000–2FFFFF	SA90	1011010	5A0000-5AFFFF
SA5	0000101	050000-05FFFF	SA48	0110000	300000–30FFFF	SA91	1 0 1 1 0 1 1	5B0000–5BFFFF
SA6	0000110	060000-06FFFF	SA49	0 1 1 0 0 0 1	310000–31FFFF	SA92	1011100	5C0000-5CFFFF
SA7	0000111	070000-07FFFF	SA50	0 1 1 0 0 1 0	320000–32FFFF	SA93	1 0 1 1 1 0 1	5D0000-5DFFFF
SA8	000100	080000-08FFFF	SA51	0 1 1 0 0 1 1	330000–33FFFF	SA94	1 0 1 1 1 1 0	5E0000-5EFFFF
SA9	0001001	090000-09FFFF	SA52	0 1 1 0 1 0 0	340000–34FFFF	SA95	1 0 1 1 1 1 1	5F0000-5FFFFF
SA10	0001010	0A0000-0AFFFF	SA53	0 1 1 0 1 0 1	350000–35FFFF	SA96	1 1 0 0 0 0 0	600000-60FFFF
SA11	0001011	OBOOOO-OBFFFF	SA54	0 1 1 0 1 1 0	360000–36FFFF	SA97	1 1 0 0 0 0 1	610000–61FFFF
SA12	0001100	0C0000-0CFFFF	SA55	0 1 1 0 1 1 1	370000–37FFFF	SA98	1 1 0 0 0 1 0	620000–62FFFF
SA13	0001101	0D0000-0DFFFF	SA56	0 1 1 1 0 0 0	380000–38FFFF	SA99	1 1 0 0 0 1 1	630000–63FFFF
SA14	0 0 0 1 1 1 0	0E0000-0EFFFF	SA57	0 1 1 1 0 0 1	390000–39FFFF	SA100	1 1 0 0 1 0 0	640000–64FFFF
SA15	0 0 0 1 1 1 1	OFOOOO-OFFFFF	SA58	0 1 1 1 0 1 0	3A0000–3AFFFF	SA101	1 1 0 0 1 0 1	650000–65FFFF
SA16	001000	100000-10FFFF	SA59	0 1 1 1 0 1 1	3B0000–3BFFFF	SA102	1 1 0 0 1 1 0	660000–66FFFF
SA17	0010001	110000-11FFFF	SA60	0 1 1 1 1 0 0	3C0000-3CFFFF	SA103	1 1 0 0 1 1 1	670000–67FFFF
SA18	0 0 1 0 0 1 0	120000-12FFFF	SA61	0 1 1 1 1 0 1	3D0000–3DFFFF	SA104	1 1 0 1 0 0 0	680000–68FFFF
SA19	0010011	130000–13FFFF	SA62	0 1 1 1 1 1 0	3E0000-3EFFFF	SA105	1 1 0 1 0 0 1	690000–69FFFF
SA20	0010100	140000-14FFFF	SA63	0 1 1 1 1 1 1	3F0000-3FFFFF	SA106	1 1 0 1 0 1 0	6A0000-6AFFFF
SA21	0 0 1 0 1 0 1	150000–15FFFF	SA64	10000000	400000-40FFFF	SA107	1 1 0 1 0 1 1	6B0000-6BFFFF
SA22	0 0 1 0 1 1 0	160000–16FFFF	SA65	1000001	410000–41FFFF	SA108	1 1 0 1 1 0 0	6C0000-6CFFFF
SA23	0 0 1 0 1 1 1	170000–17FFFF	SA66	1000010	420000–42FFFF	SA109	1 1 0 1 1 0 1	6D0000–6DFFFF
SA24	0011000	180000–18FFFF	SA67	1000011	430000–43FFFF	SA110	1 1 0 1 1 1 0	6E0000-6EFFFF
SA25	0011001	190000–19FFFF	SA68	1000100	440000–44FFFF	SA111	1 1 0 1 1 1 1	6F0000-6FFFFF
SA26	0 0 1 1 0 1 0	1A0000–1AFFFF	SA69	1000101	450000–45FFFF	SA112	1 1 1 0 0 0 0	700000-70FFFF
SA27	0 0 1 1 0 1 1	1B0000–1BFFFF	SA70	1000110	460000–46FFFF	SA113	1 1 1 0 0 0 1	710000–71FFFF
SA28	0 0 1 1 1 0 0	1C0000-1CFFFF	SA71	1000111	470000–47FFFF	SA114	1 1 1 0 0 1 0	720000–72FFFF
SA29	0011101	1D0000-1DFFFF	SA72	100100	480000–48FFFF	SA115	1 1 1 0 0 1 1	730000–73FFFF
SA30	0 0 1 1 1 1 0	1E0000-1EFFFF	SA73	1 0 0 1 0 0 1	490000–49FFFF	SA116	1 1 1 0 1 0 0	740000–74FFFF
SA31	0011111	1F0000–1FFFFF	SA74	1001010	4A0000–4AFFFF	SA117	1 1 1 0 1 0 1	750000–75FFFF
SA32	010000	200000–20FFFF	SA75	1001011	4B0000–4BFFFF	SA118	1110110	760000–76FFFF
SA33	0100001	210000–21FFFF	SA76	1001100	4C0000-4CFFFF	SA119	1 1 1 0 1 1 1	770000–77FFFF
SA34	0100010		SA77	1001101	4D0000–4DFFFF	SA120	1 1 1 1 0 0 0	780000–78FFFF
SA35	0 1 0 0 0 1 1		SA78	1001110	4E0000–4EFFFF	SA121	1 1 1 1 0 0 1	790000–79FFFF
SA36	0100100	240000-24FFFF	SA79	1001111	4F0000–4FFFFF	SA122	1 1 1 1 0 1 0	7A0000–7AFFFF
SA37	0100101	250000-25FFFF	SA80	1010000	500000-50FFFF	SA123	1 1 1 1 0 1 1	7B0000–7BFFFF
SA38	0100110	260000-26FFFF	SA81	1010001	510000–51FFFF	SA124	1 1 1 1 1 0 0	7C0000-7CFFFF
SA39	0 1 0 0 1 1 1	270000–27FFFF	SA82	1010010	520000-52FFFF	SA125	1 1 1 1 1 0 1	7D0000–7DFFFF
SA40	0101000	280000–28FFFF	SA83	1010011	530000–53FFFF	SA126	1 1 1 1 1 1 0	7E0000–7EFFFF
SA41	0101001	290000–29FFFF	SA84	1010100	540000–54FFFF	SA127	1 1 1 1 1 1 1	7F0000–7FFFFF
SA42	0 1 0 1 0 1 0	2A0000–2AFFFF	SA85	1010101	550000–55FFFF			



# Table II. S29GL064M (Models RI, R2, R8, R9) Sector Addresses (Sheet I of 3)

Sector			A	21–A	15			Sector Size (KB/ Kwords)	8-bit Address Range	8-bit Address Range
SA0	0	0	0	0	0	0	0	64/32	000000-00FFFF	000000-007FFF
SA1	0	0	0	0	0	0	1	64/32	010000-01FFFF	008000-00FFFF
SA2	0	0	0	0	0	1	0	64/32	020000-02FFFF	010000-017FFF
SA3	0	0	0	0	0	1	1	64/32	030000-03FFFF	018000-01FFFF
SA4	0	0	0	0	1	0	0	64/32	040000-04FFFF	020000-027FFF
SA5	0	0	0	0	1	0	1	64/32	050000-05FFFF	028000-02FFFF
SA6	0	0	0	0	1	1	0	64/32	060000-06FFFF	030000-037FFF
SA7	0	0	0	0	1	1	1	64/32	070000-07FFFF	038000-03FFFF
SA8	0	0	0	1	0	0	0	64/32	080000-08FFFF	040000-047FFF
SA9	0	0	0	1	0	0	1	64/32	090000-09FFFF	048000-04FFFF
SA10	0	0	0	1	0	1	0	64/32	0A0000-0AFFFF	050000-057FFF
SA11	0	0	0	1	0	1	1	64/32	0B0000-0BFFFF	058000-05FFFF
SA12	0	0	0	1	1	0	0	64/32	0C0000-0CFFFF	060000-067FFF
SA13	0	0	0	1	1	0	1	64/32	0D0000-0DFFFF	068000-06FFFF
SA14	0	0	0	1	1	1	0	64/32	0E0000-0EFFFF	070000-077FFF
SA15	0	0	0	1	1	1	1	64/32	0F0000-0FFFFF	078000-07FFFF
SA16	0	0	1	0	0	0	0	64/32	100000-10FFFF	080000-087FFF
SA17	0	0	1	0	0	0	1	64/32	110000-11FFFF	088000-08FFFF
SA18	0	0	1	0	0	1	0	64/32	120000-12FFFF	090000-097FFF
SA19	0	0	1	0	0	1	1	64/32	130000–13FFFF	098000-09FFFF
SA20	0	0	1	0	1	0	0	64/32	140000-14FFFF	0A0000-0A7FFF
SA21	0	0	1	0	1	0	1	64/32	150000-15FFFF	0A8000-0AFFFF
SA22	0	0	1	0	1	1	0	64/32	160000-16FFFF	0B0000-0B7FFF
SA23	0	0	1	0	1	1	1	64/32	170000-17FFFF	OB8000-OBFFFF
SA24	0	0	1	1	0	0	0	64/32	180000–18FFFF	0C0000-0C7FFF
SA25	0	0	1	1	0	0	1	64/32	190000-19FFFF	OC8000-OCFFFF
SA26	0	0	1	1	0	1	0	64/32	1A0000-1AFFFF	0D0000-0D7FFF
SA27	0	0	1	1	0	1	1	64/32	1B0000-1BFFFF	0D8000-0DFFFF
SA28	0	0	1	1	1	0	0	64/32	1C0000-1CFFFF	0E0000-0E7FFF
SA29	0	0	1	1	1	0	1	64/32	1D0000-1DFFFF	0E8000-0EFFFF
SA30	0	0	1	1	1	1	0	64/32	1E0000-1EFFFF	0F0000-0F7FFF
SA31	0	0	1	1	1	1	1	64/32	1F0000-1FFFFF	0F8000-0FFFFF
SA32	0	1	0	0	0	0	0	64/32	200000-20FFFF	100000-107FFF
SA33	0	1	0	0	0	0	1	64/32	210000-21FFFF	108000-10FFFF
SA34	0	1	0	0	0	1	0	64/32	220000-22FFFF	110000–117FFF
SA35	0	1	0	0	0	1	1	64/32	230000-23FFFF	118000–11FFFF
SA36	0	1	0	0	1	0	0	64/32	240000-24FFFF	120000–127FFF
SA37	0	1	0	0	1	0	1	64/32	250000-25FFFF	128000-12FFFF
SA38	0	1	0	0	1	1	0	64/32	260000-26FFFF	130000-137FFF
SA39	0	1	0	0	1	1	1	64/32	270000-27FFFF	138000-13FFFF
SA40	0	1	0	1	0	0	0	64/32	280000-28FFFF	140000-147FFF
SA41	0	1	0	1	0	0	1	64/32	290000-29FFFF	148000-14FFFF
SA42	0	1	0	1	0	1	0	64/32	2A0000–2AFFFF	150000-157FFF
SA43	0	1	0	1	0	1	1	64/32	2B0000–2BFFFF	158000–15FFFF



# Table II. S29GL064M (Models RI, R2, R8, R9) Sector Addresses (Sheet 2 of 3)

Sector			A	21–A	15			Sector Size (KB/ Kwords)	8-bit Address Range	8-bit Address Range
SA44	0	1	0	1	1	0	0	64/32	2C0000-2CFFFF	160000–167FFF
SA45	0	1	0	1	1	0	1	64/32	2D0000–2DFFFF	168000–16FFFF
SA46	0	1	0	1	1	1	0	64/32	2E0000-2EFFFF	170000–177FFF
SA47	0	1	0	1	1	1	1	64/32	2F0000–2FFFFF	178000–17FFFF
SA48	0	1	1	0	0	0	0	64/32	300000-30FFFF	180000–187FFF
SA49	0	1	1	0	0	0	1	64/32	310000-31FFFF	188000–18FFFF
SA50	0	1	1	0	0	1	0	64/32	320000-32FFFF	190000-197FFF
SA51	0	1	1	0	0	1	1	64/32	330000-33FFFF	198000-19FFFF
SA52	0	1	1	0	1	0	0	64/32	340000-34FFFF	1A0000-1A7FFF
SA53	0	1	1	0	1	0	1	64/32	350000-35FFFF	1A8000–1AFFFF
SA54	0	1	1	0	1	1	0	64/32	360000-36FFFF	1B0000-1B7FFF
SA55	0	1	1	0	1	1	1	64/32	370000-37FFFF	1B8000–1BFFFF
SA56	0	1	1	1	0	0	0	64/32	380000-38FFFF	1C0000-1C7FFF
SA57	0	1	1	1	0	0	1	64/32	390000–39FFFF	1C8000-1CFFFF
SA58	0	1	1	1	0	1	0	64/32	3A0000-3AFFFF	1D0000-1D7FFF
SA59	0	1	1	1	0	1	1	64/32	3B0000-3BFFFF	1D8000-1DFFFF
SA60	0	1	1	1	1	0	0	64/32	3C0000-3CFFFF	1E0000-1E7FFF
SA61	0	1	1	1	1	0	1	64/32	3D0000-3DFFFF	1E8000-1EFFFF
SA62	0	1	1	1	1	1	0	64/32	3E0000-3EFFFF	1F0000-1F7FFF
SA63	0	1	1	1	1	1	1	64/32	3F0000-3FFFFF	1F8000-1FFFFF
SA64	1	0	0	0	0	0	0	64/32	400000-40FFFF	200000-207FFF
SA65	1	0	0	0	0	0	1	64/32	410000-41FFFF	208000-20FFFF
SA66	1	0	0	0	0	1	0	64/32	420000-42FFFF	210000-217FFF
SA67	1	0	0	0	0	1	1	64/32	430000-43FFFF	218000–21FFFF
SA68	1	0	0	0	1	0	0	64/32	440000-44FFFF	220000-227FFF
SA69	1	0	0	0	1	0	1	64/32	450000-45FFFF	228000-22FFFF
SA70	1	0	0	0	1	1	0	64/32	460000-46FFFF	230000-237FFF
SA71	1	0	0	0	1	1	1	64/32	470000-47FFFF	238000-23FFFF
SA72	1	0	0	1	0	0	0	64/32	480000-48FFFF	240000-247FFF
SA73	1	0	0	1	0	0	1	64/32	490000-49FFFF	248000-24FFFF
SA74	1	0	0	1	0	1	0	64/32	4A0000-4AFFFF	250000-257FFF
SA75	1	0	0	1	0	1	1	64/32	4B0000–4BFFFF	258000-25FFFF
SA76	1	0	0	1	1	0	0	64/32	4C0000-4CFFFF	260000-267FFF
SA77	1	0	0	1	1	0	1	64/32	4D0000-4DFFFF	268000-26FFFF
SA78	1	0	0	1	1	1	0	64/32	4E0000-4EFFFF	270000-277FFF
SA79	1	0	0	1	1	1	1	64/32	4F0000-4FFFFF	278000-27FFFF
SA80	1	0	1	0	0	0	0	64/32	500000-50FFFF	280000-287FFF
SA81	1	0	1	0	0	0	1	64/32	510000-51FFFF	288000-28FFFF
SA82	1	0	1	0	0	1	0	64/32	520000-52FFFF	290000-297FFF
SA83	1	0	1	0	0	1	1	64/32	530000-53FFFF	298000-29FFFF
SA84	1	0	1	0	1	0	0	64/32	540000-54FFFF	2A0000-2A7FFF
SA85	1	0	1	0	1	0	1	64/32	550000-55FFFF	2A8000–2AFFFF
SA86	1	0	1	0	1	1	0	64/32	560000-56FFFF	2B0000-2B7FFF
SA87	1	0	1	0	1	1	1	64/32	570000-57FFFF	2B8000–2BFFFF



# Table II. S29GL064M (Models RI, R2, R8, R9) Sector Addresses (Sheet 3 of 3)

Sector			A2	21–A	15			Sector Size (KB/ Kwords)	8-bit Address Range	8-bit Address Range
SA88	1	0	1	1	0	0	0	64/32	580000-58FFFF	2C0000-2C7FFF
SA89	1	0	1	1	0	0	1	64/32	590000-59FFFF	2C8000-2CFFFF
SA90	1	0	1	1	0	1	0	64/32	5A0000-5AFFFF	2D0000-2D7FFF
SA91	1	0	1	1	0	1	1	64/32	5B0000-5BFFFF	2D8000-2DFFFF
SA92	1	0	1	1	1	0	0	64/32	5C0000-5CFFFF	2E0000-2E7FFF
SA93	1	0	1	1	1	0	1	64/32	5D0000-5DFFFF	2E8000-2EFFFF
SA94	1	0	1	1	1	1	0	64/32	5E0000-5EFFFF	2F0000-2F7FFF
SA95	1	0	1	1	1	1	1	64/32	5F0000-5FFFFF	2F8000-2FFFFF
SA96	1	1	0	0	0	0	0	64/32	600000-60FFFF	300000-307FFF
SA97	1	1	0	0	0	0	1	64/32	610000-61FFFF	308000-30FFFF
SA98	1	1	0	0	0	1	0	64/32	620000-62FFFF	310000-317FFF
SA99	1	1	0	0	0	1	1	64/32	630000-63FFFF	318000-31FFFF
SA100	1	1	0	0	1	0	0	64/32	640000-64FFFF	320000-327FFF
SA101	1	1	0	0	1	0	1	64/32	650000-65FFFF	328000-32FFFF
SA102	1	1	0	0	1	1	0	64/32	660000-66FFFF	330000-337FFF
SA103	1	1	0	0	1	1	1	64/32	670000–67FFFF	338000–33FFFF
SA104	1	1	0	1	0	0	0	64/32	680000-68FFFF	340000-347FFF
SA105	1	1	0	1	0	0	1	64/32	690000-69FFFF	348000–34FFFF
SA106	1	1	0	1	0	1	0	64/32	6A0000-6AFFFF	350000–357FFF
SA107	1	1	0	1	0	1	1	64/32	6B0000-6BFFFF	358000–35FFFF
SA108	1	1	0	1	1	0	0	64/32	6C0000-6CFFFF	360000–367FFF
SA109	1	1	0	1	1	0	1	64/32	6D0000-6DFFFF	368000–36FFFF
SA110	1	1	0	1	1	1	0	64/32	6E0000-6EFFFF	370000–377FFF
SA111	1	1	0	1	1	1	1	64/32	6F0000-6FFFFF	378000–37FFFF
SA112	1	1	1	0	0	0	0	64/32	700000-70FFFF	380000–387FFF
SA113	1	1	1	0	0	0	1	64/32	710000–71FFFF	388000–38FFFF
SA114	1	1	1	0	0	1	0	64/32	720000-72FFFF	390000-397FFF
SA115	1	1	1	0	0	1	1	64/32	730000–73FFFF	398000-39FFFF
SA116	1	1	1	0	1	0	0	64/32	740000-74FFFF	3A0000-3A7FFF
SA117	1	1	1	0	1	0	1	64/32	750000–75FFFF	3A8000–3AFFFF
SA118	1	1	1	0	1	1	0	64/32	760000–76FFFF	3B0000–3B7FFF
SA119	1	1	1	0	1	1	1	64/32	770000–77FFFF	3B8000–3BFFFF
SA120	1	1	1	1	0	0	0	64/32	780000–78FFFF	3C0000-3C7FFF
SA121	1	1	1	1	0	0	1	64/32	790000–79FFFF	3C8000–3CFFFF
SA122	1	1	1	1	0	1	0	64/32	7A0000–7AFFFF	3D0000-3D7FFF
SA123	1	1	1	1	0	1	1	64/32	7B0000–7BFFFF	3D8000–3DFFFF
SA124	1	1	1	1	1	0	0	64/32	7C0000-7CFFFF	3E0000-3E7FFF
SA125	1	1	1	1	1	0	1	64/32	7D0000–7DFFFF	3E8000–3EFFFF
SA126	1	1	1	1	1	1	0	64/32	7E0000–7EFFFF	3F0000-3F7FFF
SA127	1	1	1	1	1	1	1	64/32	7F0000–7FFFFF	3F8000–3FFFFF



Table I2. S29GL064M (Model R3) Top Boot Sector Addresses (Sheet I of 2)

Sector	A21–A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A21–A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA0	0000000xxx	64/32	000000h-00FFFFh	00000h-07FFFh	SA45	0101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh
SA1	0000001xxx	64/32	010000h-01FFFFh	08000h-0FFFFh	SA46	0101110xxx	64/32	2E0000h-2EFFFFh	170000h-177FFFh
SA2	0000010xxx	64/32	020000h-02FFFFh	10000h–17FFFh	SA47	01011111xxx	64/32	2F0000h-2FFFFFh	178000h-17FFFFh
SA3	0000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA48	0110000xxx	64/32	300000h-30FFFFh	180000h-187FFFh
SA4	0000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA49	0110001xxx	64/32	310000h-31FFFFh	188000h-18FFFFh
SA5	0000101xxx	64/32	050000h-05FFFFh	28000h–2FFFFh	SA50	0110010xxx	64/32	320000h-32FFFFh	190000h-197FFFh
SA6	0000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA51	0110011xxx	64/32	330000h-33FFFFh	198000h-19FFFFh
SA7	0000111xxx	64/32	070000h-07FFFFh	38000h–3FFFFh	SA52	0100100xxx	64/32	340000h-34FFFFh	1A0000h-1A7FFFh
SA8	0001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA53	0110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh
SA9	0001001xxx	64/32	090000h-09FFFFh	48000h–4FFFFh	SA54	0110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA10	0001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA55	0110111xxx	64/32	370000h-37FFFFh	1B8000h-1BFFFFh
SA11	0001011xxx	64/32	0B0000h-0BFFFFh	58000h–5FFFFh	SA56	0111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA12	0001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh	SA57	0111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA13	0001101xxx	64/32	0D0000h-0DFFFFh	68000h-6FFFFh	SA58	0111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA14	0001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA59	0111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA15	0001111xxx	64/32	0F0000h-0FFFFFh	78000h–7FFFFh	SA60	0111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA16	0010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh	SA61	0111101xxx	64/32	3D0000h-3DFFFFh	1E8000h-1EFFFFh
SA17	0010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA62	0111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh
SA18	0010010xxx	64/32	120000h-12FFFFh	90000h–97FFFh	SA63	01111111xxx	64/32	3F0000h-3FFFFFh	1F8000h-1FFFFFh
SA19	0010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh	SA64	1000000xxx	64/32	400000h-40FFFFh	200000h-207FFFh
SA20	0010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh	SA65	1000001xxx	64/32	410000h-41FFFFh	208000h-20FFFFh
SA21	0010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh	SA66	1000010xxx	64/32	420000h-42FFFFh	210000h-217FFFh
SA22	0010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh	SA67	1000011xxx	64/32	430000h-43FFFFh	218000h-21FFFFh
SA23	0010111xxx	64/32	170000h-17FFFFh	B8000h-BFFFFh	SA68	1000100xxx	64/32	440000h-44FFFFh	220000h-227FFFh
SA24	0011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh	SA69	1000101xxx	64/32	450000h-45FFFFh	228000h-22FFFFh
SA25	0011001xxx	64/32	190000h-19FFFFh	C8000h-CFFFFh	SA70	1000110xxx	64/32	460000h-46FFFFh	230000h-237FFFh
SA26	0011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh	SA71	1000111xxx	64/32	470000h-47FFFFh	238000h-23FFFFh
SA27	0011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh	SA72	1001000xxx	64/32	480000h-48FFFFh	240000h-247FFFh
SA28	0011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh	SA73	1001001xxx	64/32	490000h-49FFFFh	248000h-24FFFFh
SA29	0011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh	SA74	1001010xxx	64/32		250000h-257FFFh
SA30	0011110xxx	64/32	1E0000h-1EFFFFh	F0000h-F7FFFh	SA75	1001011xxx	64/32	4B0000h-4BFFFFh	258000h-25FFFFh
SA31	0011111xxx	64/32	1F0000h-1FFFFFh	F8000h-FFFFFh	SA76	1001100xxx	64/32	4C0000h-4CFFFFh	260000h-267FFh
SA32	0100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA77	1001101xxx	64/32	4D0000h-4DFFFFh	268000h-26FFFFh
SA33	0100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA78	1001110xxx	64/32	4E0000h-4EFFFFh	270000h-277FFFh
SA34	0100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA79	1001111xxx	64/32	4F0000h–4FFFFFh	278000h-27FFFh
SA35	0101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh	SA80	1010000xxx	64/32	500000h-50FFFFh	280000h-28FFFFh
SA36	0100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh	SA81	1010001xxx	64/32	510000h-51FFFFh	288000h-28FFFFh
SA37	0100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh	SA82	1010010xxx	64/32	520000h-52FFFFh	290000h-297FFFh
SA38	0100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh	SA83	1010011xxx	64/32	530000h-53FFFFh	298000h-29FFFFh
SA39	0100111xxx	64/32	270000h-27FFFFh	138000h-13FFFFh	SA84	1010100xxx	64/32	540000h-54FFFFh	2A0000h-2A7FFFh
SA40	0101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh	SA85	1010101xxx	64/32	550000h-55FFFFh	2A8000h-2AFFFFh
SA41	0101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh	SA86	1010110xxx	64/32	560000h-56FFFFh	2B0000h-2B7FFFh
SA42	0101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh	SA87	1010111xxx	64/32	570000h-57FFFh	2B8000h-2BFFFFh
SA43	0101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh	SA88	1011000xxx	64/32	580000h-58FFFFh	2C0000h-2C7FFFh
SA44	0101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh	SA89	1011001xxx	64/32	590000h-59FFFFh	2C8000h-2CFFFFh



Table I2. S29GL064M (Model R3) Top Boot Sector Addresses (Sheet 2 of 2)

Sector	A21-A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A21–A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA90	1011010xxx	64/32	5A0000h-5AFFFFh	2D0000h-2D7FFFh	SA113	1110001xxx	64/32	710000h–71FFFFh	388000h-38FFFFh
SA91	1011011xxx	64/32	5B0000h-5BFFFFh	2D8000h-2DFFFFh	SA114	1110010xxx	64/32	720000h-72FFFFh	390000h-397FFFh
SA92	1011100xxx	64/32	5C0000h-5CFFFFh	2E0000h-2E7FFFh	SA115	1110011xxx	64/32	730000h-73FFFFh	398000h-39FFFFh
SA93	1011101xxx	64/32	5D0000h-5DFFFFh	2E8000h-2EFFFFh	SA116	1110100xxx	64/32	740000h-74FFFFh	3A0000h-3A7FFFh
SA94	1011110xxx	64/32	5E0000h-5EFFFFh	2F0000h-2FFFFFh	SA117	1110101xxx	64/32	750000h-75FFFFh	3A8000h-3AFFFFh
SA95	10111111xxx	64/32	5F0000h-5FFFFFh	2F8000h-2FFFFFh	SA118	1110110xxx	64/32	760000h-76FFFFh	3B0000h-3B7FFFh
SA96	1100000xxx	64/32	600000h-60FFFFh	300000h-307FFFh	SA119	11101111xxx	64/32	770000h-77FFFFh	3B8000h-3BFFFFh
SA97	1100001xxx	64/32	610000h-61FFFFh	308000h-30FFFFh	SA120	1111000xxx	64/32	780000h-78FFFFh	3C0000h-3C7FFFh
SA98	1100010xxx	64/32	620000h-62FFFFh	310000h-317FFFh	SA121	1111001xxx	64/32	790000h-79FFFFh	3C8000h-3CFFFFh
SA99	1100011xxx	64/32	630000h-63FFFFh	318000h-31FFFFh	SA122	1111010xxx	64/32	7A0000h–7AFFFFh	3D0000h-3D7FFFh
SA100	1100100xxx	64/32	640000h-64FFFFh	320000h-327FFFh	SA123	1111011xxx	64/32	7B0000h–7BFFFFh	3D8000h-3DFFFFh
SA101	1100101xxx	64/32	650000h-65FFFFh	328000h-32FFFFh	SA124	1111100xxx	64/32	7C0000h-7CFFFFh	3E0000h-3E7FFFh
SA102	1100110xxx	64/32	660000h-66FFFFh	330000h-337FFFh	SA125	1111101xxx	64/32	7D0000h-7DFFFFh	3E8000h-3EFFFFh
SA103	1100111xxx	64/32	670000h-67FFFh	338000h-33FFFFh	SA126	1111110xxx	64/32	7E0000h–7EFFFFh	3F0000h-3F7FFFh
SA104	1101000xxx	64/32	680000h-68FFFFh	340000h-347FFFh	SA127	1111111000	8/4	7F0000h-7F1FFFh	3F8000h-3F8FFFh
SA105	1101001xxx	64/32	690000h-69FFFFh	348000h-34FFFFh	SA128	1111111001	8/4	7F2000h-7F3FFFh	3F9000h-3F9FFFh
SA106	1101010xxx	64/32	6A0000h-6AFFFFh	350000h-357FFFh	SA129	1111111010	8/4	7F4000h-7F5FFFh	3FA000h-3FAFFFh
SA107	1101011xxx	64/32	6B0000h-6BFFFFh	358000h-35FFFFh	SA130	1111111011	8/4	7F6000h-7F7FFFh	3FB000h-3FBFFFh
SA108	1101100xxx	64/32	6C0000h-6CFFFFh	360000h-367FFFh	SA131	1111111100	8/4	7F8000h-7F9FFFh	3FC000h-3FCFFFh
SA109	1101101xxx	64/32	6D0000h-6DFFFFh	368000h-36FFFFh	SA132	1111111101	8/4	7FA000h-7FBFFFh	3FD000h-3FDFFFh
SA110	1101110xxx	64/32	6E0000h-6EFFFFh	370000h-377FFFh	SA133	1111111110	8/4	7FC000h-7FDFFFh	3FE000h-3FEFFFh
SA111	11011111xxx	64/32	6F0000h-6FFFFFh	378000h-37FFFFh	SA134	1111111111	8/4	7FE000h–7FFFFFh	3FF000h-3FFFFFh
SA112	1110000xxx	64/32	700000h-70FFFh	380000h-387FFFh					

<sup>\*</sup> Sector sizes are given in Kbytes/Kwords.



Table I3. S29GL064M (Model R4) Bottom Boot Sector Addresses (Sheet I of 2)

Sector	A21-A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A21-A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA0	0000000000	8/4	000000h-001FFFh	00000h-00FFFh	SA45	0100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh
SA1	000000001	8/4	002000h-003FFFh	01000h-01FFFh	SA46	0100111xxx	64/32	270000h-27FFFh	138000h-13FFFFh
SA2	000000010	8/4	004000h-005FFFh	02000h-02FFFh	SA47	0101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh
SA3	000000011	8/4	006000h-007FFFh	03000h-03FFFh	SA48	0101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh
SA4	000000100	8/4	008000h-009FFFh	04000h-04FFFh	SA49	0101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh
SA5	000000101	8/4	00A000h-00BFFFh	05000h-05FFFh	SA50	0101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh
SA6	0000000110	8/4	00C000h-00DFFFh	06000h-06FFFh	SA51	0101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh
SA7	0000000111	8/4	00E000h-00FFFFh	07000h-07FFFh	SA52	0101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh
SA8	0000001xxx	64/32	010000h-01FFFFh	08000h–0FFFFh	SA53	0101110xxx	64/32	2E0000h-2EFFFFh	170000h–177FFFh
SA9	0000010xxx	64/32	020000h-02FFFFh	10000h-17FFFh	SA54	01011111xxx	64/32	2F0000h–2FFFFFh	178000h–17FFFFh
SA10	0000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA55	0110000xxx	64/32	300000h-30FFFFh	180000h-187FFFh
SA11	0000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA56	0110001xxx	64/32	310000h-31FFFFh	188000h-18FFFFh
SA12	0000101xxx	64/32	050000h-05FFFFh	28000h-2FFFFh	SA57	0110010xxx	64/32	320000h-32FFFFh	190000h-197FFFh
SA13	0000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA58	0110011xxx	64/32	330000h-33FFFFh	198000h-19FFFFh
SA14	0000111xxx	64/32	070000h-07FFFh	38000h-3FFFFh	SA59	0100100xxx	64/32	340000h-34FFFFh	1A0000h-1A7FFFh
SA15	0001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA60	0110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh
SA16	0001001xxx	64/32	090000h-09FFFFh	48000h–4FFFFh	SA61	0110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA17	0001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA62	0110111xxx	64/32	370000h-37FFFFh	1B8000h-1BFFFFh
SA18	0001011xxx	64/32	0B0000h-0BFFFFh	58000h-5FFFFh	SA63	0111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA19	0001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh	SA64	0111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA20	0001101xxx	64/32	0D0000h-0DFFFFh	68000h-6FFFFh	SA65	0111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA21	0001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA66	0111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA22	0001111xxx	64/32	0F0000h-0FFFFh	78000h–7FFFFh	SA67	0111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA23	0010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh	SA68	0111101xxx	64/32	3D0000h-3DFFFFh	1E8000h-1EFFFFh
SA24	0010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA69	0111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh
SA25	0010010xxx	64/32	120000h-12FFFFh	90000h-97FFFh	SA70	01111111xxx	64/32	3F0000h-3FFFFFh	1F8000h–1FFFFFh
SA26	0010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh	SA71	1000000xxx	64/32	400000h-40FFFFh	200000h-207FFFh
SA27	0010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh	SA72	1000001xxx	64/32	410000h-41FFFFh	208000h-20FFFFh
SA28	0010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh	SA73	1000010xxx	64/32	420000h-42FFFFh	210000h-217FFFh
SA29	0010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh	SA74	1000011xxx	64/32	430000h-43FFFFh	218000h-21FFFFh
SA30	0010111xxx	64/32	170000h-17FFFFh	B8000h-BFFFFh	SA75	1000100xxx	64/32	440000h-44FFFFh	220000h-227FFFh
SA31	0011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh	SA76	1000101xxx	64/32	450000h-45FFFFh	228000h-22FFFFh
SA32	0011001xxx	64/32	190000h-19FFFFh	C8000h-CFFFFh	SA77	1000110xxx	64/32	460000h-46FFFFh	230000h-237FFFh
SA33	0011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh	SA78	1000111xxx	64/32	470000h-47FFFFh	238000h-23FFFFh
SA34	0011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh	SA79	1001000xxx	64/32	480000h-48FFFFh	240000h-247FFFh
SA35	0011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh	SA80	1001001xxx	64/32	490000h-49FFFFh	248000h-24FFFFh
SA36	0011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh	SA81	1001010xxx	64/32	4A0000h-4AFFFFh	250000h-257FFFh
SA37	0011110xxx	64/32	1E0000h-1EFFFFh	F0000h-F7FFFh	SA82	1001011xxx	64/32	4B0000h-4BFFFFh	258000h-25FFFFh
SA38	00111111xxx	64/32	1F0000h-1FFFFFh	F8000h–FFFFFh	SA83	1001100xxx	64/32	4C0000h-4CFFFFh	260000h-267FFFh
SA39	0100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA84	1001101xxx	64/32	4D0000h-4DFFFFh	268000h-26FFFFh
SA40	0100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA85	1001110xxx	64/32	4E0000h-4EFFFFh	270000h-277FFFh
SA41	0100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA86	1001111xxx	64/32	4F0000h-4FFFFFh	278000h-27FFFh
SA42	0101011xxx	64/32	230000h-23FFFFh	118000h–11FFFFh	SA87	1010000xxx	64/32	500000h-50FFFFh	280000h-28FFFFh
SA43	0100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh	SA88	1010001xxx	64/32	510000h-51FFFFh	288000h-28FFFFh
SA44	0100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh	SA89	1010010xxx	64/32	520000h-52FFFFh	290000h-297FFFh



Table 13. S29GL064M (Model R4) Bottom Boot Sector Addresses (Sheet 2 of 2)

Sector	A21-A12	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A21-A12	Sector Size*	8-bit Address Range	16-bit Address Range
SA90	1010011xxx	64/32	530000h-53FFFFh	298000h-29FFFFh	SA113	1101010xxx	64/32	6A0000h-6AFFFFh	350000h-357FFFh
SA91	1010100xxx	64/32	540000h-54FFFFh	2A0000h-2A7FFFh	SA114	1101011xxx	64/32	6B0000h-6BFFFFh	358000h-35FFFFh
SA92	1010101xxx	64/32	550000h-55FFFFh	2A8000h–2AFFFFh	SA115	1101100xxx	64/32	6C0000h-6CFFFFh	360000h-367FFFh
SA93	1010110xxx	64/32	560000h-56FFFFh	2B0000h-2B7FFFh	SA116	1101101xxx	64/32	6D0000h-6DFFFFh	368000h-36FFFFh
SA94	1010111xxx	64/32	570000h-57FFFh	2B8000h-2BFFFFh	SA117	1101110xxx	64/32	6E0000h-6EFFFFh	370000h-377FFFh
SA95	1011000xxx	64/32	580000h-58FFFFh	2C0000h-2C7FFFh	SA118	11011111xxx	64/32	6F0000h-6FFFFFh	378000h-37FFFFh
SA96	1011001xxx	64/32	590000h-59FFFFh	2C8000h-2CFFFFh	SA119	1110000xxx	64/32	700000h-70FFFFh	380000h-387FFFh
SA97	1011010xxx	64/32	5A0000h-5AFFFFh	2D0000h-2D7FFFh	SA120	1110001xxx	64/32	710000h–71FFFFh	388000h-38FFFFh
SA98	1011011xxx	64/32	5B0000h-5BFFFFh	2D8000h-2DFFFFh	SA121	1110010xxx	64/32	720000h-72FFFFh	390000h-397FFFh
SA99	1011100xxx	64/32	5C0000h-5CFFFFh	2E0000h-2E7FFh	SA122	1110011xxx	64/32	730000h–73FFFFh	398000h-39FFFFh
SA100	1011101xxx	64/32	5D0000h-5DFFFFh	2E8000h-2EFFFFh	SA123	1110100xxx	64/32	740000h-74FFFFh	3A0000h-3A7FFFh
SA101	1011110xxx	64/32	5E0000h-5EFFFFh	2F0000h–2FFFFFh	SA124	1110101xxx	64/32	750000h-75FFFFh	3A8000h-3AFFFFh
SA102	10111111xxx	64/32	5F0000h-5FFFFFh	2F8000h–2FFFFFh	SA125	1110110xxx	64/32	760000h-76FFFFh	3B0000h-3B7FFFh
SA103	1100000xxx	64/32	600000h-60FFFFh	300000h-307FFFh	SA126	1110111xxx	64/32	770000h–77FFFFh	3B8000h-3BFFFFh
SA104	1100001xxx	64/32	610000h-61FFFFh	308000h-30FFFFh	SA127	1111000xxx	64/32	780000h–78FFFFh	3C0000h-3C7FFFh
SA105	1100010xxx	64/32	620000h-62FFFFh	310000h-317FFFh	SA128	1111001xxx	64/32	790000h-79FFFFh	3C8000h-3CFFFFh
SA106	1100011xxx	64/32	630000h-63FFFFh	318000h-31FFFFh	SA129	1111010xxx	64/32	7A0000h–7AFFFFh	3D0000h-3D7FFFh
SA107	1100100xxx	64/32	640000h-64FFFFh	320000h-327FFFh	SA130	1111011xxx	64/32	7B0000h–7BFFFFh	3D8000h-3DFFFFh
SA108	1100101xxx	64/32	650000h-65FFFFh	328000h-32FFFFh	SA131	1111100xxx	64/32	7C0000h-7CFFFFh	3E0000h-3E7FFFh
SA109	1100110xxx	64/32	660000h-66FFFFh	330000h-337FFFh	SA132	1111101xxx	64/32	7D0000h-7DFFFFh	3E8000h-3EFFFFh
SA110	1100111xxx	64/32	670000h-67FFFh	338000h-33FFFFh	SA133	1111110xxx	64/32	7E0000h–7EFFFFh	3F0000h-3F7FFFh
SA111	1101000xxx	64/32	680000h-68FFFFh	340000h-347FFFh	SA134	1111111000	64/32	7F0000h–7FFFFFh	3F8000h-3FFFFFh
SA112	1101001xxx	64/32	690000h-69FFFFh	348000h-34FFFFh	•				

<sup>\*</sup> Sector sizes are given in Kbytes/Kwords.



Table I4. S29GL064M (Model R5, R6, R7) Sector Addresses

Sector	A21-A15	16-bit Address Range	Sector	A21–A15	16-bit Address Range	Sector	A21–A15	16-bit Address Range
SA0	0000000	000000-007FFF	SA43	0 1 0 1 0 1 1	158000-15FFFF	SA86	1 0 1 0 1 1	0 2B0000–2B7FFF
SA1	0 0 0 0 0 0 1	008000-00FFFF	SA44	0 1 0 1 1 0 0	160000-167FFF	SA87	1 0 1 0 1 1	1 2B8000–2BFFFF
SA2	0 0 0 0 0 1 0	010000-017FFF	SA45	0 1 0 1 1 0 1	168000-16FFFF	SA88	1 0 1 1 0 0	0 2C0000–2C7FFF
SA3	0 0 0 0 0 1 1	018000-01FFFF	SA46	0 1 0 1 1 1 0	170000-177FFF	SA89	1 0 1 1 0 0	1 2C8000–2CFFFF
SA4	0 0 0 0 1 0 0	020000-027FFF	SA47	0 1 0 1 1 1 1	178000-17FFFF	SA90	1 0 1 1 0 1	0 2D0000–2D7FFF
SA5	0 0 0 0 1 0 1	028000-02FFFF	SA48	0 1 1 0 0 0 0	180000-187FFF	SA91	1 0 1 1 0 1	1 2D8000–2DFFFF
SA6	0 0 0 0 1 1 0	030000-037FFF	SA49	0 1 1 0 0 0 1	188000-18FFFF	SA92	1 0 1 1 1 0	0 2E0000–2E7FFF
SA7	0 0 0 0 1 1 1	038000-03FFFF	SA50	0 1 1 0 0 1 0	190000-197FFF	SA93	1 0 1 1 1 0	1 2E8000–2EFFFF
SA8	0 0 0 1 0 0 0	040000-047FFF	SA51	0 1 1 0 0 1 1	198000-19FFFF	SA94	1 0 1 1 1 1	0 2F0000–2F7FFF
SA9	0 0 0 1 0 0 1	048000-04FFFF	SA52	0 1 1 0 1 0 0	1A0000-1A7FFF	SA95	1 0 1 1 1 1	1 2F8000–2FFFFF
SA10	0 0 0 1 0 1 0	050000-057FFF	SA53	0 1 1 0 1 0 1	1A8000-1AFFFF	SA96	1 1 0 0 0 0	0 300000–307FFF
SA11	0 0 0 1 0 1 1	058000-05FFFF	SA54	0 1 1 0 1 1 0	1B0000-1B7FFF	SA97	1 1 0 0 0 0	1 308000–30FFFF
SA12	0 0 0 1 1 0 0	060000-067FFF	SA55	0 1 1 0 1 1 1	1B8000-1BFFFF	SA98	1 1 0 0 0 1	0 310000–317FFF
SA13	0 0 0 1 1 0 1	068000-06FFFF	SA56	0 1 1 1 0 0 0	1C0000-1C7FFF	SA99	1 1 0 0 0 1	1 318000–31FFFF
SA14	0 0 0 1 1 1 0	070000-077FFF	SA57	0 1 1 1 0 0 1	1C8000-1CFFFF	SA100	1 1 0 0 1 0	0 320000–327FFF
SA15	0 0 0 1 1 1 1	078000-07FFFF	SA58	0 1 1 1 0 1 0	1D0000-1D7FFF	SA101	1 1 0 0 1 0	1 328000–32FFFF
SA16	0 0 1 0 0 0 0	080000-087FFF	SA59	0 1 1 1 0 1 1	1D8000-1DFFFF	SA102	1 1 0 0 1 1	0 330000–337FFF
SA17	0 0 1 0 0 0 1	088000-08FFFF	SA60	0 1 1 1 1 0 0	1E0000-1E7FFF	SA103	1 1 0 0 1 1	1 338000–33FFFF
SA18	0 0 1 0 0 1 0	090000-097FFF	SA61	0 1 1 1 1 0 1	1E8000-1EFFFF	SA104	1 1 0 1 0 0	0 340000–347FFF
SA19	0 0 1 0 0 1 1	098000-09FFFF	SA62	0 1 1 1 1 1 0	1F0000-1F7FFF	SA105	1 1 0 1 0 0	1 348000–34FFFF
SA20	0 0 1 0 1 0 0	0A0000-0A7FFF	SA63	0 1 1 1 1 1 1	1F8000–1FFFFF	SA106	1 1 0 1 0 1	0 350000–357FFF
SA21	0 0 1 0 1 0 1	0A8000-0AFFFF	SA64	10000000	200000-207FFF	SA107	1 1 0 1 0 1	1 358000–35FFFF
SA22	0 0 1 0 1 1 0	0B0000-0B7FFF	SA65	1 0 0 0 0 0 1	208000-20FFFF	SA108	1 1 0 1 1 0	0 360000–367FFF
SA23	0 0 1 0 1 1 1	0B8000-0BFFFF	SA66	1 0 0 0 0 1 0	210000-217FFF	SA109	1 1 0 1 1 0	
SA24	0 0 1 1 0 0 0	0C0000-0C7FFF	SA67	1 0 0 0 0 1 1	218000–21FFFF	SA110	1 1 0 1 1 1	0 370000–377FFF
SA25	0 0 1 1 0 0 1	0C8000-0CFFFF	SA68	1 0 0 0 1 0 0	220000–227FFF	SA111	1 1 0 1 1 1	1 378000–37FFFF
SA26	0 0 1 1 0 1 0	0D0000-0D7FFF	SA69	1 0 0 0 1 0 1	228000-22FFFF	SA112	1 1 1 0 0 0	0 380000–387FFF
SA27	0 0 1 1 0 1 1	0D8000-0DFFFF	SA70	1 0 0 0 1 1 0	230000–237FFF	SA113	1 1 1 0 0 0	1 388000–38FFFF
SA28	0 0 1 1 1 0 0	0E0000-0E7FFF	SA71	1 0 0 0 1 1 1	238000–23FFFF	SA114	1 1 1 0 0 1	0 390000–397FFF
SA29	0 0 1 1 1 0 1	0E8000-0EFFFF	SA72	1 0 0 1 0 0 0	240000-247FFF	SA115	1 1 1 0 0 1	
SA30	0 0 1 1 1 1 0		SA73	1 0 0 1 0 0 1	248000-24FFFF	SA116	1 1 1 0 1 0	0 3A0000–3A7FFF
SA31	0 0 1 1 1 1 1			1 0 0 1 0 1 0	250000-257FFF	SA117	1 1 1 0 1 0	1 3A8000–3AFFFF
SA32	0 1 0 0 0 0 0			1 0 0 1 0 1 1	258000-25FFFF	SA118	1 1 1 0 1 1	0 3B0000–3B7FFF
SA33	0 1 0 0 0 0 1			1 0 0 1 1 0 0	260000-267FFF	SA119	1 1 1 0 1 1	
SA34	0 1 0 0 0 1 0			1 0 0 1 1 0 1	268000-26FFFF	SA120	1 1 1 1 0 0	
SA35	0 1 0 0 0 1 1			1 0 0 1 1 1 0	270000-277FFF	SA121	1 1 1 1 0 0	
SA36	0 1 0 0 1 0 0	120000–127FFF	SA79	1 0 0 1 1 1 1	278000-27FFFF	SA122	1 1 1 1 0 1	
SA37	0 1 0 0 1 0 1		SA80	1010000	280000-287FFF	SA123	1 1 1 1 0 1	
SA38	0 1 0 0 1 1 0		SA81	1 0 1 0 0 0 1	288000-28FFFF	SA124	1 1 1 1 1 0	
SA39	0 1 0 0 1 1 1	138000–13FFFF	SA82	1 0 1 0 0 1 0	290000-297FFF	SA125	1 1 1 1 1 0	1 3E8000–3EFFFF
SA40	0 1 0 1 0 0 0	140000–147FFF	SA83	1 0 1 0 0 1 1	298000–29FFFF	SA126	1 1 1 1 1 1	0 3F0000–3F7FFF
SA41	0 1 0 1 0 0 1			1 0 1 0 1 0 0	2A0000-2A7FFF	SA127	1 1 1 1 1 1	1 3F8000–3FFFFF
SA42	0 1 0 1 0 1 0	150000–157FFF	SA85	1 0 1 0 1 0 1	2A8000-2AFFFF			



Table I5. S29GLI28M Sector Address Table (Sheet I of 3)

ector	A22-A15	Sector Size*	8-bit Address	16-bit Address	ector	A22–A15	Sector Size*	8-bit Address	16-bit Address
SA0	00000000		Range	Range	<b>ن</b> SA41	00101001	64/32	Range 290000–29FFFF	Range
	00000001		000000-00FFFF 010000-01FFFF	000000-007FFF		00101010			148000–14FFFF
SA1				008000-00FFFF	SA42			2A0000–2AFFFF	150000–157FFF
SA2	00000010		020000-02FFFF	010000-017FF	SA43	00101011	64/32	2B0000-2BFFFF	158000–15FFFF
SA3	00000011		030000–03FFFF	018000–01FFFF	SA44	00101100		2C0000–2CFFFF	160000–167FFF
SA4	00000100		040000–04FFFF	020000-027FFF	SA45	00101101	64/32	2D0000–2DFFFF	168000–16FFFF
SA5	00000101		050000–05FFFF	028000-02FFFF	SA46	00101110		2E0000–2EFFFF	170000–177FFF
SA6	00000110		060000-06FFFF	030000-037FFF	SA47	00101111	64/32	2F0000–2FFFFF	178000–17FFFF
SA7	00000111		070000-07FFFF	038000-03FFFF	SA48	00110000	64/32	300000-30FFFF	180000–187FFF
SA8	00001000		080000–08FFFF	040000-047FFF	SA49	00110001	64/32	310000–31FFFF	188000–18FFFF
SA9	00001001	64/32	090000-09FFFF	048000-04FFFF	SA50	00110010	64/32	320000-32FFFF	190000–197FFF
SA10	00001010	64/32	OAOOOO-OAFFFF	050000–057FFF	SA51	0 0 1 1 0 0 1 1	64/32	330000–33FFFF	198000–19FFFF
SA11	00001011	64/32	OBOOOO-OBFFFF	058000-05FFFF	SA52	00110100	64/32	340000-34FFFF	1A0000-1A7FFF
SA12	00001100	64/32	OCOOOO-OCFFFF	060000-067FFF	SA53	0 0 1 1 0 1 0 1	64/32	350000-35FFFF	1A8000–1AFFFF
SA13	00001101	64/32	ODOOOO-ODFFFF	068000-06FFFF	SA54	0 0 1 1 0 1 1 0	64/32	360000-36FFFF	1B0000-1B7FFF
SA14	00001110	64/32	OEOOOO-OEFFFF	070000-077FFF	SA55	0 0 1 1 0 1 1 1	64/32	370000-37FFFF	1B8000–1BFFFF
SA15	00001111	64/32	OFOOOO-OFFFFF	078000-07FFFF	SA56	0 0 1 1 1 0 0 0	64/32	380000–38FFFF	1C0000-1C7FFF
SA16	0001000	64/32	100000-10FFFF	080000-087FFF	SA57	0 0 1 1 1 0 0 1	64/32	390000-39FFFF	1C8000-1CFFFF
SA17	00010001	64/32	110000-11FFFF	088000-08FFFF	SA58	0 0 1 1 1 0 1 0	64/32	3A0000-3AFFFF	1D0000-1D7FFF
SA18	00010010	64/32	120000-12FFFF	090000-097FFF	SA59	0 0 1 1 1 0 1 1	64/32	3B0000-3BFFFF	1D8000–1DFFFF
SA19	00010011	64/32	130000–13FFFF	098000-09FFFF	SA60	0 0 1 1 1 1 0 0	64/32	3C0000-3CFFFF	1E0000-1E7FFF
SA20	00010100	64/32	140000-14FFFF	0A0000-0A7FFF	SA61	0 0 1 1 1 1 0 1	64/32	3D0000-3DFFFF	1E8000–1EFFFF
SA21	00010101	64/32	150000-15FFFF	0A8000-0AFFFF	SA62	0 0 1 1 1 1 1 0	64/32	3E0000-3EFFFF	1F0000-1F7FFF
SA22	00010110	64/32	160000-16FFFF	0B0000-0B7FFF	SA63	0 0 1 1 1 1 1 1	64/32	3F0000-3FFFFF	1F8000–1FFFFF
SA23	00010111	64/32	170000-17FFFF	OB8000-OBFFFF	SA64	0 1 0 0 0 0 0 0	64/32	400000-40FFFF	200000-207FFF
SA24	00011000	64/32	180000–18FFFF	0C0000-0C7FFF	SA65	01000001	64/32	410000-41FFFF	208000-20FFFF
SA25	00011001	64/32	190000-19FFFF	0C8000-0CFFFF	SA66	01000010	64/32	420000-42FFFF	210000-217FFF
SA26	00011010	64/32	1A0000-1AFFFF	0D0000-0D7FFF	SA67	0 1 0 0 0 0 1 1	64/32	430000-43FFFF	218000–21FFFF
SA27	00011011	64/32	1B0000-1BFFFF	0D8000-0DFFFF	SA68	01000100	64/32	440000-44FFFF	220000-227FFF
	00011100		1C0000-1CFFFF	0E0000-0E7FFF		0 1 0 0 0 1 0 1		450000-45FFFF	228000–22FFFF
SA29	00011101	64/32	1D0000-1DFFFF	0E8000-0EFFFF	SA70	0 1 0 0 0 1 1 0	64/32	460000-46FFFF	230000-237FFF
SA30	00011110	64/32	1E0000-1EFFFF	OFOOOO-OF7FFF	SA71	0 1 0 0 0 1 1 1	64/32	470000–47FFF	238000–23FFFF
SA31	0 0 0 1 1 1 1 1	64/32	1F0000-1FFFFF	OF8000-OFFFFF	SA72	01001000	64/32	480000–48FFFF	240000-247FFF
SA32	0010000	64/32	200000-20FFFF	100000-107FFF	SA73	01001001	64/32	490000-49FFFF	248000–24FFFF
SA33	00100001	64/32	210000–21FFFF	108000-10FFFF	SA74	01001010	64/32	4A0000–4AFFFF	250000–257FFF
	00100010		220000-22FFFF	110000–117FFF	SA75	0 1 0 0 1 0 1 1	64/32	4B0000–4BFFFF	258000–25FFFF
SA35	00100011	64/32	230000–23FFFF	118000–11FFFF	SA76	01001100	64/32	4C0000-4CFFFF	260000–267FFF
SA36	00100100	64/32	240000–24FFFF	120000–127FFF	SA77	01001101	64/32	4D0000–4DFFFF	268000–26FFFF
SA37	00100101		250000–25FFFF	128000–12FFFF		0 1 0 0 1 1 1 0		4E0000–4EFFFF	270000–277FFF
SA38	00100110		260000–26FFFF	130000–137FFF		0 1 0 0 1 1 1 1		4F0000–4FFFF	278000–27FFF
	00100111		270000–27FFF	138000–13FFFF		01010000		500000-50FFFF	280000–287FFF
	00101000		280000–28FFFF	140000–147FFF		01010001		510000–51FFFF	288000–28FFFF
	1 1 - 1 1 1 - 1 1 9 9 9	02	20						



Table I5. S29GLI28M Sector Address Table (Sheet 2 of 3)

Sector	A22-A15	Sector Size*	8-bit Address Range	16-bit Address Range	Sector	A22-A15	Sector Size*	8-bit Address Range	16-bit Address Range
SA82	0 1 0 1 0 0 1 0	64/32	520000-52FFFF	290000-297FFF	SA158	1 0 0 1 1 1 1 0	64/32	9E0000-9EFFFF	4F0000-4F7FFF
SA83	0 1 0 1 0 0 1 1	64/32	530000-53FFFF	298000-29FFFF	SA159	10011111	64/32	9F0000-9FFFFF	4F8000–4FFFF
SA84	0 1 0 1 0 1 0 0	64/32	540000-54FFFF	2A0000-2A7FFF	SA160	10100000	64/32	A00000-A0FFFF	500000-507FFF
SA85	0 1 0 1 0 1 0 1	64/32	550000-55FFFF	2A8000-2AFFFF	SA161	10100001	64/32	A10000-A1FFFF	508000-50FFFF
SA86	0 1 0 1 0 1 1 0	64/32	560000-56FFFF	2B0000-2B7FFF	SA162	10100010	64/32	A20000-A2FFFF	510000-517FFF
SA87	0 1 0 1 0 1 1 1	64/32	570000-57FFF	2B8000-2BFFFF	SA163	1 0 1 0 0 0 1 1	64/32	A30000-A3FFFF	518000-51FFFF
SA88	0 1 0 1 1 0 0 0	64/32	580000-58FFFF	2C0000-2C7FFF	SA164	10100100	64/32	A40000-A4FFFF	520000-527FFF
SA89	0 1 0 1 1 0 0 1	64/32	590000-59FFFF	2C8000-2CFFFF	SA165	1 0 1 0 0 1 0 1	64/32	A50000-A5FFFF	528000-52FFFF
SA90	0 1 0 1 1 0 1 0	64/32	5A0000-5AFFFF	2D0000-2D7FFF	SA166	10100110	64/32	A60000–A6FFFF	530000-537FFF
SA91	0 1 0 1 1 0 1 1	64/32	5B0000-5BFFFF	2D8000-2DFFFF	SA167	1 0 1 0 0 1 1 1	64/32	A70000–A7FFFF	538000-53FFFF
SA92	0 1 0 1 1 1 0 0	64/32	5C0000-5CFFFF	2E0000-2E7FFF	SA168	10101000	64/32	A80000–A8FFFF	540000–547FFF
SA93	0 1 0 1 1 1 0 1	64/32	5D0000-5DFFFF	2E8000–2EFFFF	SA169	1 0 1 0 1 0 0 1	64/32	A90000–A9FFFF	548000–54FFFF
SA94	0 1 0 1 1 1 1 0	64/32	5E0000-5EFFFF	2F0000-2F7FFF	SA170	1 0 1 0 1 0 1 0	64/32	AA0000–AAFFFF	550000–557FFF
SA95	0 1 0 1 1 1 1 1	64/32	5F0000-5FFFFF	2F8000–2FFFFF	SA171	1 0 1 0 1 0 1 1	64/32	AB0000–ABFFFF	558000–55FFFF
SA96	0 1 1 0 0 0 0 0	64/32	600000-60FFFF	300000-307FFF	SA172	1 0 1 0 1 1 0 0	64/32	ACOOOO-ACFFFF	560000–567FFF
SA97	0 1 1 0 0 0 0 1	64/32	610000–61FFFF	308000-30FFFF	SA173	1 0 1 0 1 1 0 1	64/32	AD0000–ADFFFF	568000–56FFFF
SA98	0 1 1 0 0 0 1 0	64/32	620000–62FFFF	310000–317FFF	SA174	1 0 1 0 1 1 1 0	64/32	AE0000-AEFFFF	570000–577FFF
SA66	0 1 0 0 0 0 1 0	64/32	420000–42FFFF	210000–217FFF	SA175	1 0 1 0 1 1 1 1	64/32	AF0000-AFFFFF	578000–57FFFF
SA67	0 1 0 0 0 0 1 1	64/32	430000–43FFFF	218000–21FFFF	SA176	10110000	64/32	B00000-B0FFFF	580000–587FFF
SA136	1000100	64/32	880000–88FFFF	440000–447FFF	SA177	1 0 1 1 0 0 0 1	64/32	B10000-B1FFFF	588000–58FFFF
SA137	10001001	64/32	890000–89FFFF	448000–44FFFF	SA178	1 0 1 1 0 0 1 0	64/32	B20000-B2FFFF	590000–597FFF
SA138	10001010	64/32	8A0000-8AFFFF	450000–457FFF	SA179	10110011	64/32	B30000-B3FFFF	598000-59FFFF
SA139	10001011	64/32	8B0000-8BFFFF	458000–45FFFF	SA180	10110100	64/32	B40000-B4FFFF	5A0000-5A7FFF
SA140	10001100	64/32	8C0000-8CFFFF	460000–467FFF	SA181	10110101	64/32	B50000-B5FFFF	5A8000-5AFFFF
SA141	10001101	64/32	8D0000-8DFFFF	468000–46FFFF	SA182	10110110	64/32	B60000-B6FFFF	5B0000-5B7FFF
SA142	10001110	64/32	8E0000-8EFFFF	470000–477FFF	SA183	1011011	64/32	B70000-B7FFFF	5B8000-5BFFFF
SA143	100011111	64/32	8F0000-8FFFFF	478000–47FFFF	SA184	10111000	64/32	B80000-B8FFFF	5C0000-5C7FFF
	10010000		900000–90FFFF	480000–487FFF	SA185	10111001	64/32	B90000-B9FFFF	5C8000-5CFFFF
SA145	10010001	64/32	910000–91FFFF	488000–48FFFF	SA186	10111010	64/32	BA0000-BAFFFF	5D0000-5D7FFF
	10010010		920000–92FFFF	490000-497FFF	ļ	10111011		BB0000-BBFFFF	5D8000-5DFFFF
	10010011		930000–93FFFF	498000–49FFFF		10111100		BC0000-BCFFFF	5E0000-5E7FFF
	10010100		940000–94FFFF	4A0000–4A7FFF	SA189	10111101	64/32	BD0000-BDFFFF	5E8000-5EFFFF
	10010101		950000–95FFFF	4A8000–4AFFFF		1011110		BE0000-BEFFFF	5F0000-5F7FFF
	1001010		960000–96FFFF	4B0000-4B7FFF		1011111		BF0000-BFFFFF	5F8000-5FFFFF
	10010111		970000–97FFFF	4B8000–4BFFFF		1 1 0 0 0 0 0 0		C00000-C0FFFF	600000-607FFF
	10011000		980000–98FFFF	4C0000-4C7FFF	ļ	1 1 0 0 0 0 0 1		C10000-C1FFFF	608000-60FFFF
	10011001		990000–99FFFF	4C8000-4CFFFF		1 1 0 0 0 0 1 0		C20000–C2FFFF	610000–617FFF
	100110		9A0000–9AFFFF	4D0000–4D7FFF		1 1 0 0 0 0 1 1		C30000–C3FFFF	618000–61FFFF
	10011011		9B0000–9BFFFF	4D8000–4DFFFF		1 1 0 0 0 1 0 0		C40000–C4FFFF	620000–627FFF
	10011100		9C0000–9CFFFF	4E0000-4E7FFF		1 1 0 0 0 1 0 1		C50000–C5FFFF	628000–62FFFF
SA157	10011101	64/32	9D0000–9DFFFF	4E8000-4EFFFF	SA198	1 1 0 0 0 1 1 0	64/32	C60000–C6FFFF	630000–637FFF



Table I5. S29GLI28M Sector Address Table (Sheet 3 of 3)

Sector	A22-A15	Sector Size*	8-bit Address Range	16-bit Address Range	Sector		,	A22	2-	Α1	5		Sector Size*	8-bit Address Range	16-bit Address Range
SA199	1 1 0 0 0 1 1 1	64/32	C70000-C7FFFF	638000-63FFFF	SA228	1	1	1 (	0 (	0 1	0	0	64/32	E40000-E4FFFF	720000-727FFF
SA200	1 1 0 0 1 0 0 0	64/32	C80000-C8FFFF	640000-647FFF	SA229	1	1	1 (	0 (	0 1	0	1	64/32	E50000-E5FFFF	728000-72FFFF
SA201	1 1 0 0 1 0 0 1	64/32	C90000-C9FFFF	648000-64FFFF	SA230	1	1	1 (	0 (	0 1	1	0	64/32	E60000-E6FFFF	730000–737FFF
SA202	1 1 0 0 1 0 1 0	64/32	CA0000-CAFFFF	650000-657FFF	SA231	1	1	1 (	0 (	0 1	1 1	1	64/32	E70000-E7FFF	738000–73FFFF
SA203	1 1 0 0 1 0 1 1	64/32	CB0000-CBFFFF	658000-65FFFF	SA232	1	1	1 (	0	1 (	0	0	64/32	E80000-E8FFFF	740000-747FFF
SA204	1 1 0 0 1 1 0 0	64/32	CC0000-CCFFFF	660000-667FFF	SA233	1	1	1 (	0	1 (	0	1	64/32	E90000-E9FFFF	748000–74FFF
SA205	1 1 0 0 1 1 0 1	64/32	CD0000-CDFFFF	668000-66FFFF	SA234	1	1	1 (	0	1 (	) 1	0	64/32	EA0000-EAFFFF	750000–757FFF
SA206	1 1 0 0 1 1 1 0	64/32	CE0000-CEFFFF	670000-677FFF	SA235	1	1	1 (	0	1 (	) 1	1	64/32	EB0000-EBFFFF	758000–75FFFF
SA207	1 1 0 0 1 1 1 1	64/32	CF0000-CFFFFF	678000-67FFF	SA236	1	1	1 (	0	1 1	0	0	64/32	EC0000-ECFFFF	760000–767FFF
SA208	1 1 0 1 0 0 0 0	64/32	D00000-D0FFFF	680000-687FFF	SA237	1	1	1 (	0	1 1	0	1	64/32	ED0000-EDFFFF	768000–76FFFF
SA209	1 1 0 1 0 0 0 1	64/32	D10000-D1FFFF	688000-68FFFF	SA238	1	1	1 (	0	1 1	1	0	64/32	EE0000-EEFFFF	770000-777FFF
SA210	1 1 0 1 0 0 1 0	64/32	D20000-D2FFFF	690000-697FFF	SA239	1	1	1 (	0	1 1	1	1	64/32	EF0000-EFFFFF	778000–77FFF
SA211	1 1 0 1 0 0 1 1	64/32	D30000-D3FFFF	698000-69FFFF	SA240	1	1	1	1 (	0 0	0	0	64/32	F00000-F0FFFF	780000–787FFF
SA212	1 1 0 1 0 1 0 0	64/32	D40000-D4FFFF	6A0000-6A7FFF	SA241	1	1	1	1 (	0 0	0	1	64/32	F10000-F1FFFF	788000–78FFFF
SA213	1 1 0 1 0 1 0 1	64/32	D50000-D5FFFF	6A8000-6AFFFF	SA242	1	1	1	1 (	0 0	) 1	0	64/32	F20000-F2FFFF	790000–797FFF
SA214	1 1 0 1 0 1 1 0	64/32	D60000-D6FFFF	6B0000-6B7FFF	SA243	1	1	1	1 (	0 0	) 1	1	64/32	F30000-F3FFFF	798000–79FFFF
SA215	1 1 0 1 0 1 1 1	64/32	D70000-D7FFFF	6B8000-6BFFFF	SA244	1	1	1	1 (	0 1	0	0	64/32	F40000-F4FFFF	7A0000-7A7FFF
SA216	1 1 0 1 1 0 0 0	64/32	D80000-D8FFFF	6C0000-6C7FFF	SA245	1	1	1	1 (	0 1	0	1	64/32	F50000-F5FFFF	7A8000–7AFFFF
SA217	1 1 0 1 1 0 0 1	64/32	D90000-D9FFFF	6C8000-6CFFFF	SA246	1	1	1	1 (	0 1	1	0	64/32	F60000-F6FFFF	7B0000-7B7FFF
SA218	1 1 0 1 1 0 1 0	64/32	DA0000-DAFFFF	6D0000-6D7FFF	SA247	1	1	1	1 (	0 1	1	1	64/32	F70000-F7FFF	7B8000–7BFFFF
SA219	1 1 0 1 1 0 1 1	64/32	DB0000-DBFFFF	6D8000-6DFFFF	SA248	1	1	1	1	1 (	0	0	64/32	F80000-F8FFFF	7C0000-7C7FFF
SA220	1 1 0 1 1 1 0 0	64/32	DC0000-DCFFFF	6E0000-6E7FFF	SA249	1	1	1	1	1 (	0	1	64/32	F90000-F9FFFF	7C8000-7CFFFF
SA221	1 1 0 1 1 1 0 1	64/32	DD0000-DDFFFF	6E8000-6EFFFF	SA250	1	1	1	1	1 (	) 1	0	64/32	FA0000-FAFFFF	7D0000-7D7FFF
SA222	1 1 0 1 1 1 1 0	64/32	DE0000-DEFFFF	6F0000-6F7FFF	SA251	1	1	1	1	1 (	) 1	1	64/32	FB0000-FBFFFF	7D8000–7DFFFF
SA223	1 1 0 1 1 1 1 1	64/32	DF0000-DFFFFF	6F8000-6FFFFF	SA252	1	1	1	1	1 1	1 0	0	64/32	FC0000-FCFFFF	7E0000-7E7FFF
SA224	1 1 1 0 0 0 0 0	64/32	E00000-E0FFFF	700000-707FFF	SA253	1	1	1	1	1 1	1 0	1	64/32	FD0000-FDFFFF	7E8000-7EFFFF
SA225	1 1 1 0 0 0 0 1	64/32	E10000-E1FFFF	708000-70FFFF	SA254	1	1	1	1	1 1	1 1	0	64/32	FE0000-FEFFFF	7F0000-7F7FFF
SA226	1 1 1 0 0 0 1 0	64/32	E20000-E2FFFF	710000–717FFF	SA255	1	1	1	1	1 1	1 1	1	64/32	FF0000-FFFFFF	7F8000–7FFFF
SA227	1 1 1 0 0 0 1 1	64/32	E30000-E3FFFF	718000–71FFFF											

<sup>\*</sup> Sector sizes are given in Kbytes/Kwords.



Table I6. S29GL256M Sector Address Table (Sheet I of 6)

Sector	A23-A15	8-bit Address Range	16-bit Address Range	Sector	A23-	A15	8-bit Address Range	16-bit Address Range
SA0	0000000000	0000000-000FFFF	000000-007FFF	SA44	0 0 0 1 0	1 1 0 0	02C0000-02CFFFF	160000-167FFF
SA1	0000000001	0010000-001FFFF	008000-00FFFF	SA45	0 0 0 1 0	1 1 0 1	02D0000-02DFFFF	168000–16FFFF
SA2	000000010	0020000-002FFFF	010000-017FFF	SA46	0 0 0 1 0	1 1 1 0	02E0000-02EFFFF	170000-177FFF
SA3	0000000111	0030000-003FFFF	018000-01FFFF	SA47	0 0 0 1 0	1 1 1 1	02F0000-02FFFFF	178000–17FFFF
SA4	000000100	0040000-004FFFF	020000-027FFF	SA48	0 0 0 1 1	0000	0300000-030FFFF	180000–187FFF
SA5	000000101	0050000-005FFFF	028000-02FFFF	SA49	00011	0 0 0 1	0310000-031FFFF	188000–18FFFF
SA6	000000110	0060000-006FFFF	030000-037FFF	SA50	00011	0 0 1 0	0320000-032FFFF	190000–197FFF
SA7	000000111	0070000-007FFFF	038000-03FFFF	SA51	00011	0 0 1 1	0330000-033FFFF	198000–19FFFF
SA8	000001000	0080000-008FFFF	040000-047FFF	SA52	00011	0 1 0 0	0340000-034FFFF	1A0000-1A7FFF
SA9	000001001	0090000-009FFFF	048000-04FFFF	SA53	0 0 0 1 1	0 1 0 1	0350000-035FFFF	1A8000-1AFFFF
SA10	000001010	00A0000-00AFFFF	050000-057FFF	SA54	00011	0 1 1 0	0360000-036FFFF	1B0000-1B7FFF
SA11	000001011	00B0000-00BFFFF	058000-05FFFF	SA55	00011	0 1 1 1	0370000-037FFFF	1B8000–1BFFFF
SA12	0000011000	00C0000-00CFFFF	060000-067FFF	SA56	0 0 0 1 1	1 0 0 0	0380000-038FFFF	1C0000-1C7FFF
SA13	000001101	00D0000-00DFFFF	068000-06FFFF	SA57	0 0 0 1 1	1 0 0 1	0390000-039FFFF	1C8000-1CFFFF
SA14	000001110	00E0000-00EFFFF	070000-077FFF	SA58	0 0 0 1 1	1 0 1 0	03A0000-03AFFFF	1D0000-1D7FFF
SA15	0000011111	00F0000-00FFFFF	078000-07FFFF	SA59	0 0 0 1 1	1 0 1 1	03B0000-03BFFFF	1D8000–1DFFFF
SA16	000010000	0100000-010FFFF	080000-087FFF	SA60	0 0 0 1 1	1 1 0 0	03C0000-03CFFFF	1E0000-1E7FFF
SA17	000010001	0110000-011FFFF	088000-08FFFF	SA61	0 0 0 1 1	1 1 0 1	03D0000-03DFFFF	1E8000–1EFFFF
SA18	000010010	0120000-012FFFF	090000-097FFF	SA62	0 0 0 1 1	1 1 1 0	03E0000-03EFFFF	1F0000-1F7FFF
SA19	000010011	0130000-013FFFF	098000-09FFFF	SA63	0 0 0 1 1	1 1 1 1	03F0000-03FFFFF	1F8000–1FFFFF
SA20	000010100	0140000-014FFFF	0A0000-0A7FFF	SA64	0 0 1 0 0	0000	0400000-040FFFF	200000-207FFF
SA21	000010101	0150000-015FFFF	0A8000-0AFFFF	SA65	0 0 1 0 0	0001	0410000-041FFFF	208000-20FFFF
SA22	000010110	0160000-016FFFF	0B0000-0B7FFF	SA66	0 0 1 0 0	0 0 1 0	0420000-042FFFF	210000-217FFF
SA23	0000101111	0170000-017FFFF	0B8000-0BFFFF	SA67	0 0 1 0 0	0 0 1 1	0430000-043FFFF	218000–21FFFF
SA24	000011000	0180000-018FFFF	0C0000-0C7FFF	SA68	0 0 1 0 0	0 1 0 0	0440000-044FFFF	220000-227FFF
SA25	000011001	0190000-019FFFF	0C8000-0CFFFF	SA69	0 0 1 0 0	0 1 0 1	0450000-045FFFF	228000-22FFFF
SA26	000011010	01A0000-01AFFFF	0D0000-0D7FFF	SA70	0 0 1 0 0	0 1 1 0	0460000-046FFFF	230000-237FFF
SA27	000011011	01B0000-01BFFFF	0D8000-0DFFFF	SA71	0 0 1 0 0	0 1 1 1	0470000-047FFF	238000-23FFFF
SA28	000011100	01C0000-01CFFFF	0E0000-0E7FFF	SA72	00100	1000	0480000-048FFFF	240000-247FFF
SA29	000011101	01D0000-01DFFFF	0E8000-0EFFFF	SA73	00100			248000-24FFFF
SA30	0 0 0 0 1 1 1 1 0	01E0000-01EFFFF	0F0000-0F7FFF	SA74	0 0 1 0 0	1 0 1 0	04A0000-04AFFFF	250000-257FFF
SA31	0000111111	01F0000-01FFFFF	0F8000-0FFFFF	SA75	00100	1 0 1 1	04B0000-04BFFFF	258000-25FFFF
SA32	000100000	0200000-020FFFF	100000–107FFF	SA76	0 0 1 0 0	1 1 0 0	04C0000-04CFFFF	260000-267FFF
SA33	000100001	0210000-021FFFF	108000-10FFFF	SA77	0 0 1 0 0	++++	04D0000-04DFFFF	268000-26FFFF
SA34	0 0 0 1 0 0 0 1 0	0220000-022FFFF	110000–117FFF	SA78			04E0000-04EFFFF	270000-277FFF
SA35	0 0 0 1 0 0 0 1 1	0230000-023FFFF	118000–11FFFF	SA79	0 0 1 0 0		04F0000-04FFFFF	278000–27FFFF
SA36	0 0 0 1 0 0 1 0 0	0240000-024FFFF	120000–127FFF	SA80	0 0 1 0 1	0000	0500000-050FFFF	280000-287FFF
SA37	000100101	0250000-025FFFF	128000–12FFFF	SA81	0 0 1 0 1	0 0 0 1	0510000-051FFFF	288000–28FFFF
SA38	0 0 0 1 0 0 1 1 0	0260000-026FFFF	130000–137FFF	SA82	0 0 1 0 1	0 0 1 0	0520000-052FFFF	290000–297FFF
SA39	0 0 0 1 0 0 1 1 1	0270000-027FFFF	138000–13FFFF	SA83	0 0 1 0 1	+	0530000-053FFFF	298000–29FFFF
SA40	0 0 0 1 0 1 0 0	0280000-028FFFF	140000–147FFF	SA84	0 0 1 0 1		0540000-054FFFF	2A0000-2A7FFF
SA41	0 0 0 1 0 1 0 0 1	0290000-029FFFF	148000–14FFFF	SA85	0 0 1 0 1	0 1 0 1	0550000-055FFFF	2A8000-2AFFFF
SA42	000101010	02A0000-02AFFFF	150000–157FFF	SA86	0 0 1 0 1	++++	0560000-056FFFF	2B0000–2B7FFF
SA43	000101011	02B0000-02BFFFF	158000–15FFFF	SA87	0 0 1 0 1	0 1 1 1	0570000-057FFFF	2B8000–2BFFFF



Table I6. S29GL256M Sector Address Table (Sheet 2 of 6)

Sector	A23-A15	8-bit Address Range	16-bit Address Range	Sector			A2:	3-	-A1	5		8-bit Address Range	16-bit Address Range
SA88	001011000	0580000–058FFFF	2C0000-2C7FFF	SA133	0	1 (	O C	0	0	1 (	0 1	0850000-085FFFF	428000–42FFFF
SA89	001011001	0590000–059FFFF	2C8000-2CFFFF	SA134	0	1 (	) C	0	0	1	1 0	0860000-086FFFF	430000–437FFF
SA90	001011010	05A0000-05AFFFF	2D0000–2D7FFF	SA135	0	1 (	) C	0	0	1	1 1	0870000-087FFFF	438000–43FFFF
SA91	001011011	05B0000–05BFFFF	2D8000–2DFFFF	SA136	0	1 (	O C	0	) 1	0	0 0	0880000-088FFFF	440000-447FFF
SA92	001011100	05C0000-05CFFFF	2E0000-2E7FFF	SA137	0	1 (	0	0	1	0	0 1	0890000-089FFFF	448000–44FFFF
SA93	001011101	05D0000–05DFFFF	2E8000–2EFFFF	SA138	0	1 (	0	0	1	0	1 0	08A0000-08AFFFF	450000–457FFF
SA94	001011110	05E0000–05EFFFF	2F0000–2F7FFF	SA139	0	1 (	) C	0	1	0	1 1	08B0000-08BFFFF	458000–45FFFF
SA95	<u> </u>	05F0000–05FFFFF	2F8000–2FFFFF	SA140	ш	_	4	4	$\bot$	_	0 0	08C0000-08CFFFF	460000–467FFF
SA96	<del>                                     </del>	0600000–060FFFF	300000-307FFF	SA141	0	_	+	+				08D0000-08DFFFF	468000–46FFFF
SA97	<del>                                     </del>	0610000–061FFFF	308000–30FFFF	SA142	$\vdash$	4	_	4	_	_	1 0		470000–477FFF
SA98	<del>                                     </del>	0620000–062FFFF	310000–317FFF		0	+	+	+	+	_	+	08F0000-08FFFFF	478000–47FFFF
SA99	<del>                                     </del>	0630000–063FFFF	318000–31FFFF	SA144	ш	4	4	_	4	_	0 0		480000–487FFF
SA100		0640000–064FFFF	320000–327FFF	SA145	$\vdash$	_	+	+			) 1		488000–48FFFF
SA101	<del>                                     </del>	0650000-065FFFF	328000–32FFFF	SA146	ш	_	4	4	$\bot$	_	1 0		490000–497FFF
SA102	<del>                                     </del>	0660000-066FFFF	330000–337FFF		0	-	_	+	$\perp$	_	_	0930000-093FFFF	498000–49FFFF
SA103	<del>                                     </del>	0670000-067FFF	338000–33FFFF	SA148		_		4	1 0		0		4A0000-4A7FFF
SA104	<del></del>	0680000-068FFFF	340000–347FFF	SA149	$\vdash$	4	_	4	_	_	10	0950000-095FFFF	4A8000-4AFFFF
SA105	<del></del>	0690000–069FFFF 06A0000–06AFFFF	348000–34FFFF 350000–357FFF	SA150 SA151	0	_		4	Ļ	_			4B0000-4B7FFF
SA106 SA107	+++++++++	06B0000-06BFFFF	358000–357FFF 358000–35FFFF	SA151	$\vdash$	+	+	+	+	_	0 0		4B8000–4BFFFF 4C0000–4C7FFF
SA107	<del></del>	06C0000-06CFFFF	36000–35FFF 360000–367FFF	SA152	$\vdash$	_	+	+	+	_	0 1		4C8000-4C7FFF
SA109	+++++++++	06D0000-06DFFFF	368000–36FFFF	SA153	$\vdash$	_	+	+			1 0		4D0000-4D7FFF
SA110	<del></del>	06E0000-06EFFFF	370000–377FFF	SA155	$\vdash$	4	_	4	_	_	1 1	09B0000-09BFFFF	4D8000-4DFFFF
SA111	+++++++++	06F0000-06FFFFF	378000–37FFFF	SA156	$\vdash$	+	+	+	+	_	0 0		4E0000-4E7FFF
SA112	<del></del>	0700000–070FFFF	380000–387FFF	SA157	$\vdash$	4	_	4	1 1	_		09D0000-09DFFFF	4E8000–4EFFFF
SA113	<del>                                     </del>	0710000–071FFFF	388000–38FFFF	SA158	$\vdash$	_	+	+			1 0	09E0000-09EFFFF	4F0000–4F7FFF
SA114	<del>                                     </del>	0720000–072FFFF	390000–397FFF	SA159	0	1 (	) C	) 1	1 1	1	1 1	09F0000-09FFFFF	4F8000–4FFFF
SA115	001110011	0730000–073FFFF	398000–39FFFF	SA160	0	1 (	) 1	C	0	0	0 0	OAOOOOO-OAOFFFF	500000-507FFF
SA116	001110100	0740000–074FFFF	3A0000–3A7FFF	SA161	0	1 (	) 1	C	0	0	0 1	0A10000-0A1FFFF	508000-50FFFF
SA117	001110101	0750000–075FFFF	3A8000–3AFFFF	SA162	0	1 (	) 1	C	0	0	1 0	0A20000-0A2FFFF	510000-517FFF
SA118	001110110	0760000–076FFFF	3B0000-3B7FFF	SA163	0	1 (	) 1	C	0	0	1 1	0A30000-0A3FFFF	518000–51FFFF
_	<del> </del>	0770000–077FFFF	3B8000–3BFFFF									0A40000-0A4FFFF	520000-527FFF
SA120	0011111000	0780000–078FFFF	3C0000-3C7FFF	SA165	0	1 (	) 1	C	0	1 (	0 1	0A50000-0A5FFFF	528000–52FFFF
SA121	001111001	0790000–079FFFF	3C8000-3CFFFF	SA166	0	1 (	) 1	C	0	1	1 0	0A60000-0A6FFFF	530000-537FFF
SA122	001111010	07A0000–07AFFFF	3D0000–3D7FFF	SA167	0	1 (	) 1	C	0	1	1 1	0A70000-0A7FFFF	538000–53FFFF
SA123	001111011	07B0000–07BFFFF	3D8000–3DFFFF	SA168									540000-547FFF
SA124	0011111100	07C0000-07CFFFF	3E0000–3E7FFF	SA169	0	1 (	) 1	C	1	0	) 1	0A90000-0A9FFFF	548000–54FFFF
SA125	<del>                                     </del>	07D0000–07DFFFF	3E8000–3EFFFF	SA170	0	1 (	) 1	C	) 1	0	1 0	OAAOOOO-OAAFFFF	550000–557FFF
SA126		07E0000–07EFFFF	3F0000–3F7FFF	SA171	0	1 (	) 1	C	1	0	1 1	OABOOOO-OABFFFF	558000–55FFFF
SA127		07F0000–07FFFFF	3F8000–3FFFFF			_						OACOOOO-OACFFFF	560000–567FFF
SA128		0800000-080FFFF	400000-407FFF	SA173		_	_	_		_			568000-56FFFF
SA129		0810000–081FFFF	408000–40FFFF		$\vdash$	_		_	-	_	_	OAEOOOO-OAEFFFF	570000-577FFF
SA130	<del>                                     </del>	0820000–082FFFF	410000–417FFF	SA175	$\vdash$	+	-	+	_	-+	_		578000–57FFFF
SA131		0830000–083FFFF	418000–41FFFF	SA176		_	_	_		_			580000–587FFF
SA132	010000100	0840000–084FFFF	420000–427FFF	SA177	0	1 (	) 1	1	0	0	) 1	0B10000-0B1FFFF	588000–58FFFF



Table I6. S29GL256M Sector Address Table (Sheet 3 of 6)

Sector	A23-A15	8-bit Address Range	16-bit Address Range	Sector			P	12:	3-	-A1	15			8-bit Address Range	16-bit Address Range
SA178	010110010	0B20000-0B2FFFF	590000-597FFF	SA223	0	1	1	С	) 1	1 1	1	1	1	ODF0000-ODFFFFF	6F8000-6FFFFF
SA179	0 1 0 1 1 0 0 1 1	0B30000-0B3FFFF	598000-59FFFF	SA224	0	1	1	1	(	0	0	0	0	OEOOOOO-OEOFFFF	700000-707FFF
SA180	0101100	0B40000-0B4FFFF	5A0000-5A7FFF	SA225	0	1	1	1	C	0	0	0	1	OE10000-0E1FFFF	708000–70FFFF
SA181	0 1 0 1 1 0 1 0 1	0B50000-0B5FFFF	5A8000-5AFFFF	SA226	0	1	1	1	C	0	0	1	0	0E20000-0E2FFFF	710000–717FFF
SA182	0 1 0 1 1 0 1 1 0	0B60000-0B6FFFF	5B0000-5B7FFF	SA227	0	1	1	1	(	0	0	1	1	0E30000-0E3FFFF	718000–71FFFF
SA183	0 1 0 1 1 0 1 1 1	0B70000-0B7FFFF	5B8000-5BFFFF	SA228	0	1	1	1	C	0	1	0	0	0E40000-0E4FFFF	720000–727FFF
SA184	0 1 0 1 1 1 0 0 0	0B80000-0B8FFFF	5C0000-5C7FFF	SA229	0	1	1	1	C	0	1	0	1	0E50000-0E5FFFF	728000–72FFFF
SA185	010111001	0B90000-0B9FFFF	5C8000-5CFFFF	SA230	0	1	1	1	C	0	1	1	0	0E60000-0E6FFFF	730000–737FFF
SA186	0 1 0 1 1 1 0 1 0	OBAOOOO-OBAFFFF	5D0000-5D7FFF	SA231	0	1	1	1	C	0	1	1	1	0E70000-0E7FFFF	738000–73FFFF
SA187	0 1 0 1 1 1 0 1 1	OBBOOOO-OBBFFFF	5D8000-5DFFFF	SA232	Ľ	1	1	+	(	4	Ļ	0	Щ	0E80000-0E8FFFF	740000–747FFF
SA188	010111100		5E0000-5E7FFF	SA233	+	+	4	+	+	4	+	0	Щ	0E90000-0E9FFFF	748000–74FFFF
SA189	0 1 0 1 1 1 1 0 1	OBD0000-OBDFFFF	5E8000–5EFFFF	1	_	+	+	+	+	+	+	1	Н	OEA0000-OEAFFFF	750000–757FFF
SA190	0 1 0 1 1 1 1 1 0		5F0000-5F7FFF	SA235	_	+	+	+	+	4	+	1	ш	OEBOOOO-OEBFFFF	758000–75FFFF
SA191	0 1 0 1 1 1 1 1 1	OBF0000-OBFFFFF	5F8000–5FFFFF	SA236	Ľ	1	4	_	Į.		_	0		0EC0000-0ECFFFF	760000–767FFF
SA192	011000000		600000-607FFF	SA237	+	+	4	+	+	4	+	0	Щ	0ED0000-0EDFFFF	768000–76FFFF
SA193	011000001	0C10000-0C1FFFF	608000–60FFFF	SA238	_	+	+	+	+	+	+	1	Н	OEE0000-OEEFFFF	770000–777FFF
SA194	011000010		610000–617FF	SA239	_	+	+	+	+	4	+	1	ш	OEFOOOO-OEFFFFF	778000–77FFF
SA195	011000011	0C30000-0C3FFFF	618000–61FFFF	SA240	Ľ	1	+	+	╀	4	Ļ	0	Щ	OFOOOOO—OFOFFFF	780000–787FFF
SA196	011000100		620000–627FFF	SA241	_	+	+	+	+	4	+	0	ш	0F10000-0F1FFFF	788000–78FFFF
SA197	011000101	0C50000-0C5FFFF	628000–62FFFF	ļ	+	+	+	+	+	+	+	1	Н	OF20000-OF2FFFF	790000–797FFF
SA198	0 1 1 0 0 0 1 1 0		630000–637FFF	SA243	_	+	+	+	+	4	+	1	ш	0F30000-0F3FFFF	798000–79FFF
SA199 SA200	011000101	0C70000-0C7FFFF 0C80000-0C8FFFF	638000–63FFFF 640000–647FFF	SA244 SA245	_	1	+	+	╀	4	+	0	Щ	0F40000-0F4FFF 0F50000-0F5FFFF	7A0000–7A7FFF 7A8000–7AFFFF
SA200	01100100	0C90000-0C9FFFF	648000–64FFFF	SA245	Ľ	1	+	+	╀	4	+	1	Н	0F60000-0F5FFF	7B0000-7B7FFF
SA201	011001010		650000-657FFF	SA240	+	+	+	+	+	+	+	1	Н	0F70000-0F7FFF	7B8000–7B7FFF
SA203	011001011	OCBOOOO-OCBFFFF	658000-65FFFF	SA248	+	1	+	+	1	4	+	0	ш	0F80000-0F8FFFF	7C0000-7C7FFF
SA204	011001100		660000-667FFF	SA249	Ľ	1	+	+	╀	4	Ļ	0	Щ	0F90000-0F9FFF	7C8000-7CFFFF
SA205	011001101	OCDO000-OCDFFFF	668000-66FFFF		+	+	1	+	+	4	+	1	Н	OFAOOOO-OFAFFFF	7D0000-7D7FFF
SA206	011001110		670000-677FFF	SA251	_	+	+	+	+	+	+	1	ш	OFB0000-OFBFFFF	7D8000–7DFFFF
SA207	011001111	OCFO000-OCFFFFF	678000–67FFFF	SA252	0	1	1	1	1	1 1	1	0	0	OFC0000-OFCFFFF	7E0000–7E7FFF
SA208	<u> </u>	ODOOOOO-ODOFFFF	680000–687FFF	SA253	0	1	1	1	1	1 1	1	0	1	OFD0000-OFDFFFF	7E8000–7EFFFF
	011010001		688000–68FFFF	SA254	+	+	+-	+-	+	+	+-	_	-		7F0000–7F7FFF
	011010010		690000–697FFF	SA255	0	1	1	1	1	1 1	1	1	1	OFF0000-OFFFFF	7F8000–7FFFFF
SA211	011010011	OD30000-0D3FFFF	698000-69FFFF	SA256	1	C	0	С	0	0	0	0	0	1000000-100FFFF	800000-807FFF
SA212	011010100	0D40000-0D4FFFF	6A0000-6A7FFF	SA257	1	C	0	С	0	0	0	0	1	1010000-101FFFF	808000-80FFFF
SA213	011010101	0D50000-0D5FFFF	6A8000-6AFFFF	SA258	1	C	0	С	0	0	0	1	0	1020000-102FFFF	810000–817FFF
SA214	0 1 1 0 1 0 1 1 0	0D60000-0D6FFFF	6B0000–6B7FFF	SA259	1	C	0	С	0	0	0	1	1	1030000-103FFFF	818000–81FFFF
SA215	0 1 1 0 1 0 1 1 1	0D70000-0D7FFFF	6B8000-6BFFFF	SA260	1	C	0	С	0	0	1	0	0	1040000-104FFFF	820000-827FFF
SA216	0 1 1 0 1 1 0 0 0	0D80000-0D8FFFF	6C0000-6C7FFF	SA261	1	C	0	С	0	0	1	0	1	1050000-105FFFF	828000–82FFFF
SA217	0 1 1 0 1 1 0 0 1	0D90000-0D9FFFF	6C8000-6CFFFF	SA262	1	C	0	С	0	0	1	1	0	1060000-106FFFF	830000-837FFF
SA218	0 1 1 0 1 1 0 1 0	ODAOOOO-ODAFFFF	6D0000-6D7FFF	SA263	1	C	0	С	0	0	1	1	1	1070000-107FFFF	838000–83FFFF
SA219	0 1 1 0 1 1 0 1 1	ODB0000-ODBFFFF	6D8000–6DFFFF	SA264	1	C	0	С	0	) 1	0	0	0	1080000–108FFFF	840000–847FFF
SA220	0 1 1 0 1 1 1 0 0	0DC0000-0DCFFFF	6E0000-6E7FFF	SA265	1	C	0	С	0	) 1	0	0	1	1090000-109FFFF	848000–84FFFF
SA221	0 1 1 0 1 1 1 0 1		6E8000-6EFFFF	SA266	+	+	+	+	+	+	+	1	_	10A0000-10AFFFF	850000–857FFF
SA222	01101110	ODE0000-ODEFFFF	6F0000-6F7FFF	SA267	1	C	0	С	0	1	0	1	1	10B0000-10BFFFF	858000–85FFFF



Table I6. S29GL256M Sector Address Table (Sheet 4 of 6)

Sector	A23-A15	8-bit Address Range	16-bit Address Range	Sector			A2	:3-	-A	15			8-bit Address Range	16-bit Address Range
SA268	100001100	10C0000-10CFFFF	860000-867FFF	SA313	1	0	0 1	1	1 1	0	0	1	1390000–139FFFF	9C8000-9CFFFF
SA269	100001101	10D0000-10DFFFF	868000-86FFFF	SA314	1	0	0 1	1	1 1	0	1	0	13A0000-13AFFFF	9D0000-9D7FFF
SA270	100001110	10E0000-10EFFFF	870000–877FFF	SA315	1	0	0 1	1	1 1	0	1	1	13B0000–13BFFFF	9D8000–9DFFFF
SA271	100001111	10F0000-10FFFFF	878000–87FFFF	SA316	1	0	0 1	1	1 1	1	0	0	13C0000-13CFFFF	9E0000-9E7FFF
SA272	10001000	1100000-110FFFF	880000-887FFF	SA317	1	0	0 1	1	1 1	1	0	1	13D0000-13DFFFF	9E8000–9EFFFF
SA273	100010001	1110000-111FFFF	888000-88FFFF	SA318	1	0	0 1	1	1 1	1	1	0	13E0000-13EFFFF	9F0000–9F7FFF
SA274	100010010	1120000-112FFFF	890000-897FFF	SA319	1	0	0 1	1	1 1	1	1	1	13F0000–13FFFFF	9F8000–9FFFFF
SA275	10001011	1130000–113FFFF	898000–89FFFF	SA320	1	0	1 (	) (	0 0	0	0	0	1400000-140FFFF	A00000-A07FFF
SA276	100010100	1140000-114FFFF	8A0000-8A7FFF	SA321	1	0	1 (	) (	0 0	0	0	1	1410000–141FFFF	A08000-A0FFFF
SA277	100010101	1150000-115FFFF	8A8000-8AFFFF	SA322	1	0	1 (	0	0 0	0	1	0	1420000-142FFFF	A10000-A17FFF
SA278	10001010	1160000-116FFFF	8B0000-8B7FFF	SA323	1	0	1 (	0	0 0	0	1	1	1430000-143FFFF	A18000–A1FFFF
SA279	1000101111	1170000-117FFFF	8B8000-8BFFFF	SA324	1	0	1 (	0	0 0	1	0	0	1440000-144FFFF	A20000-A27FFF
SA280	100011000	1180000-118FFFF	8C0000-8C7FFF	SA325	1	0	1 (	0	0 0	1	0	1	1450000-145FFFF	A28000–A2FFFF
SA281	1 0 0 0 1 1 0 0 1	1190000–119FFFF	8C8000-8CFFFF	SA326	1	0	1 (	)	0 0	1	1	0	1460000-146FFFF	A30000-A37FFF
SA282	100011010	11A0000-11AFFFF	8D0000-8D7FFF	SA327	1	0	1 (	) (	0 0	1	1	1	1470000-147FFFF	A38000–A3FFFF
SA283	100011011	11B0000-11BFFFF	8D8000-8DFFFF	SA328	1	0	1 (	) (	0 1	0	0	0	1480000–148FFFF	A40000-A47FFF
SA284	100011100	11C0000-11CFFFF	8E0000-8E7FFF	SA329	1	0	1 (	) (	0 1	0	0	1	1490000–149FFFF	A48000–A4FFFF
SA285	100011101	11D0000–11DFFFF	8E8000-8EFFFF	SA330	1	0	1 (	) (	0 1	0	1	0	14A0000-14AFFFF	A50000–A57FFF
SA286	1000111110	11E0000-11EFFFF	8F0000–8F7FFF	SA331	1	0	1 (	) (	0 1	0	1	1	14B0000-14BFFFF	A58000–A5FFFF
SA287	1000111111	11F0000-11FFFFF	8F8000–8FFFFF	SA332	1	0	1 (	) (	0 1	1	0	0	14C0000-14CFFFF	A60000–A67FFF
SA288	100100000	1200000-120FFFF	900000-907FFF	SA333	1	0	1 (	) (	0 1	1	0	1	14D0000-14DFFFF	A68000–A6FFFF
SA289	100100001	1210000-121FFFF	908000–90FFFF	SA334	Н	4	4	4	0 1	_	Ш	Ш	14E0000-14EFFFF	A70000–A77FFF
SA290	100100010	1220000-122FFFF	910000–917FFF	SA335	1	0	1 (	) (	0 1	1	1	1	14F0000–14FFFFF	A78000–A7FFFF
SA291	100100011	1230000–123FFFF	918000–91FFFF	SA336	Н	+	+	+	1 0	_				A80000–A87FFF
SA292	100100100	1240000–124FFFF	920000–927FFF	SA337	Н	+	+	+	1 (	_			1510000–151FFFF	A88000–A8FFFF
SA293	100100101	1250000–125FFFF	928000–92FFFF	SA338	ш	_	4	_	1 (	4				A90000–A97FFF
SA294	100100110	1260000–126FFFF	930000–937FFF	SA339	Н	+	+	+	1 (	+-	H		1530000–153FFFF	A98000–A9FFFF
SA295	100100111	1270000–127FFFF	938000–93FFFF	SA340	ш	_	4	_	1 (	4				AA0000–AA7FFF
SA296	100101000	1280000–128FFFF	940000–947FFF	SA341	Н	4	4	4	1 (	_	0	Ш	1550000–155FFFF	AA8000–AAFFFF
SA297	100101001	1290000–129FFFF	948000–94FFFF	SA342									1560000–156FFFF	AB0000–AB7FFF
		12A0000-12AFFFF	950000–957FFF	1	-	_	_	-	_	_	-	-	1570000–157FFFF	AB8000–ABFFFF
<b>!</b>	100101011	12B0000–12BFFFF	958000–95FFFF										1580000–158FFFF	AC0000–AC7FFF
SA300	100101100	12C0000-12CFFFF	960000–967FF	1	+	_	-	-	-	+-	-	Н	1590000–159FFFF	AC8000–ACFFFF
SA301	100101101	12D0000-12DFFFF	968000–96FFFF		$\vdash$	4	+	+	4	+-	1	Н	15A0000-15AFFFF	AD0000-AD7FFF
SA302	<del>                                     </del>	12E0000-12EFFFF	970000–977FF	-	+	_	+	+	-	-			15B0000-15BFFFF	AD8000-ADFFFF
SA303		12F0000_12FFFFF	978000–97FFF	4	$\perp$	_				_		$\blacksquare$	15C0000-15CFFFF	AE0000-AE7FFF
SA304	100110000	1300000–130FFFF	980000–987FFF	SA349	ш	_		_				Ш		AE8000-AEFFFF
SA305	100110001	1310000–131FFFF	988000–98FFFF	1	+	_	-	-	-	+-	-	Н	15E0000_15EFFFF	AF0000_AFFFFF
SA306	<del>                                     </del>	1320000-132FFFF	990000–997FF	SA351 SA352	$\vdash$	4	+	+	4	+-	1	Н		AF8000-AFFFFF
SA307	100110011	1330000-133FFFF	998000–99FFFF	SA352 SA353										B00000-B07FFF
SA308	100110101	1340000-134FFFF	9A0000-9A7FFF										1610000–161FFFF 1620000–162FFFF	B08000-B0FFFF
SA309	<del></del>	1350000-135FFFF	9A8000–9AFFFF	SA354 SA355	-	_	_	_	_	_				B10000-B17FFF
SA310	100110110	1360000–136FFFF 1370000–137FFFF	9B0000–9B7FFF 9B8000–9BFFFF	SA355 SA356	$\vdash$	4	+	+	4	+-	1	Н		B18000–B1FFFF B20000–B27FFF
SA311	++++++++	1370000=137FFF 1380000=138FFFF	9B8000-9BFFFF 9C0000-9C7FFF	SA356 SA357										B28000-B27FFF
JAS 12		1300000-138FFFF	700000-70/FFF	JA35/	Ľ	J	'	1	٠١	′ ′	U	Ľ	1030000-1035555	DZOUUU-DZFFFF



Table I6. S29GL256M Sector Address Table (Sheet 5 of 6)

Sector	A23-A15	8-bit Address Range	16-bit Address Range	Sector			-	.23	-A	15		8-bit Address Range	16-bit Address Range
SA358	101100110	1660000–166FFFF	B30000–B37FFF	SA403	1	ı I -	1 0	n	1 (	าไก	1 1	Ţ Ţ	C98000–C9FFFF
SA359	101100111	1670000–167FFF	B38000-B3FFFF	SA404	+	+	+		-	-	0 0		CA0000-CA7FFF
SA360	101101000	1680000–168FFFF	B40000-B47FFF	SA405	+	4	_	4	_		0 1		CA8000-CAFFFF
SA361	101101001	1690000–169FFFF	B48000-B4FFFF	SA406	+	+	+	₩	-+	+-	1 C		CB0000-CB7FFF
SA362	101101010	16A0000–16AFFFF	B50000-B57FFF	SA407	1	+	+		-	-	1 1	1970000–197FFFF	CB8000-CBFFFF
SA363	101101011	16B0000–16BFFFF	B58000-B5FFFF	SA408	1	1	1 0	0	1	1 0	0 0	1980000–198FFFF	CC0000-CC7FFF
SA364	101101100	16C0000-16CFFFF	B60000-B67FFF	SA409	1	1	1 0	0	1	1 0	0 1	1990000–199FFFF	CC8000-CCFFFF
SA365	101101101	16D0000-16DFFFF	B68000-B6FFFF	SA410	1	1	1 0	0	1	1 0	1 C	19A0000–19AFFFF	CD0000-CD7FFF
SA366	101101110	16E0000-16EFFFF	B70000-B77FFF	SA411	1	1	1 0	0	1	1 0	1 1	19B0000–19BFFFF	CD8000-CDFFFF
SA367	10110111	16F0000-16FFFFF	B78000-B7FFFF	SA412	1	1	1 0	0	1	1 1	0 0	19C0000-19CFFFF	CE0000-CE7FFF
SA368	101110000	1700000–170FFFF	B80000-B87FFF	SA413	1	1	1 0	0	1	1 1	0 1	19D0000-19DFFFF	CE8000-CEFFFF
SA369	101110001	1710000–171FFFF	B88000-B8FFFF	SA414	1	1	1 0	0	1	1 1	1 C	19E0000-19EFFFF	CF0000-CF7FFF
SA370	101110010	1720000-172FFFF	B90000-B97FFF	SA415	1	1	1 0	0	1	1 1	1 1	19F0000-19FFFFF	CF8000-CFFFFF
SA371	101110011	1730000-173FFFF	B98000-B9FFFF	SA416	1	1	1 0	1	0 (	0 0	0 0	1A00000-1A0FFFF	D00000-D07FFF
SA372	101110100	1740000-174FFFF	BA0000-BA7FFF	SA417	1	1	1 0	1	0	0 0	0 1	1A10000-1A1FFFF	D08000-D0FFFF
SA373	101110101	1750000–175FFFF	BA8000-BAFFFF	SA418	1	1	1 0	1	0	0 0	1 C	1A20000-1A2FFFF	D10000-D17FFF
SA374	101110110	1760000–176FFFF	BB0000-BB7FFF	SA419	1	1	1 0	1	0	0 0	1 1	1A30000-1A3FFFF	D18000-D1FFFF
SA375	10111011	1770000-177FFFF	BB8000-BBFFFF	SA420	1	1	1 0	1	0	0 1	0 0	1A40000-1A4FFFF	D20000-D27FFF
SA376	101111000	1780000–178FFFF	BC0000-BC7FFF	SA421	1	1	1 0	1	0	0 1	0 1	1A50000-1A5FFFF	D28000-D2FFFF
SA377	101111001	1790000-179FFFF	BC8000-BCFFFF	SA422	1	1	1 0	1	0	0 1	1 C	1A60000-1A6FFFF	D30000-D37FFF
SA378	101111010	17A0000-17AFFFF	BD0000-BD7FFF	SA423	1	1	1 0	1	0	0 1	1 1	1A70000-1A7FFFF	D38000-D3FFFF
SA379	101111011	17B0000-17BFFFF	BD8000-BDFFFF	SA424	1	1	1 0	1	0	1 0	0 0	1A80000-1A8FFFF	D40000-D47FFF
SA380	10111100	17C0000-17CFFFF	BE0000-BE7FFF	SA425	1	1	1 0	1	0	1 0	0 1	1A90000-1A9FFFF	D48000-D4FFFF
SA381	101111101	17D0000–17DFFFF	BE8000-BEFFFF	SA426	1	1	1 0	1	0	1 0	1 C	1AA0000-1AAFFFF	D50000-D57FFF
SA382	10111110	17E0000–17EFFFF	BF0000-BF7FFF	SA427	1	1	1 0	1	0	1 0	1 1	1AB0000–1ABFFFF	D58000-D5FFFF
SA383	10111111	17F0000–17FFFFF	BF8000-BFFFFF	SA428	1	1	1 0	1	0	1 1	0 0	1AC0000-1ACFFFF	D60000-D67FFF
SA384	110000000	1800000–180FFFF	C00000-C07FFF	SA429	1	1	1 0	1	0	1 1	0 1	1AD0000-1ADFFFF	D68000-D6FFFF
SA385	1 1 0 0 0 0 0 0 1	1810000–181FFFF	C08000-C0FFFF	SA430	1	+	1 0		-	-	1 C	1AE0000-1AEFFFF	D70000-D77FFF
SA386	110000010	1820000–182FFFF	C10000-C17FFF	SA431	1	+	1 0			1 1	Щ.	1AF0000–1AFFFFF	D78000-D7FFFF
SA387	110000011	1830000–183FFFF	C18000–C1FFFF	SA432							0 0		D80000-D87FFF
SA388	1100000100	1840000–184FFFF	C20000–C27FFF		-	-	_	_	_	_		1B10000–1B1FFFF	
-	1 1 0 0 0 0 1 0 1	1850000–185FFFF	C28000–C2FFFF		+	+	4	┰	-	+	++	1B20000-1B2FFFF	D90000-D97FFF
SA390	1 1 0 0 0 0 1 1 0		C30000–C37FFF	SA435	+	_	4	4	_	4	ш.		D98000-D9FFFF
SA391	1 1 0 0 0 0 1 1 1	1870000–187FFF	C38000–C3FFFF		+	+	+	_	_	_	-	1B40000–1B4FFFF	DA0000-DA7FFF
	<del></del>	1880000–188FFFF	C40000–C47FFF	1	+	+	+	$\vdash$	+	+-	++	1B50000–1B5FFFF	DA8000-DAFFFF
-	<u> </u>	1890000–189FFFF	C48000–C4FFFF	SA438	+	+	+	_	_	_	-		DB0000-DB7FFF
SA394	1 1 0 0 0 1 0 1 0	18A0000_18AFFFF	C50000-C57FFF								1 1		DB8000-DBFFFF
+	110001011	18B0000-18BFFFF	C58000-C5FFFF		+	-	_	-	_	4-		1B80000_1B8FFFF	DC0000-DC7FFF
SA396	<del></del>	18C0000_18CFFFF	C60000-C67FFF	SA441 SA442	+	+	+	_	_	_	-		DC8000-DCFFFF
-	1 1 0 0 0 1 1 0 1	18D0000-18DFFFF	C68000-C6FFFF		+	+	+	1	_		-		DD0000-DD7FFF
SA398 SA399	+++++++	18E0000–18EFFFF 18F0000–18FFFFF	C70000–C77FFF C78000–C7FFFF		+	+	_	_	_	_	1 1	1BB0000–1BBFFFF 1BC0000–1BCFFFF	DD8000-DDFFFF DE0000-DE7FFF
	1100101111	190000–18FFFF 190000–190FFFF	C80000-C7FFFF		+	+	+	_	_	_	-	1BD0000-1BDFFFF	DE8000-DE7FFF
SA400	11001000	1910000=190FFF 1910000=191FFFF	C88000-C87FFF	SA445	+	+	+	$\vdash$	+	+-	$\vdash$		DF0000-DF7FFF
SA401	110010010	1910000=191FFFF 1920000=192FFFF	C90000-C97FFF		+	+	+	_	_	_	1 1		DF8000-DFFFFF
JM402		1720000-172777	U70000-U7/FFF	JA44/	Ľ	1	٠١٠	Ľ		11	ĽĽ	וטו סססס וסרררר	חו ממממ–חבנבנב



Table I6. S29GL256M Sector Address Table (Sheet 6 of 6)

Sector			ļ	12	3-	Α	15	;				8-bit Address Range	16-bit Address Range	Sector			A	.23	3—/	A1	5			8-bit Address Range	16-bit Address Range
SA448	1	1	1	С	C	(	) (	O	0	0		1C00000-1C0FFFF	E00000-E07FFF	SA480	1	1	1	1	0	0	0	0	O	1E00000-1E0FFFF	F00000-F07FFF
SA449	1	1	1	С	C	(	0	O	0	1		1C10000-1C1FFFF	E08000-E0FFFF	SA481	1	1	1	1	0	0	0	0 1	1	1E10000-1E1FFFF	F08000-F0FFFF
SA450	1	1	1	С	C	(	0	O	1	0		1C20000-1C2FFFF	E10000-E17FFF	SA482	1	1	1	1	0	0	0	1 (	)	1E20000-1E2FFFF	F10000-F17FFF
SA451	1	1	1	С	C	(	0	O	1	1		1C30000-1C3FFFF	E18000-E1FFFF	SA483	1	1	1	1	0	0	0	1 1	1	1E30000-1E3FFFF	F18000–F1FFFF
SA452	1	1	1	С	C	(	) 1	1	0	0		1C40000-1C4FFFF	E20000-E27FFF	SA484	1	1	1	1	0	0	1	0 0	)	1E40000-1E4FFFF	F20000-F27FFF
SA453	1	1	1	С	C	(	) 1	1	0	1		1C50000-1C5FFFF	E28000-E2FFFF	SA485	1	1	1	1	0	0	1	0 1	1	1E50000-1E5FFFF	F28000-F2FFFF
SA454	1	1	1	С	C	(	) 1	1	1	0		1C60000-1C6FFFF	E30000-E37FFF	SA486	1	1	1	1	0	0	1	1 (	)	1E60000-1E6FFFF	F30000-F37FFF
SA455	1	1	1	С	C	(	) 1	1	1	1		1C70000-1C7FFFF	E38000-E3FFFF	SA487	1	1	1	1	0	0	1	1 1	1	1E70000-1E7FFFF	F38000–F3FFFF
SA456	1	1	1	С	C	1	1 (	O	0	0		1C80000-1C8FFFF	E40000-E47FFF	SA488	1	1	1	1	0	1	0	0 0	)	1E80000-1E8FFFF	F40000-F47FFF
SA457	1	1	1	С	C	1	1 (	O	0	1		1C90000-1C9FFFF	E48000-E4FFFF	SA489	1	1	1	1	0	1	0	0 1	1	1E90000-1E9FFFF	F48000–F4FFFF
SA458	1	1	1	С	C	1	1 (	O	1	0		1CA0000-1CAFFFF	E50000-E57FFF	SA490	1	1	1	1	0	1	0	1 (	)	1EA0000-1EAFFFF	F50000-F57FFF
SA459	1	1	1	С	C	1	1 (	O	1	1		1CB0000-1CBFFFF	E58000-E5FFFF	SA491	1	1	1	1	0	1	0	1 1	1	1EB0000-1EBFFFF	F58000–F5FFFF
SA460	1	1	1	С	C	1	1 1	1	0	0		1CC0000-1CCFFFF	E60000-E67FFF	SA492	1	1	1	1	0	1	1	0 0	)	1EC0000-1ECFFFF	F60000-F67FFF
SA461	1	1	1	С	C	1	1 1	1	0	1		1CD0000-1CDFFFF	E68000-E6FFFF	SA493	1	1	1	1	0	1	1	0 1	1	1ED0000-1EDFFFF	F68000–F6FFFF
SA462	1	1	1	С	C	1	1 1	1	1	0		1CE0000-1CEFFFF	E70000-E77FFF	SA494	1	1	1	1	0	1	1	1 (	)	1EE0000-1EEFFFF	F70000-F77FFF
SA463	1	1	1	С	C	1	1 1	1	1	1		1CF0000-1CFFFFF	E78000-E7FFFF	SA495	1	1	1	1	0	1	1	1 1	1	1EF0000-1EFFFFF	F78000–F7FFFF
SA464	1	1	1	С	1	(	0	0	0	0		1D00000-1D0FFFF	E80000-E87FFF	SA496	1	1	1	1	1	0	0	0 0	)	1F00000-1F0FFFF	F80000-F87FFF
SA465	1	1	1	С	1	(	0	0	0	1		1D10000-1D1FFFF	E88000-E8FFFF	SA497	1	1	1	1	1	0	0	0 1	1	1F10000-1F1FFFF	F88000-F8FFFF
SA466	1	1	1	С	1	(	0	O	1	0		1D20000-1D2FFFF	E90000-E97FFF	SA498	1	1	1	1	1	0	0	1 (	)	1F20000-1F2FFFF	F90000-F97FFF
SA467	1	1	1	С	1	(	0	O	1	1		1D30000-1D3FFFF	E98000-E9FFFF	SA499	1	1	1	1	1	0	0	1 1	1	1F30000-1F3FFFF	F98000–F9FFFF
SA468	1	1	1	С	1	(	) ′	1	0	0		1D40000-1D4FFFF	EA0000-EA7FFF	SA500	1	1	1	1	1	0	1	0 0	)	1F40000-1F4FFFF	FA0000-FA7FFF
SA469	1	1	1	С	1	(	) ′	1	0	1		1D50000-1D5FFFF	EA8000-EAFFFF	SA501	1	1	1	1	1	0	1	0 1	1	1F50000-1F5FFFF	FA8000-FAFFFF
SA470	1	1	1	С	1	(	) ′	1	1	0		1D60000-1D6FFFF	EB0000-EB7FFF	SA502	1	1	1	1	1	0	1	1 (	)	1F60000-1F6FFFF	FB0000-FB7FFF
SA471	1	1	1	С	1	(	) ′	1	1	1		1D70000-1D7FFFF	EB8000-EBFFFF	SA503	1	1	1	1	1	0	1	1 1	1	1F70000-1F7FFF	FB8000-FBFFFF
SA472	1	1	1	С	1	,	1 (	0	0	0		1D80000-1D8FFFF	EC0000-EC7FFF	SA504	1	1	1	1	1	1	0	0 0	)	1F80000-1F8FFFF	FC0000-FC7FFF
SA473	1	1	1	С	1	-	1 (	)	0	1		1D90000-1D9FFFF	EC8000-ECFFFF	SA505	1	1	1	1	1	1	0	0 1	1	1F90000-1F9FFFF	FC8000-FCFFFF
SA474	1	1	1	С	1	,	1 (	O	1	0		1DA0000-1DAFFFF	ED0000-ED7FFF	SA506	1	1	1	1	1	1	0	1 (	)	1FA0000-1FAFFFF	FD0000-FD7FFF
SA475	1	1	1	С	1	-	1 (	O	1	1		1DB0000-1DBFFFF	ED8000-EDFFFF	SA507	1	1	1	1	1	1	0	1 1	1	1FB0000-1FBFFFF	FD8000-FDFFFF
SA476	1	1	1	С	1	-	1 1	1	0	0		1DC0000-1DCFFFF	EE0000-EE7FFF	SA508	1	1	1	1	1	1	1	0 0	)	1FC0000-1FCFFFF	FE0000-FE7FFF
SA477	1	1	1	С	1	•	1 -	1	0	1	ŀ	1DD0000–1DDFFFF	EE8000-EEFFFF	SA509	1	1	1	1	1	1	1	0 1	1	1FD0000-1FDFFFF	FE8000-FEFFFF
SA478	1	1	1	С	1	-	1 -	1	1	0		1DE0000-1DEFFFF	EF0000-EF7FFF	SA510	1	1	1	1	1	1	1	1 (	)	1FE0000-1FEFFFF	FF0000-FF7FFF
SA479	1	1	1	С	1	•	1 1	1	1	1		1DF0000-1DFFFFF	EF8000-EFFFFF	SA511	1	1	1	1	1	1	1	1 1	1	1FF0000-1FFFFFF	FF8000-FFFFFF

Note: All sectors are 64 Kbytes or 32 Kwords in size.



### **Autoselect Mode**

The autoselect mode provides manufacturer and device identification, and sector group protection verification, through identifier codes output on DQ7–DQ0. This mode is primarily intended for programming equipment to automatically match a device to be programmed with its corresponding programming algorithm. However, the autoselect codes can also be accessed in-system through the command register.

When using programming equipment, the autoselect mode requires  $V_{ID}$  on address pin A9. Address pins A6, A3, A2, A1, and A0 must be as shown in Table 17. In addition, when verifying sector protection, the sector address must appear on the appropriate highest order address bits (see Table 6 through Table 16). Table 17 shows the remaining address bits that are don't care. When all necessary bits are set as required, the programming equipment may then read the corresponding identifier code on DQ7–DQ0.

To access the autoselect codes in-system, the host system can issue the autoselect command via the command register, as shown in Table 34 and Table 35. This method does not require  $V_{\text{ID}}$ . See Autoselect Command Sequence for more information.

Table 17. Autoselect Codes, (High Voltage Method)

						A1		Α		Α	Α			DO9 +c	DQ15			DQ7 to DQ0	
	escription	CE#	OE#	WE#	A22 to A15	4 to	Α9	8 to	A 6	5 to	3 to	A 1	A 0	טעס וו	סטטוס			Model Numbe	r
	•				AIS	A1 0		A 7	0	A 4	A 2	ı	U	BYTE# = V <sub>IH</sub>	BYTE# = V <sub>IL</sub>	RO	R1, R2, R8, R9	R3,R4	R5, R6, R7
	ufacturer ID: sion Products	L	L	Н	Х	Х	V <sub>I</sub>	Х	L	Х	L	L	L	00	Х	01 h	01h	01h	01h
M99	Cycle 1										L	L	Ι	22	Х		7Eh		
31.25	Cycle 2	L	L	Н	Х	Х	V <sub>I</sub>	Х	L	Х	Н	Н	L	22	Х		12h		
S29GL256M	Cycle 3						ט				Ι	Ι	Ι	22	X		01h		
W8.	Cycle 1										L	L	Н	22	Х		7Eh		
3112	Cycle 2	L	L	Н	Х	Х	V <sub>I</sub>	Х	L	Х	Н	Н	L	22	Х		12h		
S29GL128M	Cycle 3						ט				Ι	Ι	Ι	22	X		00h		
_	Cycle 1										L	L	Η	22	Х	7E h	7Eh	7Eh	7Eh
S29GL064M	Cycle 2	L	L	Н	X	Х	VI	Х	L	Х	Η	Η	L	22	Х	13 h	0Ch	10h	13h
S29G	Cycle 3						D				Н	Н	Н	22	×	00 h	01h	00h (-R4, bottom boot) 01h (-R3, top boot)	01h
	Cycle 1										L	ш	Ι	22	Х	7E h	7Eh	7Eh	7Eh
S29GL032M	Cycle 2	L	L	Н	X	Х	VI	Х	L	Х	Н	Н	L	22	Х	1C h	1Dh	1Ah	1Ah
S29G	Cycle 3						D				Н	Н	Н	22	×	00 h	00h	00h (-R4, bottom boot) 01h (-R3, top boot)	
Prote	or Group ection ication	L	L	Н	SA	Х	V <sub>I</sub>	х	L	X	L	Н	L	Х	Х			01h (protected 00h (unprotecte	
Sector Bit (I	red Silicon or Indicator DQ7), WP# ects highest ess sector	L	L	Н	Х	х	V <sub>I</sub>	x	L	x	L	Н	Н	Х	Х			Bh (factory lock of (not factory lo	
Sector Bit (I	red Silicon or Indicator DQ7), WP# ects lowest ess sector	L	L	Н	Х	Х	V <sub>I</sub>	х	L	X	L	Н	Н	Х	Х	88h (factory locked), 08h (not factory locked)			

**Legend:**  $L = Logic Low = V_{IL}$ ,  $H = Logic High = V_{IH}$ , SA = Sector Address, X = Don't care.



## **Sector Group Protection and Unprotection**

The hardware sector group protection feature disables both program and erase operations in any sector group. In this device, a sector group consists of four adjacent sectors that are protected or unprotected at the same time (see Table 4). The hardware sector group unprotection feature re-enables both program and erase operations in previously protected sector groups. Sector group protection/unprotection can be implemented via two methods.

Sector protection/unprotection requires  $V_{ID}$  on the RESET# pin only, and can be implemented either in-system or via programming equipment. Figure 2 shows the algorithms and Figure 24 shows the timing diagram. This method uses standard microprocessor bus cycle timing. For sector group unprotect, all unprotected sector groups must first be protected prior to the first sector group unprotect write cycle.

The device is shipped with all sector groups unprotected. Spansion offers the option of programming and protecting sector groups at its factory prior to shipping the device through Spansion Programming Service. Contact a Spansion representative for details.

It is possible to determine whether a sector group is protected or unprotected. See Autoselect Mode for details.

Table 18. S29GL032M (Model R0) Sector Group Protection/Unprotection Addresses

Sector Group	A22–A18	Sector Group	A22-A18	Sector Group	A22-A18	Sector Group	A22-A18
SA0-SA3	00000	SA16-SA19	00100	SA32-SA35	01000	SA48-SA51	01100
SA4-SA7	00001	SA20-SA23	00101	SA36-SA39	01001	SA52-SA55	01101
SA8-SA11	00010	SA24-SA27	00110	SA40-SA43	01010	SA56-SA59	01110
SA12-SA15	00011	SA28-SA31	00111	SA44-SA47	01011	SA60-SA63	01111

Note: All sector groups are 256 Kwords in size.

Table 19. S29GL032M (Models RI, R2) Sector Group Protection/Unprotection Addresses

Sector Group	A20-A15	Sector Group	A20-A15	Sector Group	A20-A15	Sector Group	A20-A15
SA0	000000	SA12-SA15	0011xx	SA36-SA39	1001xx	SA56-SA59	1110xx
SA1	000001	SA16-SA19	0100xx	SA40-SA43	1010xx	SA60	111100
SA2	000010	SA20-SA23	0101xx	SA44-SA47	1011xx	SA61	111101
SA3	000011	SA24-SA27	0110xx	SA48-SA51	1100xx	SA62	111110
SA4-SA7	0001xx	SA28-SA31	0111xx	SA52-SA55	1101xx	SA63	111111
SA8-SA11	0010xx	SA32-SA35	1000xx	-		, <del>-</del>	•

Table 20. S29GL032M (Model R3) Sector Group Protection/Unprotection Address Table

Sector	A20-A12	Sector/Sector Block Size (Kbytes)	Sector	A20-A12	Sector/Sector Block Size (Kbytes)	Sector	A20-A12	Sector/Sector Block Size (Kbytes)
SA0-SA3	0000XXXXXh	256 (4x64)	SA36-SA39	1001XXXXXh	256 (4x64)	SA63	111111000h	8
SA4-SA7	0001XXXXXh	256 (4x64)	SA40-SA43	1010XXXXXh	256 (4x64)	SA64	111111001h	8
SA8-SA11	0010XXXXXh	256 (4x64)	SA44-SA47	1011XXXXXh	256 (4x64)	SA65	111111010h	8
SA12-SA15	0011XXXXXh	256 (4x64)	SA48-SA51	1100XXXXXh	256 (4x64)	SA66	111111011h	8
SA16-SA19	0100XXXXXh	256 (4x64)	SA52-SA55	1101XXXXXh	256 (4x64)	SA67	1111111100h	8
SA20-SA23	0101XXXXXh	256 (4x64)	SA56-SA59	1110XXXXXh	256 (4x64)	SA68	111111101h	8
SA24-SA27	0110XXXXXh	256 (4x64)		111100XXXh		SA69	111111110h	8
SA28-SA31	0111XXXXXh	256 (4x64)	SA60-SA62	111101XXXh	192 (3x64)	SA70	111111111h	8
SA32-SA35	1000XXXXXh	256 (4x64)		111110XXXh				



Table 21. S29GL032M (Model R4) Sector Group Protection/Unprotection Address Table

Sector	A20-A12	Sector/Sector Block Size (Kbytes)	Sector	A20-A12	Sector/Sector Block Size (Kbytes)	Sector	A20-A12	
SA0	000000000h	8		000001XXXh		SA35-SA38	0111XXXXXh	256 (4x64)
SA1	00000001h	8	SA8-SA10	000010XXXh	192 (3x64)	SA39-SA42	1000XXXXXh	256 (4x64)
SA2	00000010h	8		000011XXXh		SA43-SA46	1001XXXXXh	256 (4x64)
SA3	000000011h	8	SA11-SA14	0001XXXXXh	256 (4x64)	SA47-SA50	1010XXXXXh	256 (4x64)
SA4	000000100h	8	SA15-SA18	0010XXXXXh	256 (4x64)	SA51-SA54	1011XXXXXh	256 (4x64)
SA5	000000101h	8	SA19-SA22	0011XXXXXh	256 (4x64)	SA55-SA58	1100XXXXXh	256 (4x64)
SA6	000000110h	8	SA23-SA26	0100XXXXXh	256 (4x64)	SA59-SA62	1101XXXXXh	256 (4x64)
SA7	000000111h	8	SA27-SA30	0101XXXXXh	256 (4x64)	SA63-SA66	1110XXXXXh	256 (4x64)
			SA31-SA34	0110XXXXXh	256 (4x64)	SA67-SA70	1111XXXXXXh	256 (4x64)

Table 22. S29GL064M (Model 00) Sector Group Protection/Unprotection Address Table

Sector Group	A22–A18	Sector Group	A22-A18	Sector Group	A22-A18	Sector Group	A22-A18
SA0-SA3	00000	SA36-SA39	01001	SA68-SA71	10001	SA100-SA103	11001
SA4-SA7	00001	SA40-SA43	01010	SA72-SA75	10010	SA104-SA107	11010
SA8-SA11	00010	SA44-SA47	01011	SA76-SA79	10011	SA108-SA111	11011
SA12-SA15	00011	SA48-SA51	01100	SA80-SA83	10100	SA112-SA115	11100
SA16-SA19	00100	SA52-SA55	01101	SA88-SA91	10110	SA116-SA119	11101
SA20-SA23	00101	SA56-SA59	01110	SA92-SA95	10111	SA120-SA123	11110
SA24-SA27	00110	SA60-SA63	01111	SA96-SA99	11000	SA124-SA127	11111
SA32-SA35	01000	SA64-SA67	10000				

Note: All sector groups are 256 Kwords in size.

Table 23. S29GL064M (Models RI, R2, R8, R9) Sector Group Protection/Unprotection Addresses

Sector Group	A21–A15	Sector Group	A21-A15	Sector Group	A21–A15	Sector Group	A21-A15
SA0	0000000	SA28-SA31	00111xx	SA64-SA67	10000xx	SA104-SA107	11010xx
SA1	0000001	SA32-SA35	01000xx	SA68-SA71	10001xx	SA108-SA111	11011xx
SA2	0000010	SA36-SA39	01001xx	SA72-SA75	10010xx	SA112-SA115	11100xx
SA3	0000011	SA40-SA43	01010xx	SA76-SA79	10011xx	SA116-SA119	11101xx
SA4-SA7	00001xx	SA44-SA47	01011xx	SA80-SA83	10100xx	SA120-SA123	11110xx
SA8-SA11	00010xx	SA48-SA51	01100xx	SA84-SA87	10101xx	SA124	1111100
SA12-SA15	00011xx	SA52-SA55	01101xx	SA88-SA91	10110xx	SA125	1111101
SA16-SA19	00100xx	SA56-SA59	01110xx	SA92-SA95	10111xx	SA126	1111110
SA20-SA23	00101xx	SA60-SA63	01111xx	SA96-SA99	11000xx	SA127	1111111
SA24-SA27	00110xx	SA28-SA31	00111xx	SA100-SA103	11001xx		



Table 24. S29GL064M (Model R3) Sector Group Protection/Unprotection Address Table

Sector	A21-A12	Sector/ Sector Block Size (Kbytes)	Sector	A21-A12	Sector/ Sector Block Size (Kbytes)	Sector	A21–A12	Sector/ Sector Block Size (Kbytes)
SA0-SA3	00000XXXXX	256 (4x64)	SA56-SA59	01110XXXXX	256 (4x64)	SA112-SA115	11100XXXXX	256 (4x64)
SA4-SA7	00001XXXXX	256 (4x64)	SA60-SA63	01111XXXXX	256 (4x64)	SA116-SA119	11101XXXXX	256 (4x64)
SA8-SA11	00010XXXXX	256 (4x64)	SA64-SA67	10000XXXXX	256 (4x64)	SA120-SA123	11110XXXXX	256 (4x64)
SA12-SA15	00011XXXXX	256 (4x64)	SA68-SA71	10001XXXXX	256 (4x64)		1111100XXX	
SA16-SA19	00100XXXXX	256 (4x64)	SA72-SA75	10010XXXXX	256 (4x64)	SA124-SA126	1111101XXX	192 (3x64)
SA20-SA23	00101XXXXX	256 (4x64)	SA76-SA79	10011XXXXX	256 (4x64)		1111110XXX	
SA24-SA27	00110XXXXX	256 (4x64)	SA80-SA83	10100XXXXX	256 (4x64)	SA127	1111111000	8
SA28-SA31	00111XXXXX	256 (4x64)	SA84-SA87	10101XXXXX	256 (4x64)	SA128	1111111001	8
SA32-SA35	01000XXXXX	256 (4x64)	SA88-SA91	10110XXXXX	256 (4x64)	SA129	1111111010	8
SA36-SA39	01001XXXXX	256 (4x64)	SA92-SA95	10111XXXXX	256 (4x64)	SA130	1111111011	8
SA40-SA43	01010XXXXX	256 (4x64)	SA96-SA99	11000XXXXX	256 (4x64)	SA131	1111111100	8
SA44-SA47	01011XXXXX	256 (4x64)	SA100-SA103	11001XXXXX	256 (4x64)	SA132	1111111101	8
SA48-SA51	01100XXXXX	256 (4x64)	SA104-SA107	11010XXXXX	256 (4x64)	SA133	1111111110	8
SA52-SA55	01101XXXXX	256 (4x64)	SA108-SA111	11011XXXXX	256 (4x64)	SA134	1111111111	8

Table 25. S29GL064M (Model R4) Sector Group Protection/Unprotection Addresses

Sector	A21–A12	Sector/Sector Block Size (Kbytes)	Sector	A21–A12	Sector/Sector Block Size (Kbytes)	Sector	A21–A12	Sector/Sector Block Size (Kbytes)
SA0	0000000000	8	SA23-SA26	00100XXXXX	256 (4x64)	SA79-SA82	10010XXXXX	256 (4x64)
SA1	000000001	8	SA27-SA30	00101XXXXX	256 (4x64)	SA83-SA86	10011XXXXX	256 (4x64)
SA2	000000010	8	SA31-SA34	00110XXXXX	256 (4x64)	SA87-SA90	10100XXXXX	256 (4x64)
SA3	000000011	8	SA35-SA38	00111XXXXX	256 (4x64)	SA91-SA94	10101XXXXX	256 (4x64)
SA4	000000100	8	SA39-SA42	01000XXXXX	256 (4x64)	SA95-SA98	10110XXXXX	256 (4x64)
SA5	000000101	8	SA43-SA46	01001XXXXX	256 (4x64)	SA99-SA102	10111XXXXX	256 (4x64)
SA6	0000000110	8	SA47-SA50	01010XXXXX	256 (4x64)	SA103-SA106	11000XXXXX	256 (4x64)
SA7	000000111	8	SA51-SA54	01011XXXXX	256 (4x64)	SA107-SA110	11001XXXXX	256 (4x64)
	0000001XXX		SA55-SA58	01100XXXXX	256 (4x64)	SA111-SA114	11010XXXXX	256 (4x64)
SA8-SA10	0000010XXX	192 (3x64)	SA59-SA62	01101XXXXX	256 (4x64)	SA115-SA118	11011XXXXX	256 (4x64)
	0000011XXX		SA63-SA66	01110XXXXX	256 (4x64)	SA119-SA122	11100XXXXX	256 (4x64)
SA11-SA14	00001XXXXX	256 (4x64)	SA67-SA70	01111XXXXX	256 (4x64)	SA123-SA126	11101XXXXX	256 (4x64)
SA15-SA18	00010XXXXX	256 (4x64)	SA71-SA74	10000XXXXX	256 (4x64)	SA127-SA130	11110XXXXX	256 (4x64)
SA19-SA22	00011XXXXX	256 (4x64)	SA75-SA78	10001XXXXX	256 (4x64)	SA131-SA134	11111XXXXX	256 (4x64)



Table 26. S29GL064M (Model R5) Sector Group Protection/Unprotection Addresses

Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17
SA0-SA3	00000	SA28-SA31	00111	SA56-SA59	01110	SA80-SA83	10100	SA104-SA107	11010
SA4-SA7	00001	SA32-SA35	01000	SA60-SA63	01111	SA84-SA87	10101	SA108-SA111	11011
SA8-SA11	00010	SA36-SA39	01001	SA64-SA67	10000	SA88-SA91	10110	SA112-SA115	11100
SA12-SA15	00011	SA40-SA43	01010	SA68-SA71	10001	SA92-SA95	10111	SA116-SA119	11101
SA16-SA19	00100	SA44-SA47	01011	SA72-SA75	10010	SA96-SA99	11000	SA120-SA123	11110
SA20-SA23	00101	SA48-SA51	01100	SA76-SA79	10011	SA100-SA103	11001	SA124-SA127	11111
SA24-SA27	00110	SA52-SA55	01101						

Note: All sector groups are 128 Kwords in size.

Table 27. S29GL064M (Models R6, R7) Sector Group Protection/Unprotection Address

Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17	Sector Group	A21-A17
SA0-SA3	00000	SA28-SA31	00111	SA56-SA59	01110	SA80-SA83	10100	SA104-SA107	11010
SA4-SA7	00001	SA32-SA35	01000	SA60-SA63	01111	SA84-SA87	10101	SA108-SA111	11011
SA8-SA11	00010	SA36-SA39	01001	SA64-SA67	10000	SA88-SA91	10110	SA112-SA115	11100
SA12-SA15	00011	SA40-SA43	01010	SA68-SA71	10001	SA92-SA95	10111	SA116-SA119	11101
SA16-SA19	00100	SA44-SA47	01011	SA72-SA75	10010	SA96-SA99	11000	SA120-SA123	11110
SA20-SA23	00101	SA48-SA51	01100	SA76-SA79	10011	SA100-SA103	11001	SA124-SA127	11111
SA24-SA27	00110	SA52-SA55	01101	-		-	•	1	

Note: All sector groups are 128 Kwords in size.

Table 28. S29GLI28M Sector Group Protection/Unprotection Addresses

	Sector Group	A22-A15	Sector Group	A22-A15	Sector Group	A22-A15	Sector Group	A22-A15
Ī	SA0	00000000	SA72-SA75	010010xx	SA156-SA159	100111xx	SA240-SA243	111100xx
Ī	SA1	00000001	SA76-SA79	010011xx	SA160-SA163	101000xx	SA244-SA247	111101xx
Ī	SA2	00000010	SA80-SA83	010100xx	SA164-SA167	101001xx	SA248-SA251	111110xx
Ī	SA3	00000011	SA84-SA87	010101xx	SA168-SA171	101010xx	SA252	11111100
Ī	SA4-SA7	000001xx	SA88-SA91	010110xx	SA172-SA175	101011xx	SA253	11111101
Ī	SA8-SA11	000010xx	SA92-SA95	010111xx	SA176-SA179	101100xx	SA254	11111110
Ī	SA12-SA15	000011xx	SA96-SA99	011000xx	SA180-SA183	101101xx	SA255	11111111
Ī	SA16-SA19	000100xx	SA100-SA103	011001xx	SA184-SA187	101110xx		
Ī	SA20-SA23	000101xx	SA104-SA107	011010xx	SA188-SA191	101111xx	1	
Ī	SA24-SA27	000110xx	SA108-SA111	011011xx	SA192-SA195	110000xx	1	
Ī	SA28-SA31	000111xx	SA112-SA115	011100xx	SA196-SA199	110001xx	]	
Ī	SA32-SA35	001000xx	SA116-SA119	011101xx	SA200-SA203	110010xx	]	
Ī	SA36-SA39	001001xx	SA120-SA123	011110xx	SA204-SA207	110011xx	1	
Ī	SA40-SA43	001010xx	SA124-SA127	011111xx	SA208-SA211	110100xx	]	
Ī	SA44-SA47	001011xx	SA128-SA131	100000xx	SA212-SA215	110101xx	1	
Ī	SA48-SA51	001100xx	SA132-SA135	100001xx	SA216-SA219	110110xx	1	
Ī	SA52-SA55	001101xx	SA136-SA139	100010xx	SA220-SA223	110111xx	1	
Ī	SA56-SA59	001110xx	SA140-SA143	100011xx	SA224-SA227	111000xx	1	
Ī	SA60-SA63	001111xx	SA144-SA147	100100xx	SA228-SA231	111001xx	1	
Ī	SA64-SA67	010000xx	SA148-SA151	100101xx	SA232-SA235	111010xx	1	
Ī	SA68-SA71	010001xx	SA152-SA155	100110xx	SA236-SA239	111011xx	1	



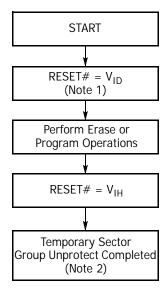
Table 29. S29GL256M Sector Group Protection/Unprotection Addresses

Sector Group	A23-A15	Sector Group	A23-A15	Sector Group	A23-A15	Sector Group	A23-A15
SA0	000000000	SA124-SA127	00111111xx	SA260-SA263	1000001xx	SA392-SA395	1100010xx
SA1	00000001	SA128-SA131	0100000xx	SA264-SA267	1000010xx	SA396-SA399	1100011xx
SA2	00000010	SA132-SA135	0100001xx	SA268-SA271	1000011xx	SA400-SA403	1100100xx
SA3	000000011	SA136-SA139	0100010xx	SA276-SA279	1000101xx	SA404-SA407	1100101xx
SA4-SA7	0000001xx	SA140-SA143	0100011xx	SA276-SA279	1000101xx	SA408-SA411	1100110xx
SA8-SA11	0000010xx	SA144-SA147	0100100xx	SA280-SA283	1000110xx	SA412-SA415	1100111xx
SA12-SA15	0000011xx	SA148-SA151	0100101xx	SA284-SA287	1000111xx	SA416-SA419	1101000xx
SA16-SA19	0000100xx	SA152-SA155	0100110xx	SA288-SA291	1001000xx	SA420-SA423	1101001xx
SA20-SA23	0000101xx	SA156-SA159	0100111xx	SA292-SA295	1001001xx	SA424-SA427	1101010xx
SA24-SA27	0000110xx	SA160-SA163	0101000xx	SA296-SA299	1001010xx	SA428-SA431	1101011xx
SA28-SA31	0000111xx	SA164-SA167	0101001xx	SA300-SA303	1001011xx	SA432-SA435	1101100xx
SA32-SA35	0001000xx	SA168-SA171	0101010xx	SA304-SA307	1001100xx	SA436-SA439	1101101xx
SA36-SA39	0001001xx	SA172-SA175	0101011xx	SA308-SA311	1001101xx	SA440-SA443	1101110xx
SA40-SA43	0001010xx	SA176-SA179	0101100xx	SA312-SA315	1001110xx	SA444-SA447	11011111xx
SA44-SA47	0001011xx	SA180-SA183	0101101xx	SA316-SA319	1001111xx	SA448-SA451	1110000xx
SA48-SA51	0001100xx	SA184-SA187	0101110xx	SA320-SA323	1010000xx	SA452-SA455	1110001xx
SA52-SA55	0001101xx	SA188-SA191	0101111xx	SA324-SA327	1010001xx	SA456-SA459	1110010xx
SA56-SA59	0001110xx	SA192-SA195	0110000xx	SA328-SA331	1010010xx	SA460-SA463	1110011xx
SA60-SA63	0001111xx	SA196-SA199	0110001xx	SA332-SA335	1010011xx	SA464-SA467	1110100xx
SA64-SA67	0010000xx	SA200-SA203	0110010xx	SA336-SA339	1010100xx	SA468-SA471	1110101xx
SA68-SA71	0010001xx	SA204-SA207	0110011xx	SA340-SA343	1010101xx	SA472-SA475	1110110xx
SA72-SA75	0010010xx	SA208-SA211	0110100xx	SA344-SA347	1010110xx	SA476-SA479	11101111xx
SA76-SA79	0010011xx	SA212-SA215	0110101xx	SA348-SA351	1010111xx	SA480-SA483	1111000xx
SA80-SA83	0010100xx	SA216-SA219	0110110xx	SA352-SA355	1011000xx	SA484-SA487	1111001xx
SA84-SA87	0010101xx	SA220-SA223	0110111xx	SA356-SA359	1011001xx	SA488-SA491	1111010xx
SA88-SA91	0010110xx	SA224-SA227	0111000xx	SA360-SA363	1011010xx	SA492-SA495	1111011xx
SA92-SA95	0010111xx	SA228-SA231	0111001xx	SA364-SA367	1011011xx	SA496-SA499	1111100xx
SA96-SA99	0011000xx	SA232-SA235	0111010xx	SA368-SA371	1011100xx	SA500-SA503	1111101xx
SA100-SA103	0011001xx	SA236-SA239	0111011xx	SA372-SA375	1011101xx	SA504-SA507	1111110xx
SA104-SA107	0011010xx	SA240-SA243	0111100xx	SA376-SA379	1011110xx	SA508	111111100
SA108-SA111	0011011xx	SA244-SA247	0111101xx	SA380-SA383	10111111xx	SA509	111111101
SA112-SA115	0011100xx	SA248-SA251	0111110xx	SA384-SA387	1100000xx	SA510	111111110
SA116-SA119	0011101xx	SA252-SA255	01111111xx	SA388-SA391	1100001xx	SA511	111111111
SA120-SA123	0011110xx	SA256-SA259	1000000xx				



## **Temporary Sector Group Unprotect**

This feature allows temporary unprotection of previously protected sector groups to change data in-system. The Sector Group Unprotect mode is activated by setting the RESET# pin to  $V_{ID}$ . During this mode, formerly protected sector groups can be programmed or erased by selecting the sector group addresses. Once  $V_{ID}$  is removed from the RESET# pin, all the previously protected sector groups are protected again. For this feature, Figure 1 shows the algorithm, and Figure 23 shows the timing diagrams.



#### Notes:

- 1. All protected sector groups unprotected (If WP# =  $V_{IL}$ , the highest or lowest address sector remains protected for uniform sector devices, the top or bottom two address sectors remains protected for boot sector devices).
- 2. All previously protected sector groups are protected once again.

Figure I. Temporary Sector Group Unprotect Operation



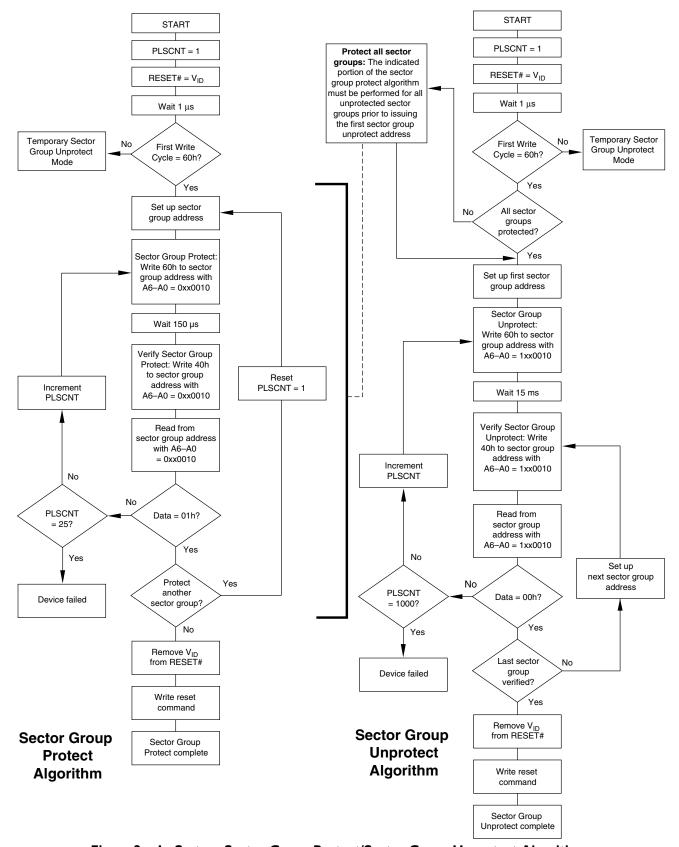


Figure 2. In-System Sector Group Protect/Sector Group Unprotect Algorithms



# **Secured Silicon Sector Flash Memory Region**

The Secured Silicon Sector feature provides a Flash memory region that enables permanent part identification through an Electronic Serial Number (ESN). The Secured Silicon Sector is 256 bytes in length, and uses a Secured Silicon Sector Indicator Bit (DQ7) to indicate whether or not the Secured Silicon Sector is locked when shipped from the factory. This bit is permanently set at the factory and cannot be changed, which prevents cloning of a factory locked part. This ensures the security of the ESN once the product is shipped to the field.

The factory offers the device with the Secured Silicon Sector either customer lockable (standard shipping option) or factory locked (contact a Spansion sales representative for ordering information). The customer-lockable version is shipped with the Secured Silicon Sector unprotected, allowing customers to program the sector after receiving the device. The customer-lockable version also has the Secured Silicon Sector Indicator Bit permanently set to a "0." The factory-locked version is always protected when shipped from the factory, and has the Secured Silicon (Secured Silicon) Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit prevents customer-lockable devices from being used to replace devices that are factory locked.

Note: The ACC function and unlock bypass modes are not available when the Secured Silicon Sector is enabled.

The Secured Silicon sector address space in this device is allocated as follows:

Secured Silicon Se	ector Address Range	Standard	ExpressFlash	Customer		
x16	x8	Factory Locked	Factory Locked	Lockable		
000000h – 000007h	000000h – 00000Fh	ESN	ESN or determined by customer	Determined by		
000008h – 00007Fh	000010h – 0000FFh	Unavailable	Determined by customer	customer		

The system accesses the Secured Silicon Sector through a command sequence (see Write Protect (WP#)). After the system writes the Enter Secured Silicon Sector command sequence, it may read the Secured Silicon Sector by using the addresses normally occupied by the first sector (SAO). This mode of operation continues until the system issues the Exit Secured Silicon Sector command sequence, or until power is removed from the device. On power-up, or following a hardware reset, the device reverts to sending commands to sector SAO.

### Customer Lockable: Secured Silicon Sector Not Programmed or Protected At the Factory

Unless otherwise specified, the device is shipped such that the customer may program and protect the 256-byte Secured Silicon sector.

The system may program the Secured Silicon Sector using the write-buffer, accelerated and/or unlock bypass methods, in addition to the standard programming command sequence (see Command Definitions).

Programming and protecting the Secured Silicon Sector must be used with caution since, once protected, there is no procedure available for unprotecting the Secured Silicon Sector area and none of the bits in the Secured Silicon Sector memory space can be modified in any way.

The Secured Silicon Sector area can be protected using one of the following procedures:

- Write the three-cycle Enter Secured Silicon Sector Region command sequence, and then follow the in-system sector protect algorithm as shown in Figure 2, except that RESET# may be at either V<sub>IH</sub> or V<sub>ID</sub>. This allows in-system protection of the Secured Silicon Sector without raising any device pin to a high voltage. Note that this method is only applicable to the Secured Silicon Sector.
- Write the three-cycle Enter Secured Silicon Sector Region command sequence and then use the alternate method of sector protection described in the "Sector Group Protection and Unprotection" section.

Once the Secured Silicon Sector is programmed, locked, and verified, the system must write the Exit Secured Silicon Sector Region command sequence to return to reading and writing within the remainder of the array.



### Factory Locked: Secured Silicon Sector Programmed and Protected At the Factory

In devices with an ESN, the Secured Silicon Sector is protected when the device is shipped from the factory. The Secured Silicon Sector cannot be modified in any way. An ESN Factory Locked device has an 16-byte random ESN at addresses 000000h–000007h. Please contact your sales representative for details on ordering ESN Factory Locked devices.

Customers may opt to have their code programmed by the factory through the Spansion programming service (Customer Factory Locked). The devices are then shipped from the factory with the Secured Silicon Sector permanently locked. Contact your sales representative for details on using the Spansion programming service.

## Write Protect (WP#)

The Write Protect function provides a hardware method of protecting the first or last sector group without using  $V_{1D}$ . Write Protect is one of two functions provided by the WP#/ACC input.

If the system asserts  $V_{IL}$  on the WP#/ACC pin, the device disables program and erase functions in the first or last sector group independently of whether those sector groups were protected or unprotected. Note that if WP#/ACC is at  $V_{IL}$  when the device is in the standby mode, the maximum input load current is increased (Table 29).

**Note:** If the system asserts VIH on the WP#/ACC pin, the device reverts to whether the first or last sector was previously set to be protected or unprotected using the method described in "Sector Group Protection and Unprotection". Note that WP# has an internal pullup; when unconnected, WP# is at VIH.

### **Hardware Data Protection**

The command sequence requirement of unlock cycles for programming or erasing provides data protection against inadvertent writes (Table 34 and Table 35 contain command definitions). In addition, the following hardware data protection measures prevent accidental erasure or programming, which might otherwise be caused by spurious system level signals during  $V_{CC}$  power-up and power-down transitions, or from system noise.

### Low V<sub>CC</sub> Write Inhibit

When  $V_{CC}$  is less than  $V_{LKO}$ , the device does not accept any write cycles. This protects data during  $V_{CC}$  power-up and power-down. The command register and all internal program/erase circuits are disabled, and the device resets to the read mode. Subsequent writes are ignored until  $V_{CC}$  is greater than  $V_{LKO}$ . The system must provide the proper signals to the control pins to prevent unintentional writes when  $V_{CC}$  is greater than  $V_{LKO}$ .

### Write Pulse "Glitch" Protection

Noise pulses of less than 3 ns (typical) on OE#, CE# or WE# do not initiate a write cycle.

#### Logical Inhibit

Write cycles are inhibited by holding any one of  $OE\# = V_{IL}$ ,  $CE\# = V_{IH}$  or  $WE\# = V_{IH}$ . To initiate a write cycle, CE# and WE# must be a logical zero while OE# is a logical one.

### Power-Up Write Inhibit

If WE# = CE# =  $V_{IL}$  and OE# =  $V_{IH}$  during power up, the device does not accept commands on the rising edge of WE#. The internal state machine is automatically reset to the read mode on power-up.



# **Common Flash Memory Interface (CFI)**

The Common Flash Interface (CFI) specification outlines device and host system software interrogation handshake, which allows specific vendor-specified software algorithms to be used for entire families of devices. Software support can then be device-independent, JEDEC ID-independent, and forward- and backward-compatible for the specified flash device families. Flash vendors can standardize their existing interfaces for long-term compatibility.

This device enters the CFI Query mode when the system writes the CFI Query command, 98h, to address 55h, any time the device is ready to read array data. The system can read CFI information at the addresses given in Table 30 through Table 33. To terminate reading CFI data, the system must write the reset command.

The system can also write the CFI query command when the device is in the autoselect mode. The device enters the CFI query mode, and the system can read CFI data at the addresses given in Table 30 through Table 33. The system must write the reset command to return the device to reading array data.

For further information, please refer to the CFI Specification and CFI Publication 100. Alternatively, contact your sales representative for copies of these documents.

Addresses(x16)	Addresses(x8)	Data	Description					
10h	20h	0051h	Query Unique ASCII string "QRY"					
11h	22h	0052h						
12h	24h	0059h						
13h	26h	0002h	Primary OEM Command Set					
14h	28h	0000h						
15h	2Ah	0040h	Address for Primary Extended Table					
16h	2Ch	0000h						
17h	2Eh	0000h	Alternate OEM Command Set (00h = none exists)					
18h	30h	0000h						
19h	32h	0000h	Address for Alternate OEM Extended Table (00h = none exists)					
1Ah	34h	0000h						

Table 30. CFI Query Identification String

Table 31. System Interface Stri	inσ
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Addresses (x16)	Addresses (x8)	Data	Description					
1Bh	36h	0027h	V <sub>CC</sub> Min. (write/erase) D7-D4: volt, D3-D0: 100 millivolt					
1Ch	38h	0036h	V <sub>CC</sub> Max. (write/erase) D7-D4: volt, D3-D0: 100 millivolt					
1Dh	3Ah	0000h	$V_{pp}$ Min. voltage (00h = no $V_{pp}$ pin present)					
1Eh	3Ch	0000h	$V_{pp}$ Max. voltage (00h = no $V_{pp}$ pin present)					
1Fh	3Eh	0007h	Reserved for future use					
20h	40h	0007h	Typical timeout for Min. size buffer write $2^N \mu s$ (00h = not supported)					
21h	42h	000Ah	Typical timeout per individual block erase 2 <sup>N</sup> ms					
22h	44h	0000h	Typical timeout for full chip erase $2^N$ ms (00h = not supported)					
23h	46h	0001h	Reserved for future use					
24h	48h	0005h	Max. timeout for buffer write 2 <sup>N</sup> times typical					
25h	4Ah	0004h	Max. timeout per individual block erase 2 <sup>N</sup> times typical					
26h	4Ch	0000h	Max. timeout for full chip erase $2^{\mathbb{N}}$ times typical (00h = not supported)					

**Note:** CFI data related to VCC and time-outs may differ from actual VCC and time-outs of the product. Please consult the Ordering Information tables to obtain the VCC range for particular part numbers. See the Erase and Programming Performance table for typical timeout specifications.



Table 32. Device Geometry Definition

Addresses (x16)	Addresses (x8)	Data	Description
27h	4Eh	0019h 0018h 0017h 0016h	Device Size = 2 <sup>N</sup> byte 19 = 256 Mb, 18 = 128 Mb, 17 = 64 Mb, 16 = 32 Mb
28h	50h	000xh	Flash Device Interface description (refer to CFI publication 100) 0000h = x8-only bus devices 0001h = x16-only bus devices 0002h = x8/x16 bus devices
29h	52h	0000h	
2Ah	54h	0005h	Max. number of byte in multi-byte write = $2^N$ (00h = not supported)
2Bh	56h	0000h	
2Ch	58h	0001h 0002h	Number of Erase Block Regions within device (01h = uniform device, 02h = boot device)
2Dh	5Ah	00xxh	Erase Block Region 1 Information (refer to the CFI specification or CFI publication 100) 003Fh, 0000h, 0000h, 0001h = 32 Mb (-R0, -R1, -R2, R5, R6) 007Fh, 0000h, 0020h, 0000h = 32 Mb (-R3, -R4), 64 Mb (-R3, -R4) 007Fh, 0000h, 0000h, 0001h = 64 Mb (-R0, -R1, -R2, -R5, -R6, -R7) 00FFh, 0000h, 0000h, 0001h = 128 Mb 00FFh, 0001h, 0000h, 0001h = 256 Mb
2Eh	5Ch	000xh	
2Fh	5Eh	00x0h	
30h	60h	00x0h	
31h	60h	00xxh	Erase Block Region 2 Information (refer to CFI publication 100) 003Eh, 0000h, 0000h, 0001h = 32 Mb (-R1, -R2) 007Eh, 0000h, 0000h, 0001h = 64 Mb (-R1, -R2) 0000h, 0000h, 0000h, 0000h = all others
32h	64h	0000h	
33h	66h	0000h	
34h	68h	000xh	
35h	6Ah	0000h	Erase Block Region 3 Information (refer to CFI publication 100)
36h	6Ch	0000h	
37h	6Eh	0000h	
38h	70h	0000h	
39h	72h	0000h	Erase Block Region 4 Information (refer to CFI publication 100)
3Ah	74h	0000h	
3Bh	76h	0000h	
3Ch	78h	0000h	



Table 33. Primary Vendor-Specific Extended Query

Addresses (x16)	Addresses (x8)	Data	Description
40h 41h 42h	80h 82h 84h	0050h 0052h 0049h	Query-unique ASCII string "PRI"
43h	86h	0031h	Major version number, ASCII
44h	88h	0033h	Minor version number, ASCII
45h	8Ah	000xh	Address Sensitive Unlock (Bits 1-0) 0 = Required, 1 = Not Required Process Technology (Bits 7-2) 0010b = 0.23 µm MirrorBit 0009h = x8-only bus devices 0008h = all other devices
46h	8Ch	0002h	Erase Suspend 0 = Not Supported, 1 = To Read Only, 2 = To Read & Write
47h	8Eh	0001h	Sector Protect 0 = Not Supported, X = Number of sectors in per group
48h	90h	0001h	Sector Temporary Unprotect 00 = Not Supported, 01 = Supported
49h	92h	0004h	Sector Protect/Unprotect scheme 0004h = Standard Mode (Refer to Text)
4Ah	94h	0000h	Simultaneous Operation 00 = Not Supported, X = Number of Sectors in Bank
4Bh	96h	0000h	Burst Mode Type 00 = Not Supported, 01 = Supported
4Ch	98h	0001h	Page Mode Type 00 = Not Supported, 01 = 4 Word Page, 02 = 8 Word Page
4Dh	9Ah	00B5h	ACC (Acceleration) Supply Minimum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV
4Eh	9Ch	00C5h	ACC (Acceleration) Supply Maximum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV
4Fh	9Eh	00xxh	Top/Bottom Boot Sector Flag  00h = Uniform Device without WP# protect,  02h = Bottom Boot Device, 03h = Top Boot Device,  04h = Uniform sectors bottom WP# protect,  05h = Uniform sectors top WP# protect
50h	A0h	0001h	Program Suspend < 00h = Not Supported, 01h = Supported



# **Command Definitions**

Writing specific address and data commands or sequences into the command register initiates device operations. Table 34 and Table 35 define the valid register command sequences. Writing incorrect address and data values or writing them in the improper sequence may place the device in an unknown state. A reset command is then required to return the device to reading array data.

All addresses are latched on the falling edge of WE# or CE#, whichever happens later. All data is latched on the rising edge of WE# or CE#, whichever happens first. See AC Characteristics for timing diagrams.

# **Reading Array Data**

The device is automatically set to reading array data after device power-up. No commands are required to retrieve data. The device is ready to read array data after completing an Embedded Program or Embedded Erase algorithm.

After the device accepts an Erase Suspend command, the device enters the erase-suspend-read mode, after which the system can read data from any non-erase-suspended sector. After completing a programming operation in the Erase Suspend mode, the system may once again read array data with the same exception. See Erase Suspend/Erase Resume Commands for more information.

The system *must* issue the reset command to return the device to the read (or erase-suspend-read) mode if DQ5 goes high during an active program or erase operation, or if the device is in the autoselect mode. See the next section, Reset Command, for more information.

See also Requirements for Reading Array Data in the Device Bus Operations section for more information. The Read-Only Operations—AC Characteristics provides the read parameters, and Figure 13 shows the timing diagram.

### **Reset Command**

Writing the reset command resets the device to the read or erase-suspend-read mode. Address bits are don't cares for this command.

The reset command may be written between the sequence cycles in an erase command sequence before erasing begins. This resets the device to the read mode. Once erasure begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in a program command sequence before programming begins. This resets the device to the read mode. If the program command sequence is written while the device is in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode. Once programming begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in an autoselect command sequence. Once in the autoselect mode, the reset command must be written to return to the read mode. If the device entered the autoselect mode while in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode.

If DQ5 goes high during a program or erase operation, writing the reset command returns the device to the read mode (or erase-suspend-read mode if the device was in Erase Suspend).

Note that if DQ1 goes high during a Write Buffer Programming operation, the system must write the Write-to-Buffer-Abort Reset command sequence to reset the device for the next operation.



## **Autoselect Command Sequence**

The autoselect command sequence allows the host system to read several identifier codes at specific addresses:

Identifier Code	A7:A0 (x16)	A6:A-1 (x8)
Manufacturer ID	00h	00h
Device ID, Cycle 1	01h	02h
Device ID, Cycle 2	0Eh	1Ch
Device ID, Cycle 3	0Fh	1Eh
Secured Silicon Sector Factory Protect	03h	06h
Sector Protect Verify	(SA)02h	(SA)04h

**Note:** 3. The device ID is read over three cycles. SA = Sector Address

The autoselect command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle that contains the autoselect command. The device then enters the autoselect mode. The system may read at any address any number of times without initiating another autoselect command sequence:

The system must write the reset command to return to the read mode (or erase-suspend-read mode if the device was previously in Erase Suspend).

## **Enter/Exit Secured Silicon Sector Command Sequence**

The Secured Silicon Sector region provides a secured data area containing an 8-word/16-byte random Electronic Serial Number (ESN). The system can access the Secured Silicon Sector region by issuing the three-cycle Enter Secured Silicon Sector command sequence. The device continues to access the Secured Silicon Sector region until the system issues the four-cycle Exit Secured Silicon Sector command sequence. The Exit Secured Silicon Sector command sequence returns the device to normal operation. Table 34 and Table 35 show the address and data requirements for both command sequences. Also, see Secured Silicon Sector Flash Memory Region for further information. Note that the ACC function and unlock bypass modes are not available when the Secured Silicon Sector is enabled.

### **Word Program Command Sequence**

Programming is a four-bus-cycle operation. The program command sequence is initiated by writing two unlock write cycles, followed by the program set-up command. The program address and data are written next, which in turn initiate the Embedded Program algorithm. The system is not required to provide further controls or timings. The device automatically provides internally generated program pulses and verifies the programmed cell margin. Table 34 and Table 35 show the address and data requirements for the word program command sequence, respectively.

When the Embedded Program algorithm is complete, the device then returns to the read mode and addresses are no longer latched. The system can determine the status of the program operation by using DQ7 or DQ6. See Write Operation Status for information on these status bits. Any commands written to the device during the Embedded Program Algorithm are ignored. *Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress.* Note that a **hardware reset** immediately terminates the program operation. The program command sequence should be reinitiated once the device returns to the read mode, to ensure data integrity.

Programming is allowed in any sequence of address locations and across sector boundaries. Programming to the same word address multiple times without intervening erases (incremental bit programming) requires a modified programming method. For such application requirements, please contact your local Spansion representative. Word programming is supported for backward compatibility with existing Flash driver software and for occasional writing of individual words. Use of write buffer programming (see below) is strongly recommended for general programming use when more than a few words are to be programmed. The effective word programming time using write buffer programming is approximately four times shorter than the single word programming time.



Any bit in a word cannot be programmed from "0" back to a "1." Attempting to do so may cause the device to set DQ5=1, or cause DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read shows that the data is still "0." Only erase operations can convert a "0" to a "1."

### **Unlock Bypass Command Sequence**

The unlock bypass feature allows the system to program words to the device faster than using the standard program command sequence. The unlock bypass command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the unlock bypass command, 20h. The device then enters the unlock bypass mode. A two-cycle unlock bypass mode command sequence is all that is required to program in this mode. The first cycle in this sequence contains the unlock bypass program command, A0h; the second cycle contains the program address and data. Additional data is programmed in the same manner. This mode dispenses with the initial two unlock cycles required in the standard program command sequence, resulting in faster total programming time. Table 34 and Table 35 show the requirements for the command sequence.

During the unlock bypass mode, only the Unlock Bypass Program and Unlock Bypass Reset commands are valid. To exit the unlock bypass mode, the system must issue the two-cycle unlock bypass reset command sequence. The first cycle must contain the data 90h. The second cycle must contain the data 00h. The device then returns to the read mode.

### Write Buffer Programming

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. The Write Buffer Programming command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the Write Buffer Load command written at the Sector Address in which programming occurs. The fourth cycle writes the sector address and the number of word locations, minus one, to be programmed. For example, if the system programs six unique address locations, then 05h should be written to the device. This tells the device how many write buffer addresses are loaded with data and therefore when to expect the Program Buffer to Flash command. The number of locations to program cannot exceed the size of the write buffer or the operation aborts.

The fifth cycle writes the first address location and data to be programmed. The write-buffer-page is selected by address bits  $A_{MAX}$ – $A_4$ . All subsequent address/data pairs must fall within the selected-write-buffer-page. The system then writes the remaining address/data pairs into the write buffer. Write buffer locations may be loaded in any order.

The write-buffer-page address must be the same for all address/data pairs loaded into the write buffer. (This means Write Buffer Programming cannot be performed across multiple write-buffer pages.) This also means that Write Buffer Programming cannot be performed across multiple sectors. If the system attempts to load programming data outside of the selected write-buffer page, the operation aborts.

Note that if a Write Buffer address location is loaded multiple times, the address/data pair counter is decremented for every data load operation. The host system must therefore account for loading a write-buffer location more than once. The counter decrements for each data load operation, not for each unique write-buffer-address location. Note also that if an address location is loaded more than once into the buffer, the final data loaded for that address is programmed.

Once the specified number of write buffer locations are loaded, the system must then write the Program Buffer to Flash command at the sector address. Any other address and data combination aborts the Write Buffer Programming operation. The device then begins programming. Data polling should be used while monitoring the last address location loaded into the write buffer. DQ7, DQ6, DQ5, and DQ1 should be monitored to determine the device status during Write Buffer Programming.

The write-buffer programming operation can be suspended using the standard program suspend/ resume commands. Upon successful completion of the Write Buffer Programming operation, the device is ready to execute the next command.

The Write Buffer Programming Sequence can be aborted in the following ways:

Load a value that is greater than the page buffer size during the Number of Locations to Program step.



- Write to an address in a sector different than the one specified during the Write-Buffer-Load command.
- Write an Address/Data pair to a different write-buffer-page than the one selected by the Starting Address during the write buffer data loading stage of the operation.
- Write data other than the Confirm Command after the specified number of data load cycles.

The abort condition is indicated by DQ1 = 1, DQ7 = DATA# (for the last address location loaded), DQ6 = toggle, and DQ5 = 0. A Write-to-Buffer-Abort Reset command sequence must be written to reset the device for the next operation.

Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress. This flash device is capable of handling multiple write buffer programming operations on the same write buffer address range without intervening erases. For applications requiring incremental bit programming, a modified programming method is required; please contact your local Spansion representative. **Any bit in a write buffer address range cannot be programmed from "0" back to a "1."** Attempting to do so can cause the device to set DQ5=1, of cause the DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read shows that the data is still "0." Only erase operations can convert a "0" to a "1."

### **Accelerated Program**

The device offers accelerated program operations through the WP#/ACC or ACC pin depending on the particular product. When the system asserts  $V_{HH}$  on the WP#/ACC or ACC pin. The device uses the higher voltage on the WP#/ACC or ACC pin to accelerate the operation. Note that the WP#/ACC pin must not be at  $V_{HH}$  for operations other than accelerated programming, or device damage can result. WP# has an internal pullup; when unconnected, WP# is at  $V_{IH}$ .

Figure 3 illustrates the algorithm for the program operation. See Erase and Program Operations—S29GL032M Only and AC Characteristics for parameters, and Figure 14 for timing diagrams.



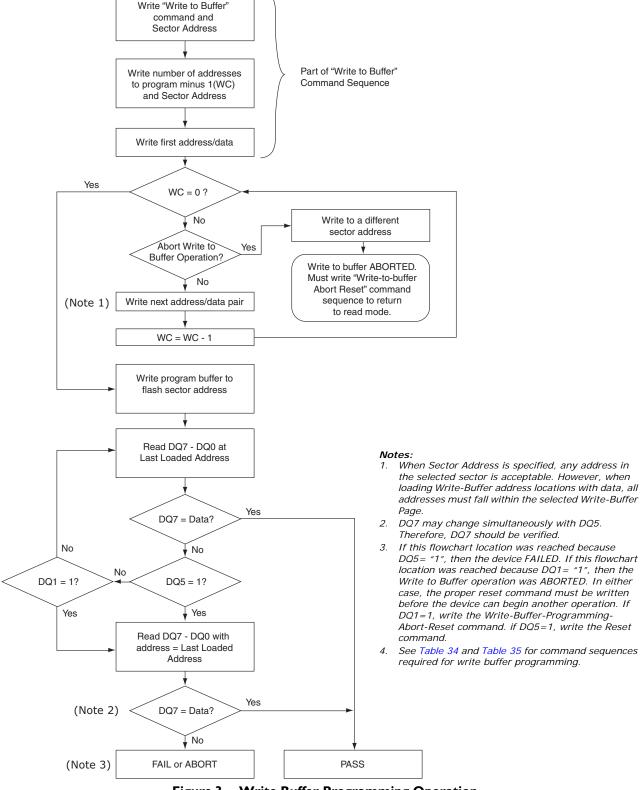
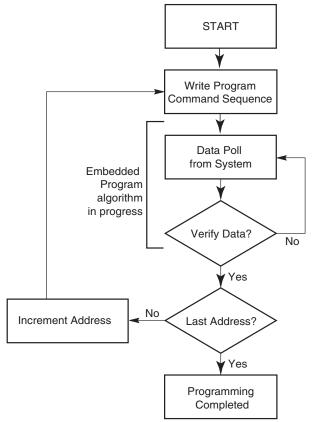


Figure 3. Write Buffer Programming Operation





Note: See Table 34 and Table 35 for program command sequence

Figure 4. Program Operation

# **Program Suspend/Program Resume Command Sequence**

The Program Suspend command allows the system to interrupt a programming operation or a Write to Buffer programming operation so that data can be read from any non-suspended sector. When the Program Suspend command is written during a programming process, the device halts the program operation within 15  $\mu$ s maximum (5  $\mu$ s typical) and updates the status bits. Addresses are not required when writing the Program Suspend command.

After the programming operation is suspended, the system can read array data from any non-suspended sector. The Program Suspend command can also be issued during a programming operation while an erase is suspended. In this case, data can be read from any addresses not in Erase Suspend or Program Suspend. If a read is needed from the Secured Silicon Sector area (One-time Program area), then user must use the proper command sequences to enter and exit this region. Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress.

The system can also write the autoselect command sequence when the device is in the Program Suspend mode. The system can read as many autoselect codes as required. When the device exits the autoselect mode, the device reverts to the Program Suspend mode, and is ready for another valid operation. See Autoselect Command Sequence for more information.

After the Program Resume command is written, the device reverts to programming. The system can determine the status of the program operation using the DQ7 or DQ6 status bits, just as in the standard program operation. See Write Operation Status for more information.

The system must write the Program Resume command (address bits are don't care) to exit the Program Suspend mode and continue the programming operation. Further writes of the Resume command are ignored. Another Program Suspend command can be written after the device resumes programming.



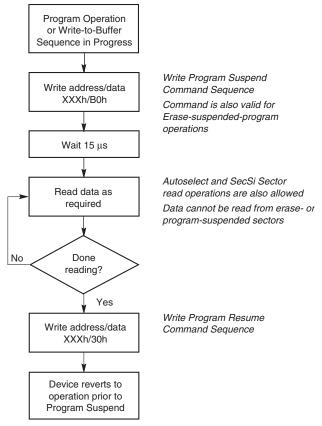


Figure 5. Program Suspend/Program Resume

# **Chip Erase Command Sequence**

Chip erase is a six bus cycle operation. The chip erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock write cycles are then followed by the chip erase command, which in turn invokes the Embedded Erase algorithm. The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically preprograms and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations. Table 34 and Table 35 show the address and data requirements for the chip erase command sequence.

When the Embedded Erase algorithm is complete, the device returns to the read mode and addresses are no longer latched. The system can determine the status of the erase operation by using DQ7, DQ6, or DQ2. See Write Operation Status for information on these status bits.

Any commands written during the chip erase operation are ignored. However, note that a **hard-ware reset** immediately terminates the erase operation. If that occurs, the chip erase command sequence should be reinitiated once the device returns to reading array data, to ensure data integrity.

Figure 6 illustrates the algorithm for the erase operation. See Erase and Programming Performance in AC Characteristics for parameters, and Figure 18 for timing diagrams.

# **Sector Erase Command Sequence**

Sector erase is a six bus cycle operation. The sector erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock cycles are written, and are then followed by the address of the sector to be erased, and the sector erase command. Table 34 and Table 35 shows the address and data requirements for the sector erase command sequence.



The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically programs and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations.

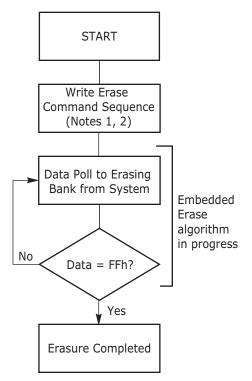
After the command sequence is written, a sector erase time-out of 50 µs occurs. During the time-out period, additional sector addresses and sector erase commands can be written. Loading the sector erase buffer can be done in any sequence, and the number of sectors can be from one sector to all sectors. The time between these additional cycles must be less than 50 µs, otherwise erasure may begin. Any sector erase address and command following the exceeded time-out can or cannot be accepted. It is recommended that processor interrupts be disabled during this time to ensure all commands are accepted. The interrupts can be re-enabled after the last Sector Erase command is written. Any command other than Sector Erase or Erase Suspend during the time-out period resets the device to the read mode. Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when an erase operation is in progress. The system must rewrite the command sequence and any additional addresses and commands.

The system can monitor DQ3 to determine if the sector erase timer has timed out (See the section on DQ3: Sector Erase Timer.). The time-out begins from the rising edge of the final WE# pulse in the command sequence.

When the Embedded Erase algorithm is complete, the device returns to reading array data and addresses are no longer latched. The system can determine the status of the erase operation by reading DQ7, DQ6, or DQ2 in the erasing sector. See Write Operation Status for information on these status bits.

Once the sector erase operation starts, only the Erase Suspend command is valid. All other commands are ignored. However, note that a **hardware reset** immediately terminates the erase operation. If that occurs, the sector erase command sequence should be reinitiated once the device returns to reading array data, to ensure data integrity.

Figure 6 illustrates the algorithm for the erase operation. See Erase and Programming Performance in AC Characteristics for parameters, and Figure 18 for timing diagrams.



#### Notes:

- 1. See Table 34 and Table 35 for program command sequence.
- 2. See DQ3: Sector Erase Timer for information on the sector erase timer.

Figure 6. Erase Operation



## **Erase Suspend/Erase Resume Commands**

The Erase Suspend command, B0h, allows the system to interrupt a sector erase operation and then read data from, or program data to, any sector not selected for erasure. This command is valid only during the sector erase operation, including the  $50~\mu s$  time-out period during the sector erase command sequence. The Erase Suspend command is ignored if written during the chip erase operation or Embedded Program algorithm.

When the Erase Suspend command is written during the sector erase operation, the device requires a typical of 5  $\mu$ s (maximum of 20  $\mu$ s) to suspend the erase operation. However, when the Erase Suspend command is written during the sector erase time-out, the device immediately terminates the time-out period and suspends the erase operation.

After the erase operation is suspended, the device enters the erase-suspend-read mode. The system can read data from or program data to any sector not selected for erasure. (The device "erase suspends" all sectors selected for erasure.) Reading at any address within erase-suspended sectors produces status information on DQ7–DQ0. The system can use DQ7, or DQ6 and DQ2 together, to determine if a sector is actively erasing or is erase-suspended. See Write Operation Status for information on these status bits.

After an erase-suspended program operation is complete, the device returns to the erase-suspend-read mode. The system can determine the status of the program operation using the DQ7 or DQ6 status bits, just as in the standard word program operation. See Write Operation Status for more information.

In the erase-suspend-read mode, the system can also issue the autoselect command sequence. See Autoselect Mode and Autoselect Command Sequence for details.

To resume the sector erase operation, the system must write the Erase Resume command. Further writes of the Resume command are ignored. Another Erase Suspend command can be written after the chip resumes erasing.

**Note:** During an erase operation, this flash device performs multiple internal operations which are invisible to the system. When an erase operation is suspended, any of the internal operations that were not fully completed must be restarted. As such, if this flash device is continually issued suspend/resume commands in rapid succession, erase progress are impeded as a function of the number of suspends. The result is a longer cumulative erase time than without suspends. Note that the additional suspends do not affect device reliability or future performance. In most systems rapid erase/suspend activity occurs only briefly. In such cases, erase performance is not significantly impacted.



### **Command Definitions**

Table 34. Command Definitions (xI6 Mode, BYTE# =  $V_{IH}$ )

Command		Cycles	Bus Cycles (Notes 2–5)												
	Sequence (Note 1)		First		Seco	ond	Third		Fourth		Fifth		Sixth		
			Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	
Rea	d (6)	1	RA	RD											
Res	et (7)	1	XXX	F0											
8)	Manufacturer ID	4	555	AA	2AA	55	555	90	X00	0001					
	Device ID (9)	4	555	AA	2AA	55	555	90	X01	227E	XOE	(Note 18)	XOF	(Note 18)	
Autoselect (Note	Secured Silicon Sector Factory Protect (10)	4	555	AA	2AA	55	555	90	X03	(Note 10)					
Autos	Sector Group Protect Verify (12)	4	555	AA	2AA	55	555	90	(SA)X02	00/01					
Ente	er Secured Silicon Sector Region	3	555	AA	2AA	55	555	88							
Exit	Exit Secured Silicon Sector Region		555	AA	2AA	55	555	90	XXX	00					
Prog	Program		555	AA	2AA	55	555	AO	PA	PD					
Writ	e to Buffer (11)	3	555	AA	2AA	55	SA	25	SA	WC	PA	PD	WBL	PD	
Prog	gram Buffer to Flash	1	SA	29											
Writ	e to Buffer Abort Reset (13)	3	555	AA	2AA	55	555	F0							
Unlo	ock Bypass	3	555	AA	2AA	55	555	20							
Unlo	ock Bypass Program (14)	2	XXX	A0	PA	PD									
Unlo	ock Bypass Reset (15)	2	XXX	90	XXX	00									
Chip	Chip Erase		555	AA	2AA	55	555	80	555	AA	2AA	55	555	10	
Sec	tor Erase	6	555	AA	2AA	55	555	80	555	AA	2AA	55	SA	30	
Prog	gram/Erase Suspend (16)	1	XXX	В0											
Prog	gram/Erase Resume (16)	1	XXX	30											
CFI	Query (18)	1	55	98											

#### Legend:

X = Don't care

RA = Read Address of memory location to be read.

RD = Read Data read from location RA during read operation.

PA = Program Address. Addresses latch on falling edge of WE# or CE# pulse, whichever happens later.

#### Notes:

- 1. See Table 1 for description of bus operations.
- 2. All values are in hexadecimal.
- 3. Shaded cells indicate read cycles. All others are write cycles.
- During unlock and command cycles, when lower address bits are 555 or 2AA as shown in table, address bits above A11 and data bits above DQ7 are don't care.
- No unlock or command cycles required when device is in read mode.
- Reset command is required to return to read mode (or to erasesuspend-read mode if previously in Erase Suspend) when device is in autoselect mode, or if DQ5 goes high while device is providing status information.
- Fourth cycle of the autoselect command sequence is a read cycle. Data bits DQ15–DQ8 are don't care. Except for RD, PD and WC. See Autoselect Command Sequence for more information.
- 8. Device ID must be read in three cycles.
- If WP# protects highest address sector, data is 98h for factory locked and 18h for not factory locked. If WP# protects lowest address sector, data is 88h for factory locked and 08h for not factor locked.

PD = Program Data for location PA. Data latches on rising edge of WE# or CE# pulse, whichever happens first.

SA = Sector Address of sector to be verified (in autoselect mode) or erased. Address bits A21–A15 uniquely select any sector.

WBL = Write Buffer Location. Address must be within same write buffer page as PA.

WC = Word Count. Number of write buffer locations to load minus 1.

- Data is 00h for an unprotected sector group and 01h for a protected sector group.
- 11. Total number of cycles in command sequence is determined by number of words written to write buffer. Maximum number of cycles in command sequence is 21, including "Program Buffer to Flash" command.
- 12. Command sequence resets device for next command after aborted write-to-buffer operation.
- 13. Unlock Bypass command is required prior to Unlock Bypass Program command.
- Unlock Bypass Reset command is required to return to read mode when device is in unlock bypass mode.
- 15. System may read and program in non-erasing sectors, or enter autoselect mode, when in Erase Suspend mode. Erase Suspend command is valid only during a sector erase operation.
- Erase Resume command is valid only during Erase Suspend mode
- 17. Command is valid when device is ready to read array data or when device is in autoselect mode.
- 18. Refer to Table 17, AutoSelect Codes for individual Device IDs per device density and model number.



Table 35. Command Definitions (x8 Mode, BYTE# =  $V_{IL}$ )

Command			Bus Cycles (Notes 2–5)											
Sequence (Note 1)		ycles	First		Second		Third		Fourth		Fifth		Sixth	
		S	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
Read	d (6)	1	RA	RD										
Rese	et (7)	1	XXX	FO										
	Manufacturer ID	4	AAA	AA	555	55	AAA	90	X00	01				
elect 8)	Device ID (9)	4	AAA	AA	555	55	AAA	90	X02	7E	X1C	(Note 17)	X1E	(Note 17)
Autoselect (Note 8)	Secured Silicon Sector Factory Protect (10)	4	AAA	AA	555	55	AAA	90	X06	(Note 10)				
1	Sector Group Protect Verify (12)	4	AAA	AA	555	55	AAA	90	(SA)X04	00/01				
Ente	r Secured Silicon Sector Region	3	AAA	AA	555	55	AAA	88						
Exit	Secured Silicon Sector Region	4	AAA	AA	555	55	AAA	90	XXX	00				
Writ	e to Buffer (11)	3	AAA	AA	555	55	SA	25	SA	BC	PA	PD	WBL	PD
Prog	ram Buffer to Flash	1	SA	29										
Writ	e to Buffer Abort Reset (13)	3	AAA	AA	555	55	AAA	F0						
Chip	Erase	6	AAA	AA	555	55	AAA	80	AAA	AA	555	55	AAA	10
Sector Erase		6	AAA	AA	555	55	AAA	80	AAA	AA	555	55	SA	30
Program/Erase Suspend (14)		1	XXX	В0										
Prog	ram/Erase Resume (15)	1	XXX	30										
CFI	Query (16)	1	AA	98										

### Legend:

X = Don't care

RA = Read Address of memory location to be read.

RD = Read Data read from location RA during read operation.

PA = Program Address. Addresses latch on falling edge of WE# or CE# pulse, whichever happens later.

#### Notes:

- 1. See Table 1 for description of bus operations.
- All values are in hexadecimal.
- 3. Shaded cells indicate read cycles. All others are write cycles.
- During unlock and command cycles, when lower address bits are 555 or AAA as shown in table, address bits above A11 are don't care.
- 5. Unless otherwise noted, address bits A21–A11 are don't cares.
- No unlock or command cycles required when device is in read mode.
- Reset command is required to return to read mode (or to erasesuspend-read mode if previously in Erase Suspend) when device is in autoselect mode, or if DQ5 goes high while device is providing status information.
- 8. Fourth cycle of autoselect command sequence is a read cycle.

  Data bits DQ15–DQ8 are don't care. See Autoselect Command
  Sequence section or more information.
- 9. Device ID must be read in three cycles.

PD = Program Data for location PA. Data latches on rising edge of WE# or CE# pulse, whichever happens first.

SA = Sector Address of sector to be verified (in autoselect mode) or erased. Address bits A21–A15 uniquely select any sector.

WBL = Write Buffer Location. Address must be within same write buffer page as PA.

BC = Byte Count. Number of write buffer locations to load minus 1.

- 10. If WP# protects highest address sector, data is 98h for factory locked and 18h for not factory locked. If WP# protects lowest address sector, data is 88h for factory locked and 08h for not factor locked.
- 11. Data is 00h for an unprotected sector group and 01h for a protected sector group.
- 12. Total number of cycles in command sequence is determined by number of bytes written to write buffer. Maximum number of cycles in command sequence is 37, including "Program Buffer to Flash" command.
- 13. Command sequence resets device for next command after aborted write-to-buffer operation.
- 14. System may read and program in non-erasing sectors, or enter autoselect mode, when in Erase Suspend mode. Erase Suspend command is valid only during a sector erase operation.
- 15. Erase Resume command is valid only during Erase Suspend
- Command is valid when device is ready to read array data or when device is in autoselect mode.
- 17. Refer to Table 17, AutoSelect Codes for individual Device IDs per device density and model number.



# **Write Operation Status**

The device provides several bits to determine the status of a program or erase operation: DQ2, DQ3, DQ5, DQ6, and DQ7. Table 36 and the following subsections describe the function of these bits. DQ7 and DQ6 each offer a method for determining whether a program or erase operation is complete or in progress. The device also provides a hardware-based output signal, RY/BY#, to determine whether an Embedded Program or Erase operation is in progress or is completed.

# **DQ7: Data# Polling**

The Data# Polling bit, DQ7, indicates to the host system whether an Embedded Program or Erase algorithm is in progress or completed, or whether the device is in Erase Suspend. Data# Polling is valid after the rising edge of the final WE# pulse in the command sequence.

During the Embedded Program algorithm, the device outputs on DQ7 the complement of the datum programmed to DQ7. This DQ7 status also applies to programming during Erase Suspend. When the Embedded Program algorithm is complete, the device outputs the datum programmed to DQ7. The system must provide the program address to read valid status information on DQ7. If a program address falls within a protected sector, Data# Polling on DQ7 is active for approximately 1  $\mu$ s, then the device returns to the read mode.

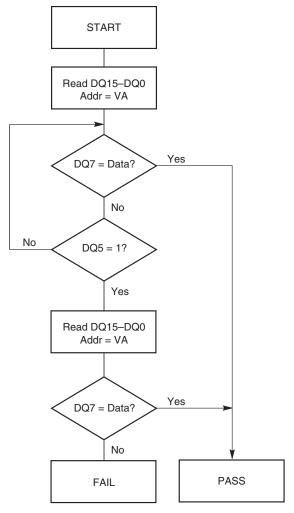
During the Embedded Erase algorithm, Data# Polling produces a "0" on DQ7. When the Embedded Erase algorithm is complete, or if the device enters the Erase Suspend mode, Data# Polling produces a "1" on DQ7. The system must provide an address within any of the sectors selected for erasure to read valid status information on DQ7.

After an erase command sequence is written, if all sectors selected for erasing are protected, Data# Polling on DQ7 is active for approximately 100  $\mu$ s, then the device returns to the read mode. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected. However, if the system reads DQ7 at an address within a protected sector, the status may not be valid.

Just prior to the completion of an Embedded Program or Erase operation, DQ7 can change asynchronously with DQ0–DQ6 while Output Enable (OE#) is asserted low. That is, the device can change from providing status information to valid data on DQ7. Depending on when the system samples the DQ7 output, it can read the status or valid data. Even if the device has completed the program or erase operation and DQ7 has valid data, the data outputs on DQ0–DQ6 may be still invalid. Valid data on DQ0–DQ7 appears on successive read cycles.

Table 36 shows the outputs for Data# Polling on DQ7. Figure 7 shows the Data# Polling algorithm. Figure 17 shows the Data# Polling timing diagram.





### Notes:

- VA = Valid address for programming. During a sector erase operation, a valid address is any sector address within the sector being erased. During chip erase, a valid address is any non-protected sector address.
- DQ7 should be rechecked even if DQ5 = "1" because DQ7 can change simultaneously with DQ5.

Figure 7. Data# Polling Algorithm

# RY/BY#: Ready/Busy#

The RY/BY# is a dedicated, open-drain output pin which indicates whether an Embedded Algorithm is in progress or complete. The RY/BY# status is valid after the rising edge of the final WE# pulse in the command sequence. Since RY/BY# is an open-drain output, several RY/BY# pins can be tied together in parallel with a pull-up resistor to  $V_{CC}$ .

If the output is low (Busy), the device is actively erasing or programming. (This includes programming in the Erase Suspend mode.) If the output is high (Ready), the device is in the read mode, the standby mode, or in the erase-suspend-read mode. Table 36 shows the outputs for RY/BY#.

# **DQ6: Toggle Bit I**

Toggle Bit I on DQ6 indicates whether an Embedded Program or Erase algorithm is in progress or complete, or whether the device entered the Erase Suspend mode. Toggle Bit I may be read at any address, and is valid after the rising edge of the final WE# pulse in the command sequence (prior to the program or erase operation), and during the sector erase time-out.

During an Embedded Program or Erase algorithm operation, successive read cycles to any address cause DQ6 to toggle. The system may use either OE# or CE# to control the read cycles. When the operation is complete, DQ6 stops toggling.



After an erase command sequence is written, if all sectors selected for erasing are protected, DQ6 toggles for approximately 100  $\mu$ s, then returns to reading array data. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected.

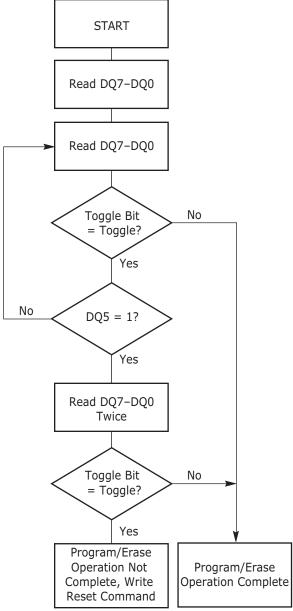
The system can use DQ6 and DQ2 together to determine whether a sector is actively erasing or is erase-suspended. When the device is actively erasing (that is, the Embedded Erase algorithm is in progress), DQ6 toggles. When the device enters the Erase Suspend mode, DQ6 stops toggling. However, the system must also use DQ2 to determine which sectors are erasing or erase-suspended. Alternatively, the system can use DQ7 (see the subsection on DQ7: Data# Polling).

If a program address falls within a protected sector, DQ6 toggles for approximately 1 µs after the program command sequence is written, then returns to reading array data.

DQ6 also toggles during the erase-suspend-program mode, and stops toggling once the Embedded Program algorithm is complete.

Table 36 shows the outputs for Toggle Bit I on DQ6. Figure 8 shows the toggle bit algorithm. Figure 20 shows the toggle bit timing diagrams. Figure 21 shows the differences between DQ2 and DQ6 in graphical form. Also, see DQ2: Toggle Bit II.





**Note:** The system should recheck the toggle bit even if DQ5 = "1" because the toggle bit may stop toggling as DQ5 changes to "1." See the subsections on DQ6 and DQ2 for more information.

Figure 8. Toggle Bit Algorithm

# **DQ2: Toggle Bit II**

The "Toggle Bit II" on DQ2, when used with DQ6, indicates whether a particular sector is actively erasing (that is, the Embedded Erase algorithm is in progress), or whether that sector is erase-suspended. Toggle Bit II is valid after the rising edge of the final WE# pulse in the command sequence.

DQ2 toggles when the system reads at addresses within those sectors that are selected for erasure. (The system may use either OE# or CE# to control the read cycles.) But DQ2 cannot distinguish whether the sector is actively erasing or is erase-suspended. DQ6, by comparison, indicates whether the device is actively erasing, or is in Erase Suspend, but cannot distinguish which sectors are selected for erasure. Thus, both status bits are required for sector and mode information. Refer to Table 36 to compare outputs for DQ2 and DQ6.



Figure 8 shows the toggle bit algorithm in flowchart form, and the section "DQ2: Toggle Bit II" explains the algorithm, also see RY/BY#: Ready/Busy#. Figure 20 shows the toggle bit timing diagram. Figure 21 shows the differences between DQ2 and DQ6 in graphical form.

Whenever the system initially begins reading toggle bit status, it must read DQ7–DQ0 at least twice in a row to determine whether a toggle bit is toggling. Typically, the system would note and store the value of the toggle bit after the first read. After the second read, the system would compare the new value of the toggle bit with the first. If the toggle bit is not toggling, the device has completed the program or erase operation. The system can read array data on DQ7–DQ0 on the following read cycle.

However, if after the initial two read cycles, the system determines that the toggle bit is still toggling, the system also should note whether the value of DQ5 is high (see the section on DQ5). If it is, the system should then determine again whether the toggle bit is toggling, since the toggle bit may have stopped toggling just as DQ5 went high. If the toggle bit is no longer toggling, the device has successfully completed the program or erase operation. If it is still toggling, the device did not completed the operation successfully, and the system must write the reset command to return to reading array data.

The remaining scenario is that the system initially determines that the toggle bit is toggling and DQ5 did not go high. The system may continue to monitor the toggle bit and DQ5 through successive read cycles, determining the status as described in the previous paragraph. Alternatively, it may choose to perform other system tasks. In this case, the system must start at the beginning of the algorithm when it returns to determine the status of the operation (top of Figure 6).

# **DQ5: Exceeded Timing Limits**

DQ5 indicates whether the program, erase, or write-to-buffer time exceeded a specified internal pulse count limit. Under these conditions DQ5 produces a "1," indicating that the program or erase cycle was not successfully completed.

The device may output a "1" on DQ5 if the system tries to program a "1" to a location that was previously programmed to "0." **Only an erase operation can change a "0" back to a "1."** Under this condition, the device halts the operation, and when the timing limit is exceeded, DQ5 produces a "1."

In all these cases, the system must write the reset command to return the device to the reading the array (or to erase-suspend-read if the device was previously in the erase-suspend-program mode).

# **DQ3: Sector Erase Timer**

After writing a sector erase command sequence, the system may read DQ3 to determine whether or not erasure started. (The sector erase timer does not apply to the chip erase command.) If additional sectors are selected for erasure, the entire time-out also applies after each additional sector erase command. When the time-out period is complete, DQ3 switches from a "0" to a "1." If the time between additional sector erase commands from the system can be assumed to be less than 50 µs, the system need not monitor DQ3(see Sector Erase Command Sequence).

After the sector erase command is written, the system should read the status of DQ7 (Data# Polling) or DQ6 (Toggle Bit I) to ensure that the device accepted the command sequence, and then reads DQ3. If DQ3 is "1," the Embedded Erase algorithm started; all further commands (except Erase Suspend) are ignored until the erase operation is complete. If DQ3 is "0," the device accepts additional sector erase commands. To ensure the command was accepted, the system software should check the status of DQ3 prior to and following each subsequent sector erase command. If DQ3 is high on the second status check, the last command might not have been accepted.

Table 36 shows the status of DQ3 relative to the other status bits.

# **DQI: Write-to-Buffer Abort**

DQ1 indicates whether a Write-to-Buffer operation was aborted. Under these conditions DQ1 produces a "1". The system must issue the Write-to-Buffer-Abort-Reset command sequence to return the device to reading array data. See Write Buffer for more details.



### Table 36. Write Operation Status

		Status	DQ7 (Note 2	DQ6	DQ5 (Note 1)	DQ3	DQ2 (Note 2)	DQ1	RY/BY#
Standar	Embedded Program Algorithm		DQ7#	Toggle	0	N/A	No toggle	0	0
d Mode	Embedded Erase Algorithm		0	Toggle	0	1	Toggle	N/A	0
Program	Program- Suspend Read	Program-Suspended Sector	Invalid (not allowed)						1
Suspend		Non-Program Suspended Sector	Data					1	
	Erase-	Erase-Suspended Sector	1	No toggle	0	N/A	Toggle	N/A	1
Erase Suspend	Suspend Read	Non-Erase Suspended Sector			Data	,			1
Mode	Erase-Suspend-Program (Embedded Program)		DQ7#	Toggle	0	N/A	N/A	N/A	0
Write-	Busy (Note 3)	Busy (Note 3)		Toggle	0	N/A	N/A	0	0
to- Buffer	Abort (Note 4)		DQ7#	Toggle	0	N/A	N/A	1	0

- 1. DQ5 switches to '1' when an Embedded Program, Embedded Erase, or Write-to-Buffer operation
- exceeded the maximum timing limits. Refer to the section on DQ5 for more information. DQ7 and DQ2 require a valid address when reading status information. Refer to the appropriate subsection for further details.
- The Data# Polling algorithm should be used to monitor the last loaded write-buffer address location.
- 4. DQ1 switches to '1' when the device aborts the write-to-buffer operation



# **Absolute Maximum Ratings**

Storage Temperature, Plastic Packages		-65°C to +150°C	
Ambient Temperature with Power Applied	Ambient Temperature with Power Applied		
	V <sub>CC</sub> (Note 1)	-0.5 V to +4.0 V	
Voltage with Respect to Ground	A9, OE#, ACC and RESET# (Note 2)	–0.5 V to +12.5 V	
	All other pins (Note 1)	–0.5 V to V <sub>CC</sub> +0.5 V	
Output Short Circuit Current (Note 3)	200 mA		

### Notes:

- 1. Minimum DC voltage on input or I/Os is -0.5 V. During voltage transitions, inputs or I/Os may overshoot  $V_{SS}$  to -2.0 V for periods of up to 20 ns. See Figure 9, Maximum Negative Overshoot Waveform. Maximum DC voltage on input or I/Os is  $V_{CC}$  + 0.5 V. During voltage transitions, input or I/O pins may overshoot to  $V_{CC}$  + 2.0 V for periods up to 20 ns. See Figure 10.
- Minimum DC input voltage on pins A9, OE#, ACC, and RESET# is -0.5 V. During voltage transitions, A9, OE#, ACC, and RESET# may overshoot V<sub>SS</sub> to -2.0 V for periods of up to 20 ns. See Figure 9. Maximum DC input voltage on pin A9, OE#, ACC, and RESET# is +12.5 V which may overshoot to +14.0V for periods up to 20 ns.
- 3. No more than one output may be shorted to ground at a time. Duration of the short circuit should not be greater than one second.
- 4. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this data sheet is not implied. Exposure of the device to absolute maximum rating conditions for extended periods may affect device reliability.

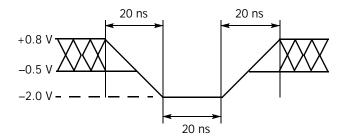


Figure 9. Maximum Negative Overshoot Waveform

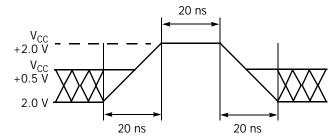


Figure 10. Maximum Positive Overshoot Waveform

# **Operating Ranges**

Ambient Temperature (T <sub>A</sub> )	Industrial (I) Devices	-40°C to +85°C
	V <sub>CC</sub> for full voltage range	+2.7 V to +3.6 V
Supply Voltages	V <sub>CC</sub> for regulated voltage range	+3.0 V to +3.6 V
	V <sub>IO</sub>	V <sub>CC</sub>

**Note:** Operating ranges define those limits between which the functionality of the device is guaranteed.



# **CMOS** Compatible

Parameter Symbol	Parameter Description (Notes)	Test Conditio	ns	Min	Тур	Max	Uni t
I <sub>LI</sub>	Input Load Current (1)	$V_{IN} = V_{SS}$ to $V_{CC}$ , $V_{CC} = V_{CC \text{ max}}$				±1.0	μΑ
I <sub>LIT</sub>	A9, ACC Input Load Current	$V_{CC} = V_{CC \text{ max}}; A9 = 12$	2.5 V			35	μΑ
$I_{LR}$	Reset Leakage Current	$V_{CC} = V_{CC \text{ max}}$ ; RESET#	= 12.5 V			35	μΑ
I <sub>LO</sub>	Output Leakage Current	$V_{OUT} = V_{SS}$ to $V_{CC}$ , $V_{CC} = V_{CC max}$			±1.0	μΑ	
			1 MHz		5	20	
	V <sub>CC</sub> Initial Read Current (2, 3)		5 MHz (4)		18	25	
I <sub>CC1</sub>		$CE\# = V_{IL}, OE\# = V_{IH}$	5 MHz (5)		25	35	mA
			10 MHz (4)		35	50	
			10 MHz (5)		40	60	
	V Junton Danie Band Commont (2, 2)	CE" V CE" V	10 MHz		5	20	m A
I <sub>CC2</sub>	V <sub>CC</sub> Intra-Page Read Current (2, 3)	$CE\# = V_{IL}, OE\# = V_{IH}$	40 MHz		10	40	mA
I <sub>CC3</sub>	V <sub>CC</sub> Active Write Current (3, 4)	$CE\# = V_{IL}, OE\# = V_{IH}$	•		50	60	mA
I <sub>CC4</sub>	V <sub>CC</sub> Standby Current (3)	CE#, RESET# = $V_{CC} \pm C$ WP# = $V_{IH}$	).3 V,		1	5	μΑ
I <sub>CC5</sub>	V <sub>CC</sub> Reset Current (3)	RESET# = $V_{SS} \pm 0.3 \text{ V}$	WP# = V <sub>IH</sub>		1	5	μΑ
I <sub>CC6</sub>	Automatic Sleep Mode (3, 7)	$V_{IH} = V_{CC} \pm 0.3 \text{ V}; \\ -0.1 < V_{IL} \le 0.3 \text{ V, WP\#}$	= V <sub>IH</sub>		1	5	μΑ
V <sub>IL</sub>	Input Low Voltage (1, 8)			-0.5		0.8	٧
V <sub>IH</sub>	Input High Voltage 1, 8)			0.7 V <sub>CC</sub>		V <sub>CC</sub> + 0.5	V
$V_{HH}$	Voltage for ACC Program Acceleration	$V_{CC} = 2.7 - 3.6 \text{ V}$		11.5	12.0	12.5	V
V <sub>ID</sub>	Voltage for Autoselect and Temporary Sector Unprotect	V <sub>CC</sub> = 2.7 -3.6 V		11.5	12.0	12.5	٧
V <sub>OL</sub>	Output Low Voltage (8)	I <sub>OL</sub> = 4.0 mA, V <sub>CC</sub> = V <sub>CC min</sub>				0.45	V
V <sub>OH1</sub>		$I_{OH} = -2.0 \text{ mA}, V_{CC} = V_{CC}$	CC min	0.85 V <sub>CC</sub>			V
V <sub>OH2</sub>	Output High Voltage	$I_{OH} = -100 \mu\text{A},  V_{CC} = V_{CC  min}$		V <sub>CC</sub> -0.4			V
V <sub>LKO</sub>	Low V <sub>CC</sub> Lock-Out Voltage (9)			2.3		2.5	V

- 1. On the WP#/ACC pin only, the maximum input load current when WP# =  $V_{IL}$  is  $\pm 5.0~\mu A$ .
- 2. The  $I_{CC}$  current listed is typically less than 3.5 mA/MHz, with OE# at  $V_{IH}$ .

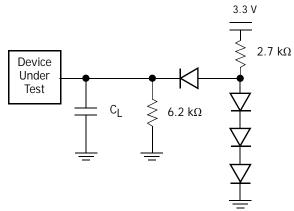
  3. Maximum  $I_{CC}$  specifications are tested with  $V_{CC} = V_{CC}$ max.

  4. S29GL032M, S29GL064M

- 5. S29GL128M, S29GL256M
- 6. I<sub>CC</sub> active while Embedded Erase or Embedded Program is in progress.
- Automatic sleep mode enables the low power mode when addresses remain stable for  $t_{ACC}$  + 30
- V<sub>CC</sub> voltage requirements.
- Not 100% tested.



# **Test Conditions**



Note: Diodes are IN3064 or equivalent

Figure II. Test Setup

**Table 37. Test Specifications** 

Test Condition	All Speeds	Unit
Output Load	1 TTL gate	
Output Load Capacitance, C <sub>L</sub> (including jig capacitance)	30	pF
Input Rise and Fall Times	5	ns
Input Pulse Levels	0.0 or V <sub>CC</sub>	V
Input timing measurement reference levels (See Note)	0.5 V <sub>CC</sub>	V
Output timing measurement reference levels	0.5 V <sub>CC</sub>	V

# **Key to Switching Waveforms**

WAVEFORM	INPUTS	OUTPUTS			
	Steady				
	Changing from H to L				
_////	Changing from L to H				
XXXXX	Don't Care, Any Change Permitted	Changing, State Unknown			
$\longrightarrow$	Does Not Apply	Center Line is High Impedance State (High Z)			



Figure 12. Input Waveforms and Measurement Levels



# Read-Only Operations—S29GL256M Only

Param	eter	Description		Toot Satur		Speed Options		Unit
JEDEC	Std.	Description		Test Setup		10	11	Oille
t <sub>AVAV</sub>	t <sub>RC</sub>	Read Cycle Time (Note 1)			Min	100	100	ns
t <sub>AVQV</sub>	t <sub>ACC</sub>	Address to Output Delay		CE#, OE# = V <sub>IL</sub>	Max	100	100	ns
t <sub>ELQV</sub>	t <sub>CE</sub>	Chip Enable to Output Delay		OE# = V <sub>IL</sub>	Max	100	100	ns
	$t_{\text{PACC}}$	Page Access Time			Max	30	30	ns
t <sub>GLQV</sub>	t <sub>OE</sub>	Output Enable to Output Delay			Max	30	30	ns
t <sub>EHQZ</sub>	t <sub>DF</sub>	Chip Enable to Output High Z (Note 1)			Max	16		ns
t <sub>GHQZ</sub>	t <sub>DF</sub>	Output Enable to Output High Z (Note 1	)		Max	16		ns
t <sub>AXQX</sub>	t <sub>OH</sub>	Output Hold Time From Addresses, CE# or OE#, Whichever Occurs First			Min	0		ns
			Read		Min	(	)	ns
t <sub>OEH</sub>			Toggle and Data# Polling		Min	1	0	ns

### Notes:

- Not 100% tested.
   See Figure 11 and Table 37 for test specifications.

# Read-Only Operations—S29GLI28M only

Param	neter	Description		Toot Satur		Speed	Options	Unit
JEDEC	Std.	Description		Test Setup		90	10	
t <sub>AVAV</sub>	t <sub>RC</sub>	Read Cycle Time (Note 1)			Min	90	100	ns
t <sub>AVQV</sub>	t <sub>ACC</sub>	Address to Output Delay		CE#, OE# = V <sub>IL</sub>	Max	90	100	ns
t <sub>ELQV</sub>	t <sub>CE</sub>	Chip Enable to Output Delay		OE# = V <sub>IL</sub>	Max	90	100	ns
	t <sub>PACC</sub>	Page Access Time			Max	25	30	ns
t <sub>GLQV</sub>	t <sub>OE</sub>	Output Enable to Output Delay			Max	25	30	ns
t <sub>EHQZ</sub>	t <sub>DF</sub>	Chip Enable to Output High Z (Note 1)			Max	16		ns
t <sub>GHQZ</sub>	t <sub>DF</sub>	Output Enable to Output High Z (Note 1	)		Max	16		ns
t <sub>AXQX</sub>	t <sub>OH</sub>	Output Hold Time From Addresses, CE# or OE#, Whichever Occurs First			Min	0		ns
			Read		Min		0	ns
		Toggle and Data# Polling		Min		10	ns	

### Notes:

- Not 100% tested.
   See Figure 11 and Table 37 for test specifications.



# Read-Only Operations—S29GL064M Only

Param	neter	Description		Test Setup		Speed Options			Unit
JEDEC	Std.	Description		rest setup		90	10	11	Unit
t <sub>AVAV</sub>	t <sub>RC</sub>	Read Cycle Time (Note 1)			Min	90	100	110	ns
t <sub>AVQV</sub>	t <sub>ACC</sub>	Address to Output Delay		CE#, OE# = V <sub>IL</sub>	Max	90	100	110	ns
t <sub>ELQV</sub>	t <sub>CE</sub>	Chip Enable to Output Delay		OE# = V <sub>IL</sub>	Max	90	100	110	ns
	$t_{\text{PACC}}$	Page Access Time			Max	25	30	30	ns
t <sub>GLQV</sub>	t <sub>OE</sub>	Output Enable to Output Delay			Max	25	30	30	ns
t <sub>EHQZ</sub>	t <sub>DF</sub>	Chip Enable to Output High Z (See Note	e)		Max	16		ns	
t <sub>GHQZ</sub>	t <sub>DF</sub>	Output Enable to Output High Z (See N	ote)		Max	x 16			ns
t <sub>AXQX</sub>	t <sub>OH</sub>	Output Hold Time From Addresses, CE# Whichever Occurs First	or OE#,		Min	۱ 0			ns
			Read		Min	0			ns
	t <sub>OEH</sub> Output Enable Hold Time (See Note)	Toggle and Data# Polling		Min		10		ns	

Note: Not 100% tested.



# Read-Only Operations—\$29GL032M only

Param	eter	Description		Test Setup		Spe	eed Opt	tions	Unit
JEDEC	Std.	Description	Description rest setup			90	10	11	Unit
t <sub>AVAV</sub>	t <sub>RC</sub>	Read Cycle Time (Note 1)			Min	90	100	110	ns
t <sub>AVQV</sub>	t <sub>ACC</sub>	Address to Output Delay		CE#, OE# = V <sub>IL</sub>	Max	90	100	110	ns
t <sub>ELQV</sub>	t <sub>CE</sub>	Chip Enable to Output Delay		OE# = V <sub>IL</sub>	Max	90	100	110	ns
	$t_{\text{PACC}}$	Page Access Time		Max	25	30	30	ns	
t <sub>GLQV</sub>	t <sub>OE</sub>	Output Enable to Output Delay			Max	25	30	30	ns
t <sub>EHQZ</sub>	t <sub>DF</sub>	Chip Enable to Output High Z (Note 1)			Max	16		ns	
t <sub>GHQZ</sub>	t <sub>DF</sub>	Output Enable to Output High Z (Note 1	)		Max	x 16			ns
t <sub>AXQX</sub>	t <sub>OH</sub>	Output Hold Time From Addresses, CE# or OE#, Whichever Occurs First			Min	n 0			ns
			Read		Min		0		ns
	t <sub>OEH</sub> Output Enable Hold Time (Note 1)	Toggle and Data# Polling		Min		10		ns	

- Notes:
  1. Not 100% tested.
- 2. See Figure 11 and Table 37 for test specifications.

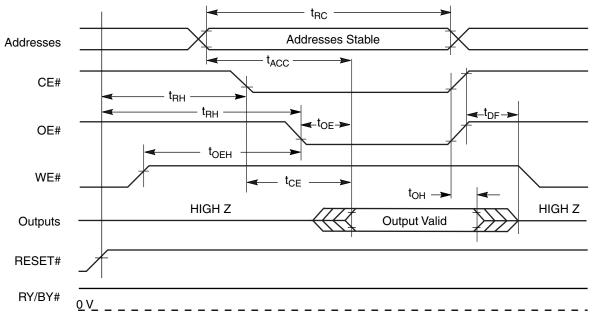
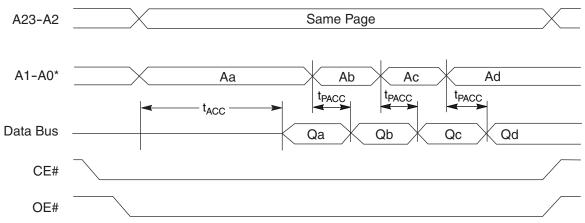


Figure I3. Read Operation Timings





**Note:** Figure shows device in word mode. Addresses are A1–A-1 for byte mode.

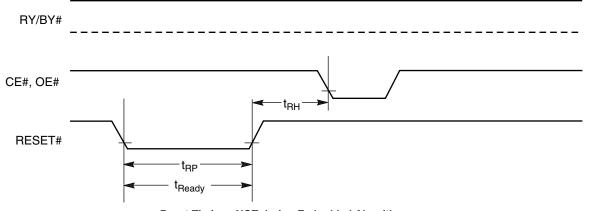
Figure I4. Page Read Timings

# Hardware Reset (RESET#)

Param	neter	Description	All Speed	Unit		
JEDEC	Std.	Description		Options	5.110	
	t <sub>Ready</sub>	RESET# Pin Low (During Embedded Algorithms) to Read Mode (See Note)	Max	20	μs	
	t <sub>Ready</sub>	RESET# Pin Low (NOT During Embedded Algorithms) to Read Mode (See Note)	Max	500	ns	
	t <sub>RP</sub>	RESET# Pulse Width	Min	500	ns	
	t <sub>RH</sub>	Reset High Time Before Read (See Note)	Min	50	ns	
	t <sub>RPD</sub>	RESET# Input Low to Standby Mode (See Note)	Min	20	μs	
	t <sub>RB</sub>	RY/BY# Output High to CE#, OE# pin Low	Min	0	ns	

Note: Not 100% tested.





Reset Timings NOT during Embedded Algorithms

**Reset Timings during Embedded Algorithms** 

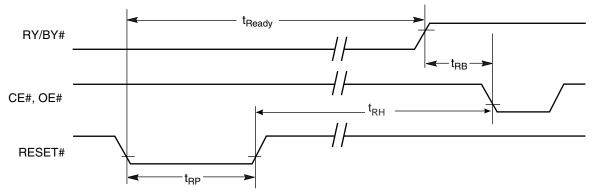


Figure I5. Reset Timings



# Erase and Program Operations—S29GL256M Only

Parar	neter	Description		Speed (	Options	Unit
JEDEC	Std.	Description		10	11	Unit
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	100	110	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min	0		ns
	t <sub>ASO</sub>	Address Setup Time to OE# low during toggle bit polling	Min	1	5	ns
t <sub>WLAX</sub>	t <sub>AH</sub>	Address Hold Time	Min	4	5	ns
	t <sub>AHT</sub>	Address Hold Time From CE# or OE# high during toggle bit polling	Min	(	)	ns
t <sub>DVWH</sub>	t <sub>DS</sub>	Data Setup Time	Min	4	5	ns
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min	(	)	ns
	t <sub>CEPH</sub>	CE# High during toggle bit polling	Min	2	0	ns
	t <sub>OEPH</sub>	OE# High during toggle bit polling	Min	20		ns
t <sub>GHWL</sub>	t <sub>GHWL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0		ns
t <sub>ELWL</sub>	t <sub>CS</sub>	CE# Setup Time	Min	0		ns
t <sub>WHEH</sub>	t <sub>CH</sub>	CE# Hold Time	Min	(	)	ns
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Width	Min	3	5	ns
t <sub>WHDL</sub>	t <sub>WPH</sub>	Write Pulse Width High	Min	3	0	ns
		Write Buffer Program Operation (Notes 2, 3)	Тур	24	10	
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур	6	0	μs
		Accelerated Single Word Program Operation (Note 2)	Тур	5	4	
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2)	Тур	0.	5	sec
	t <sub>VHH</sub>	V <sub>HH</sub> Rise and Fall Time (Note 1)	Min	25	50	ns
	t <sub>VCS</sub>	V <sub>CC</sub> Setup Time (Note 1)	Min	5	0	μs
	t <sub>BUSY</sub>	WE# High to RY/BY# Low	Max	100	110	ns
	t <sub>POLL</sub>	Program Valid before Status Polling	Max	4	ļ	μs

- Notes:
  1. Not 100% tested.
- See Erase and Programming Performance for more information.
   For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within  $t_{POLL}$ , the device requires  $t_{POLL}$  before reading status data, once programming resumes (that is, the program resume command is written). If the suspend command was issued after t<sub>POLL</sub>, status data is available immediately after programming resumes. See Figure 16.



# Erase and Program Operations—S29GLI28M Only

Parameter		Description			Speed Options		
JEDEC	Std.	Description		90	10	t	
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	90	100	ns	
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min		0	ns	
	t <sub>ASO</sub>	Address Setup Time to OE# low during toggle bit polling	Min		15	ns	
t <sub>WLAX</sub>	t <sub>AH</sub>	Address Hold Time	Min		45	ns	
	t <sub>AHT</sub>	Address Hold Time From CE# or OE# high during toggle bit polling	Min		0	ns	
t <sub>DVWH</sub>	t <sub>DS</sub>	Data Setup Time	Min		45	ns	
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min		0	ns	
	t <sub>CEPH</sub>	CE# High during toggle bit polling	Min		20	ns	
	t <sub>OEPH</sub>	OE# High during toggle bit polling	Min		20	ns	
t <sub>GHWL</sub>	t <sub>GHWL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	n 0		ns	
t <sub>ELWL</sub>	t <sub>CS</sub>	CE# Setup Time	Min	n 0		ns	
t <sub>WHEH</sub>	t <sub>CH</sub>	CE# Hold Time	Min		0	ns	
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Width	Min		35	ns	
t <sub>WHDL</sub>	t <sub>WPH</sub>	Write Pulse Width High	Min		30	ns	
		Write Buffer Program Operation (Notes 2, 3)	Тур	2	240		
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур		60	μs	
		Accelerated Single Word Program Operation (Note 2)	Тур		54		
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	H2 Sector Erase Operation (Note 2) Typ		(	0.5	sec	
	t <sub>VHH</sub>	V <sub>HH</sub> Rise and Fall Time (Note 1) Min		2	250	ns	
	t <sub>VCS</sub>	S V <sub>CC</sub> Setup Time (Note 1) Min		1in 50		μs	
	t <sub>BUSY</sub>	WE# High to RY/BY# Low Max 90		90	100	ns	
	t <sub>POLL</sub>	Program Valid before Status Polling Max			4	μs	

### Notes:

- 1. Not 100% tested.
- 2. See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within  $t_{POLL}$ , the device requires  $t_{POLL}$  before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after  $t_{POLL}$ , status data is available immediately after programming resumes. See Figure 16.



# Erase and Program Operations—S29GL064M Only

Parar	neter	Description			Speed Options		
JEDEC	Std.	Description		90	10	11	Unit
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	90	100	110	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min		0		ns
	t <sub>ASO</sub>	Address Setup Time to OE# low during toggle bit polling	Min		15		ns
t <sub>WLAX</sub>	t <sub>AH</sub>	Address Hold Time	Min		45		ns
	t <sub>AHT</sub>	Address Hold Time From CE# or OE# high during toggle bit polling	Min		0		ns
t <sub>DVWH</sub>	t <sub>DS</sub>	Data Setup Time	Min		35		ns
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min		0		ns
	t <sub>CEPH</sub>	CE# High during toggle bit polling	Min		20		ns
	t <sub>OEPH</sub>	OE# High during toggle bit polling	Min	n 20			ns
t <sub>GHWL</sub>	t <sub>GHWL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0			ns
t <sub>ELWL</sub>	t <sub>CS</sub>	CE# Setup Time	Min	0			ns
t <sub>WHEH</sub>	t <sub>CH</sub>	CE# Hold Time	Min		0		ns
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Width	Min		35		ns
t <sub>WHDL</sub>	t <sub>WPH</sub>	Write Pulse Width High	Min		30		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур		60		μs
		Accelerated Single Word Program Operation (Note 2)	Тур		54		
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2)	Тур	p 0.5		sec	
	t <sub>VHH</sub>	V <sub>HH</sub> Rise and Fall Time (Note 1)	Min	in 250		ns	
	t <sub>VCS</sub>	V <sub>CC</sub> Setup Time (Note 1)	Min	Min 50			μs
	t <sub>BUSY</sub>	WE# High to RY/BY# Low	Max	Max 90 100 110		110	ns
	t <sub>POLL</sub>	Program Valid before Status Polling	Max		4		μs

- Notes:
  1. Not 100% tested.
- See Erase and Programming Performance for more information
   For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within  $t_{POLL}$ , the device requires  $t_{POLL}$  before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after t<sub>POLL</sub>, status data is available immediately after programming resumes. See Figure 16.



# Erase and Program Operations—S29GL032M Only

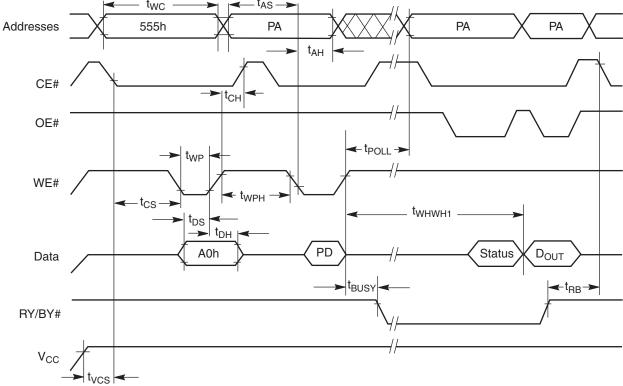
Parameter		Description		Sp	Unit		
JEDEC	Std.	Description		90	10	11	Ullit
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	90	100	110	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min		0		ns
	t <sub>ASO</sub>	Address Setup Time to OE# low during toggle bit polling	Min		15		ns
t <sub>WLAX</sub>	t <sub>AH</sub>	Address Hold Time	Min		45		ns
	t <sub>AHT</sub>	Address Hold Time From CE# or OE# high during toggle bit polling	Min		0		ns
t <sub>DVWH</sub>	t <sub>DS</sub>	Data Setup Time	Min		35		ns
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min		0		ns
	t <sub>CEPH</sub>	CE# High during toggle bit polling	Min		20		ns
	t <sub>OEPH</sub>	OE# High during toggle bit polling	Min	lin 20			ns
t <sub>GHWL</sub>	t <sub>GHWL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	n 0			ns
t <sub>ELWL</sub>	t <sub>CS</sub>	CE# Setup Time	Min	n 0			ns
t <sub>WHEH</sub>	t <sub>CH</sub>	CE# Hold Time	Min		0		ns
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Width	Min		35		ns
t <sub>WHDL</sub>	t <sub>WPH</sub>	Write Pulse Width High	Min		30		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур		60		μs
		Accelerated Single Word Program Operation (Note 2)	Тур		54		
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2)	Тур	yp 0.5			sec
	t <sub>VHH</sub>	V <sub>HH</sub> Rise and Fall Time (Note 1)	Min	in 250			ns
	t <sub>VCS</sub>	V <sub>CC</sub> Setup Time (Note 1)	Min	/lin 50			μs
	t <sub>BUSY</sub>	WE# High to RY/BY# Low	Max	Max 90 100 110		110	ns
	t <sub>POLL</sub>	Program Valid before Status Polling	Max	lax 4		•	μs

### Notes:

- Not 100% tested.
   See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- 4. Effective write buffer specification is based upon a 16-word/32-byte write buffer operation.
- 5. If a program suspend command is issued within t<sub>POLL</sub>, the device requires t<sub>POLL</sub> before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after t<sub>POLL</sub>, status data is available immediately after programming resumes. See Figure 16.







### Notes

- 1.  $PA = program \ address, \ PD = program \ data, \ D_{OUT}$  is the true data at the program address.
- 2. Illustration shows device in word mode.

Figure 16. Program Operation Timings

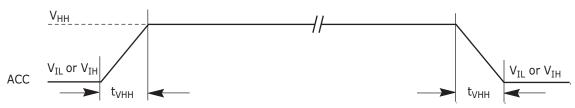
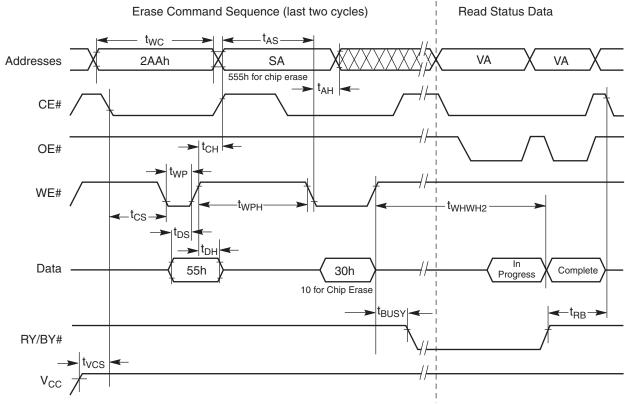


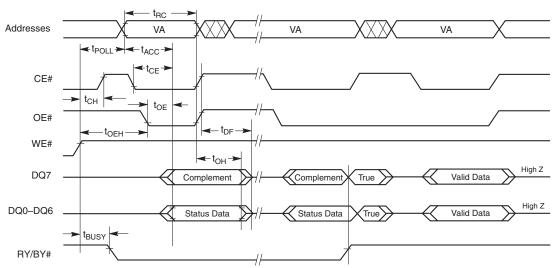
Figure I7. Accelerated Program Timing Diagram





- Notes:
- 1. SA = sector address (for Sector Erase), VA = Valid Address for reading status data (see Write Operation Status).
- 2. Illustration shows device in word mode.

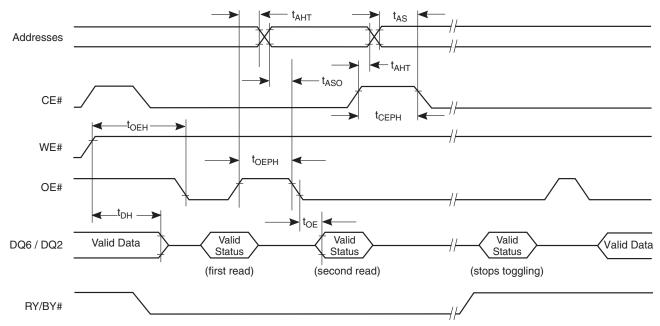
Figure 18. Chip/Sector Erase Operation Timings



**Note:** VA = Valid address. Illustration shows first status cycle after command sequence, last status read cycle, and array data read cycle.

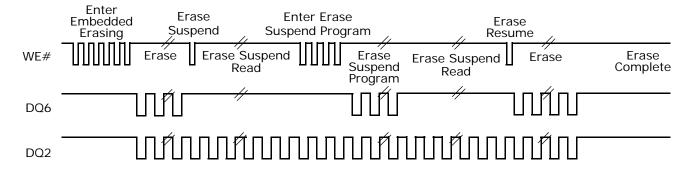
Figure 19. Data# Polling Timings (During Embedded Algorithms)





**Note:** VA = Valid address; not required for DQ6. Illustration shows first two status cycle after command sequence, last status read cycle, and array data read cycle.

Figure 20. Toggle Bit Timings (During Embedded Algorithms)



**Note:** DQ2 toggles only when read at an address within an erase-suspended sector. The system may use OE# or CE# to toggle DQ2 and DQ6.

Figure 2I. DQ2 vs. DQ6

# **Temporary Sector Unprotect**

Parameter		Description	All Speed Options		
JEDEC	Std	Description	All Speed Options	Unit	
	$t_{VIDR}$	V <sub>ID</sub> Rise and Fall Time (See Note)	Min	500	ns
	t <sub>RSP</sub>	RESET# Setup Time for Temporary Sector Unprotect	Min	4	μs

Note: Not 100% tested.



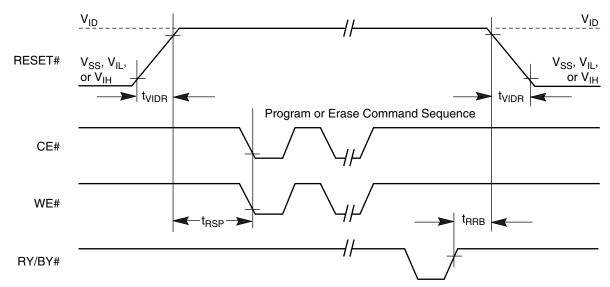
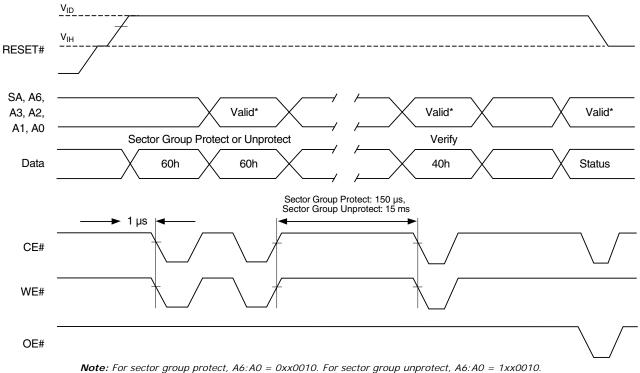


Figure 22. Temporary Sector Group Unprotect Timing Diagram



Tur sector group protect, Ao. Ao. – U.X.O.O.O. Tur sector group unprotect, Ao. Ao. – T.X.O.O.O.

Figure 23. Sector Group Protect and Unprotect Timing Diagram



# Alternate CE# Controlled Erase and Program Operations—S29GL256M

Para	meter	Description		Speed (	Options	11		
JEDEC	Std.	Description		10	11	Unit		
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	100	110	ns		
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min	(	)	ns		
t <sub>ELAX</sub>	t <sub>AH</sub>	Address Hold Time	Min	4	5	ns		
t <sub>DVEH</sub>	t <sub>DS</sub>	Data Setup Time	Min	4	5	ns		
t <sub>EHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min	(	)	ns		
t <sub>GHEL</sub>	t <sub>GHEL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	in 0		0		ns
t <sub>WLEL</sub>	t <sub>WS</sub>	WE# Setup Time	Min	nin 0		0		ns
t <sub>EHWH</sub>	t <sub>WH</sub>	WE# Hold Time	Min	0		ns		
t <sub>ELEH</sub>	t <sub>CP</sub>	CE# Pulse Width	Min	35		ns		
t <sub>EHEL</sub>	t <sub>CPH</sub>	CE# Pulse Width High	Min	2	5	ns		
		Write Buffer Program Operation (Notes 2, 3)	Тур	24	10			
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур	6	0	μs		
		Accelerated Single Word Program Operation (Note 2)	Тур	/p 54				
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2)		0	.5	sec		
	t <sub>RH</sub>	RESET# High Time Before Write		50		ns		
	t <sub>POLL</sub>	Program Valid before Status Polling Ma:		4	1	μs		

### Notes:

- Not 100% tested.
   See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- If a program suspend command is issued within t<sub>POLL</sub>, the device requires t<sub>POLL</sub> before reading status data, once programming resume (that is, the program resume command has been written). If the suspend command was issued after t<sub>POLL</sub>, status data is available immediately after programming resumes. See Figure 24.



# Alternate CE# Controlled Erase and Program Operations—S29GLI28M

Para	meter	Description		Speed (	Options	Unit
JEDEC	Std.	Description		10	11	Unit
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	100	110	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min	(	)	ns
t <sub>ELAX</sub>	t <sub>AH</sub>	Address Hold Time	Min	4	5	ns
t <sub>DVEH</sub>	t <sub>DS</sub>	Data Setup Time	Min	4	5	ns
t <sub>EHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min	(	)	ns
t <sub>GHEL</sub>	t <sub>GHEL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	(	)	ns
t <sub>WLEL</sub>	t <sub>WS</sub>	WE# Setup Time	Min	0		ns
t <sub>EHWH</sub>	t <sub>WH</sub>	WE# Hold Time	Min	0		ns
t <sub>ELEH</sub>	t <sub>CP</sub>	CE# Pulse Width	Min	3	5	ns
t <sub>EHEL</sub>	t <sub>CPH</sub>	CE# Pulse Width High	Min	2	5	ns
		Write Buffer Program Operation (Notes 2, 3)	Тур	24	10	
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур	6	0	μs
		Accelerated Single Word Program Operation (Note 2)	Тур	5	4	
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2) Typ		0.5		sec
	t <sub>RH</sub>	RESET# High Time Before Write		50		ns
	t <sub>POLL</sub>	Program Valid before Status Polling (Note 4)  Ma		4	1	μs

### Notes

- 1. Not 100% tested.
- 2. See See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within t<sub>POLL</sub>, the device requires t<sub>POLL</sub> before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after t<sub>POLL</sub>, status data is available immediately after programming resumes. See Figure 24.



# Alternate CE# Controlled Erase and Program Operations—\$29GL064M

Para	meter	Description		Speed Options			Unit
JEDEC	Std.	- Description		90	10	11	Unit
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	90	100	110	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min		0		ns
t <sub>ELAX</sub>	t <sub>AH</sub>	Address Hold Time	Min		45		ns
t <sub>DVEH</sub>	t <sub>DS</sub>	Data Setup Time	Min		35		ns
t <sub>EHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min		0		ns
t <sub>GHEL</sub>	t <sub>GHEL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0			ns
t <sub>WLEL</sub>	t <sub>WS</sub>	WE# Setup Time	Min	0			ns
t <sub>EHWH</sub>	t <sub>WH</sub>	WE# Hold Time	Min	in 0			ns
t <sub>ELEH</sub>	t <sub>CP</sub>	CE# Pulse Width	Min		35		ns
t <sub>EHEL</sub>	t <sub>CPH</sub>	CE# Pulse Width High	Min		25		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур		60		μs
		Accelerated Single Word Program Operation (Note 2)	Тур		54		
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2)		0.5			sec
	t <sub>RH</sub>	RESET# High Time Before Write	Min	50			ns
	t <sub>POLL</sub>	Program Valid before Status Polling (Note 5)	Max		4		μs

- Notes:
  1. Not 100% tested.
- 2. See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within  $t_{POLL}$ , the device requires  $t_{POLL}$  before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after  $t_{POLL}$ , status data is available immediately after programming resumes. See Figure 24.



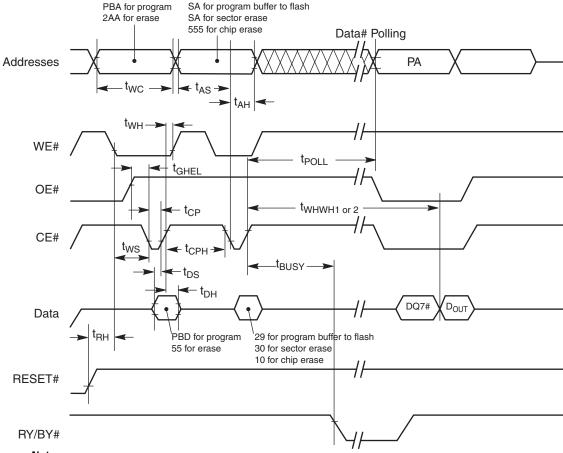
# Alternate CE# Controlled Erase and Program Operations—S29GL032M

Parai	neter	Description		S	peed Opti	ons	Unit	
JEDEC	Std.	Description		90	10	11	Unit	
t <sub>AVAV</sub>	t <sub>WC</sub>	Write Cycle Time (Note 1)	Min	90	100	110	ns	
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup Time	Min		0		ns	
t <sub>ELAX</sub>	t <sub>AH</sub>	Address Hold Time	Min		45		ns	
t <sub>DVEH</sub>	t <sub>DS</sub>	Data Setup Time	Min		35		ns	
t <sub>EHDX</sub>	t <sub>DH</sub>	Data Hold Time	Min		0		ns	
t <sub>GHEL</sub>	t <sub>GHEL</sub>	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0		0		ns
t <sub>WLEL</sub>	t <sub>WS</sub>	WE# Setup Time	Min	0			ns	
t <sub>EHWH</sub>	t <sub>WH</sub>	WE# Hold Time	Min	0		0		
t <sub>ELEH</sub>	t <sub>CP</sub>	CE# Pulse Width	Min	35		ns		
t <sub>EHEL</sub>	t <sub>CPH</sub>	CE# Pulse Width High	Min		25		ns	
		Write Buffer Program Operation (Notes 2, 3)	Тур		240			
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Single Word Program Operation (Note 2)	Тур		60		μs	
		Accelerated Single Word Program Operation (Note 2)	Тур	54				
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Operation (Note 2) Typ		0.5			sec	
	t <sub>RH</sub>	RESET# High Time Before Write Min		50			ns	
	t <sub>POLL</sub>	Program Valid before Status Polling (Note 4)	Max		4		μs	

### Notes:

- Not 100% tested.
   See Erase and Programming Performance for more information
- 3. For 1–16 words/1–32 bytes programmed.
- If a program suspend command is issued within t<sub>POLL</sub>, the device requires t<sub>POLL</sub> before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after  $t_{POLL}$ , status data is available immediately after programming resumes. See Figure 24.





### Notes:

- Figure indicates last two bus cycles of a program or erase operation.

  PA = program address, SA = sector address, PD = program data.

  DQ7# is the complement of the data written to the device. D<sub>QUT</sub> is the data written to the device.
- Illustration shows device in word mode.

Figure 24. Alternate CE# Controlled Write (Erase/Program) Operation Timings



# **Erase and Programming Performance**

Parameter (Notes)		Typ (Note 1)	Max (Note 2)	Unit	Comments
Sector Erase Time	)	0.5	3.5	sec	
	S29GL032M	32	64		Excludes 00h programming
Chin Fraca Time	S29GL064M	64	128		prior to
Chip Erase Time	S29GL128M	128	256	sec	erasure (Note 6)
	S29GL256M	256	512		
Total Write Buffer Program Time (3,	5)	240		μs	
Total Accelerated Effective Write Buf (4, 5)	fer Program Time	200		μs	Excludes
	S29GL032M	31.5			system level overhead
Chin Program Time	S29GL064M	63			(Note 7)
Chip Program Time	S29GL128M	126		sec	
	S29GL256M	252			

### Notes:

- 1. Typical program and erase times assume the following conditions:  $25^{\circ}$ C,  $V_{CC} = 3.0$ V, 10,000 cycles; checkerboard data pattern.
- 2. Under worst case conditions of 90°C; Worst case  $V_{CC}$ , 100,000 cycles.
- 3. Effective programming time (typ) is 15 µs (per word), 7.5 µs (per byte).
- 4. Effective accelerated programming time (typ) is 12.5 μs (per word), 6.3 μs (per byte).
- 5. Effective write buffer specification is calculated on a per-word/per-byte basis for a 16-word/32-byte write buffer operation.
- 6. In the pre-programming step of the Embedded Erase algorithm, all bits are programmed to 00h before erasure.
- 7. System-level overhead is the time required to execute the command sequence(s) for the program command. See Table 34 and Table 35 for further information on command definitions.

# **TSOP Pin and BGA Package Capacitance**

For package types TA, TF, BA, BF, FA, FF (refer to Ordering Information Pages):

Parameter Symbol	Parameter Description	Test Setup		Тур	Max	Unit
C···	Input Capacitance	V <sub>IN</sub> = 0	TSOP	6	7.5	pF
C <sub>IN</sub>	input capacitance	Capacitance $V_{IN} = 0$		4.2	5.0	pF
C	0.1.10.11		TSOP	8.5	12	pF
C <sub>OUT</sub>	Output Capacitance	$V_{OUT} = 0$	BGA	5.4	6.5	pF
C····	C Control Din Conscitance V 0		TSOP	7.5	9	pF
C <sub>IN2</sub>	Control Pin Capacitance	V <sub>IN</sub> = 0	BGA	3.9	4.7	pF

For package types TB, TC, BB, BC, (refer to Ordering Information Pages):

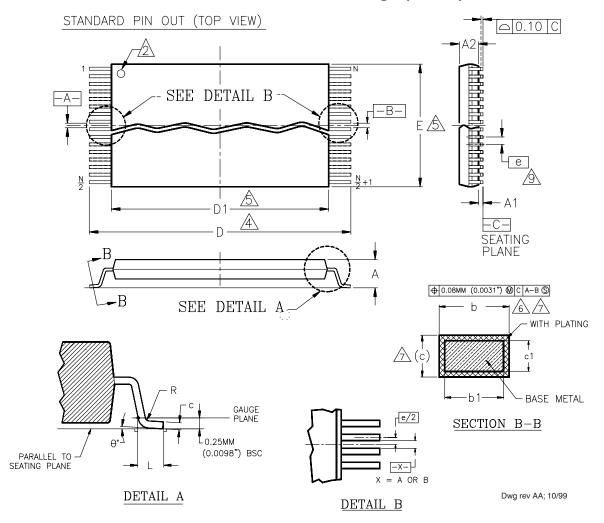
Parameter Symbol	Parameter Description	Test Setup		Тур	Max	Unit
C	Input Capacitance	V 0	TSOP	8	10	pF
C <sub>IN</sub>	input Capacitance	$V_{IN} = 0$	BGA	8	10	pF
	Output Canacitance	V <sub>OUT</sub> = 0	TSOP	8.5	12	pF
C <sub>OUT</sub>	Output Capacitance	VOUT - O	BGA	8.5	12	pF
C	Control Din Canasitanse	V 0	TSOP	8	10	pF
C <sub>IN2</sub>	Control Pin Capacitance $V_{IN} = 0$		BGA	8	10	pF
C	DESET# and WD#/ACC Din Conscitance	V 0	TSOP	20	25	pF
C <sub>IN3</sub>	RESET# and WP#/ACC Pin Capacitance	$V_{IN} = 0$	BGA	15	20	pF

### Notes.

- 1. Sampled, not 100% tested.
- 2. Test conditions  $T_A = 25$  °C, f = 1.0 MHz.



# TS040—40-Pin Standard Thin Small Outline Package (TSOP)



Package	TS 40				
Jedec	MO-1	42 (B	) CD		
Symbol	MIN	NDM	MAX		
А	_	_	1.20		
A1	0.05	_	0.15		
A2	0.95	1.00	1.05		
b1	0.17	0.20	0.23		
b	0.17	0.22	0.27		
⊂1	0.10	_	0.16		
С	0.10	_	0.21		
D	19.80	20.00	20.20		
D1	18.30	18.40	18.50		
E	9.90	10.00	10.10		
е	0.5	50 BAS	IC		
L	0.50	0.60	0.70		
θ	0°	3*	5°		
R	0.08	_	0.20		
N		40			

### NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm).



`PIN 1 IDENTIFIER FOR STANDARD PIN OUT (DIE UP).

A PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE DOWN): INK OR LASER MARK.

TO BE DETERMINED AT THE SEATING PLANE [-C-]. THE SEATING PLANE IS

DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS

ARE ALLOWED TO REST FREELY ON A FLAT HORIZONTAL SURFACE.

DIMENSIONS DI AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15mm (.0059') PER SIDE.

DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08mm (0.0031") TOTAL IN EXCESS OF 6 DIMENSION AT MAX. MATERIAL CONDITION, MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07mm (0.0028").

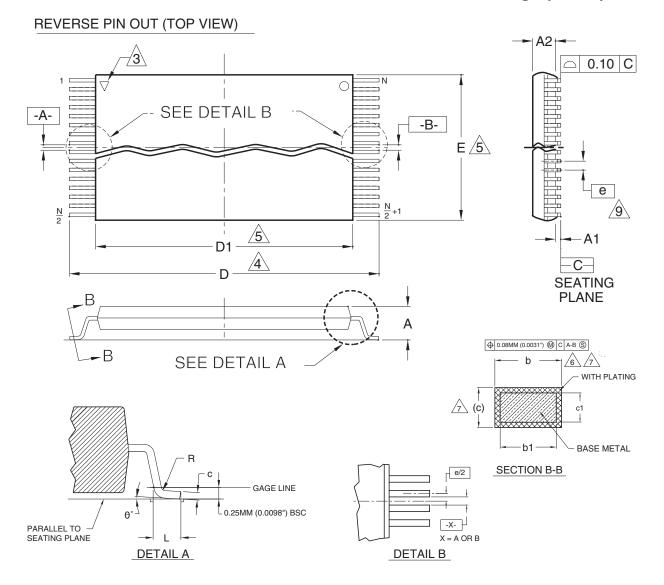
THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm (.0039") AND 0.25mm (0.0098") FROM THE LEAD TIP.

 LEAD COPLANARITY SHALL BE WITHIN 0.10mm (0.004") AS MEASURED FROM THE SEATING PLANE.

DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.



# TSR040—40-Pin Standard and Reverse Thin Small Outline Package (TSOP)



Package	TSR 040					
Jedec	MC	-142 (B)	EC			
Symbol	MIN	NOM	MAX			
Α	_	_	1.20			
A1	0.05	_	0.15			
A2	0.95	1.00	1.05			
b1	0.17	0.20	0.23			
b	0.17	0.22	0.27			
c1	0.10	_	0.16			
С	0.10	_	0.21			
D	19.80	20.00	20.20			
D1	18.30	18.40	18.50			
Е	9.90	10.00	10.10			
е	0.50 BASIC					
L	0.50	0.60	0.70			
θ	0°	3°	5°			
R	0.08	_	0.20			
N	40					

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (MM). (DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982)

NOT APPLICABLE.

PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE DOWN), INK OR LASER MARK.

TO BE DETERMINED AT THE SEATING PLANE CO. THE SEATING PLANE IS DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT

DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15MM (.0059") PER SIDE.

DIMENSION b DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 (0.0031") TOTAL IN EXCESS OF b DIMENSION AT MAX. MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 (0.0028").

THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10MM (.0039") AND 0.25MM (0.0098") FROM THE LEAD TIP.

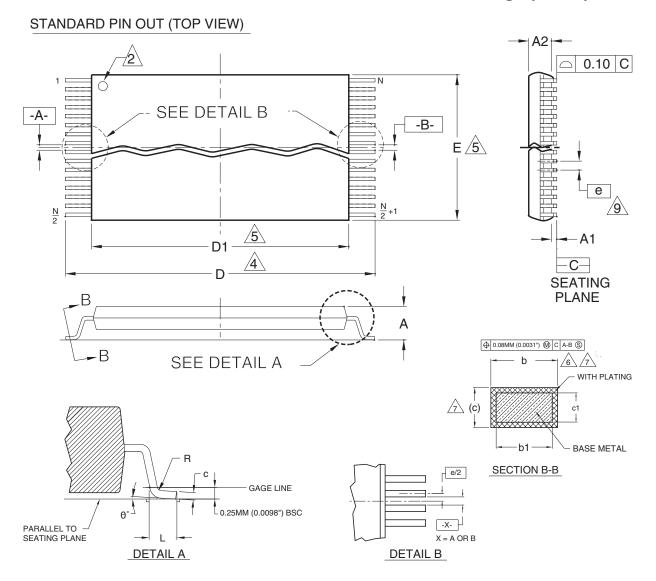
LEAD COPLANARITY SHALL BE WITHIN 0.10MM (0.004") AS MEASURED FROM THE SEATING PLANE.

DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.

3324 \ 16-038.10a



# TS048—48-Pin Standard and Reverse Thin Small Outline Package (TSOP)



Package	TS 048				
Jedec	MO-142 (B) EC				
Symbol	MIN	NOM	MAX		
Α	_	_	1.20		
A1	0.05	_	0.15		
A2	0.95	1.00	1.05		
b1	0.17	0.20	0.23		
b	0.17	0.22	0.27		
c1	0.10	_	0.16		
С	0.10	_	0.21		
D	19.80	20.00	20.20		
D1	18.30	18.40	18.50		
E	11.90	12.00	12.10		
е	0.50 BASIC				
L	0.50	0.60	0.70		
0	0°	3°	5°		
R	0.08	_	0.20		
N	48				

### NOTES:

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (MM). (DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982)

PIN 1 IDENTIFIER FOR STANDARD PIN OUT (DIE UP).

NOT APPLICABLE.

TO BE DETERMINED AT THE SEATING PLANE CT. THE SEATING PLANE IS DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT

DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15MM (.0059") PER SIDE.

DIMENSION b DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 (0.0031") TOTAL IN EXCESS OF b DIMENSION AT MAX. MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 (0.0028").

THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10MM (.0039") AND 0.25MM (0.0098") FROM THE LEAD TIP.

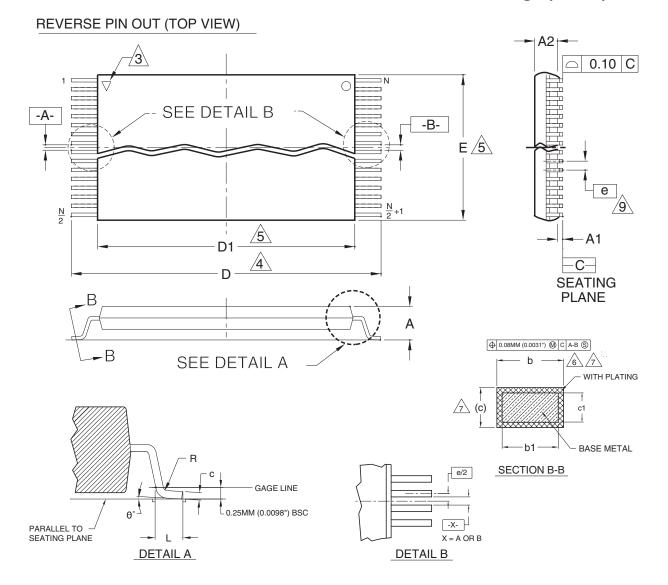
LEAD COPLANARITY SHALL BE WITHIN 0.10MM (0.004") AS MEASURED FROM THE SEATING PLANE.

DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.

3325 \ 16-038.10a



# TSR048—48-Pin Standard and Reverse Thin Small Outline Package (TSOP)



Package	TSR 048				
Jedec	MO-142 (B) EC				
Symbol	MIN	NOM	MAX		
Α	_	_	1.20		
A1	0.05	_	0.15		
A2	0.95	1.00	1.05		
b1	0.17	0.20	0.23		
b	0.17	0.22	0.27		
c1	0.10	_	0.16		
С	0.10	_	0.21		
D	19.80	20.00	20.20		
D1	18.30	18.40	18.50		
Е	11.90	12.00	12.10		
е	0.50 BASIC				
L	0.50 0.60		0.70		
θ	0°	3°	5°		
R	0.08	_	0.20		
N	48				

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (MM). (DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982)

NOT APPLICABLE.

PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE DOWN), INK OR LASER MARK.

TO BE DETERMINED AT THE SEATING PLANE CT. THE SEATING PLANE IS DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT

DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15MM (.0059") PER SIDE.

DIMENSION b DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 (0.0031") TOTAL IN EXCESS OF b DIMENSION AT MAX. MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 (0.0028").

THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10MM (.0039") AND 0.25MM (0.0098") FROM THE LEAD TIP.

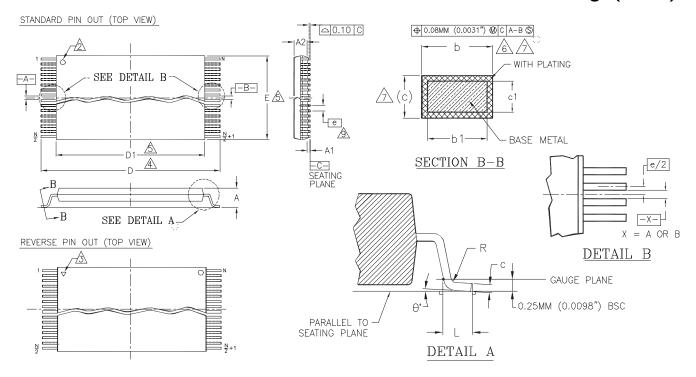
LEAD COPLANARITY SHALL BE WITHIN 0.10MM (0.004") AS MEASURED FROM THE SEATING PLANE.

DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.

3326 \ 16-038.10a



# TS056/TSR056—56-Pin Standard and Reverse Thin Small Outline Package (TSOP)



PACKAGE	TS/TSR 56			
JEDEC	MO-142 (B) EC			
SYMBOL	MIN.	NOM.	MAX.	
Α			1.20	
A1	0.05		0.15	
A2	0.95	1.00	1.05	
b1	0.17	0.20	0.23	
b	0.17	0.17 0.22		
c1	0.10		0.16	
С	0.10		0.21	
D	19.90	20.00	20.20	
D1	18.30	18.40	18.50	
E	13.90	14.00	14.10	
е	0.50 BASIC			
L	0.50 0.60 0.70			
Ø	0°	3°	5°	
R	0.08	*	0.20	
N	56			

### NOTES:

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm).
(DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982.)

2\ PIN 1 IDENTIFIER FOR STANDARD PIN OUT (DIE UP).

PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE DOWN), INK OR LASER MARK.

TO BE DETERMINED AT THE SEATING PLANE C-. THE SEATING PLANE IS DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT HORIZONTAL SURFACE.

DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15 mm PER SIDE.

DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 mm TOTAL IN EXCESS OF 6 DIMENSION AT MAX MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 mm.

THESE DIMESIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 mm AND 0.25 mm FROM THE LEAD TIP.

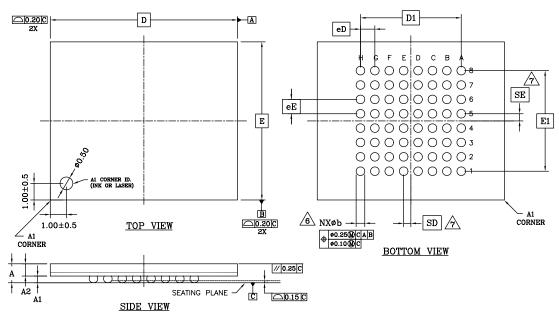
8. LEAD COPLANARITY SHALL BE WITHIN 0.10 mm AS MEASURED FROM THE SEATING PLANE.

9 DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.

3160\38.10A



# LAA064—64-Ball Fortified Ball Grid Array (FBGA)



PACKAGE	LAA 064			
JEDEC	N/A			
	13.0	OX11.00	mm	
SYMBOL	MIN.	ном.	MAX.	NOTE
Α	_	_	1.40	PROFILE HEIGHT
A1	0.40	-	_	STANDOFF
A2	0.60	_	_	BODY THICKNESS
D	13	5.00 BS	c.	BODY SIZE
E	11	.00 BS	c.	BODY SIZE
D1	7	.00 BS	Э.	MATRIX FOOTPRINT
E1	7.00 BSC.		c.	MATRIX FOOTPRINT
MD	8			MATRIX SIZE D DIRECTION
ME		8		MATRIX SIZE E DIRECTION
N		64		BALL COUNT
øb	0.50	0.50 0.60 0.70		BALL DIAMETER
eD	1.00 BSC.			BALL PITCH - D DIRECTION
eЕ	1.00 BSC.		c.	BALL PITCH - E DIRECTION
SD/SE	0.50 BSC.		С.	SOLDER BALL PLACEMENT
	A1-A8, K1-K8			DEPOPULATED SOLDER BALLS

### NOTES:

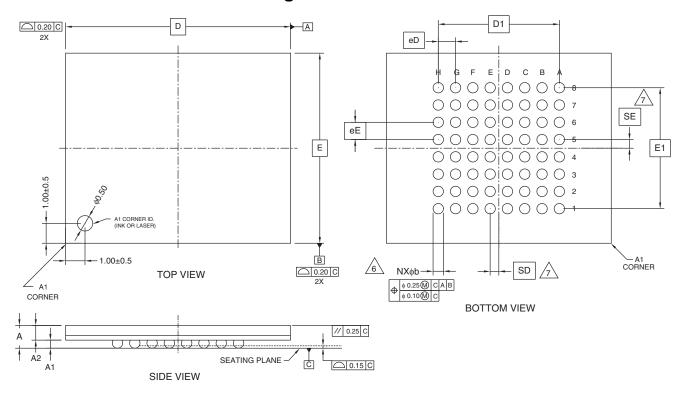
- 1. DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994
- 2. ALL DIMENSIONS ARE IN MILLIMETERS
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010 (EXCEPT AS NOTED).
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH .
- 5. SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION. SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE IN THE "E" DIRECTION. N IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- bull diameter in a plane parallel to datum "c".
- ightharpoonup 2 so and se are measured with respect to datums a and b and define the position of the center solder ball in the outer row.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = 0.000. WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = 0.2

- 8. "X" IN THE PACKAGE VARIATIONS DENOTES PART IS UNDER QUALIFICATION.
- 9. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.



# LAC064—64-Pin I8 x I2 mm Package



PACKAGE	LAC 064			
JEDEC	N/A			
	18.00 mm x 12.00 mm PACKAGE			
SYMBOL	MIN	NOM	MAX	NOTE
Α			1.40	PROFILE HEIGHT
A1	0.40			STANDOFF
A2	0.60			BODY THICKNESS
D		18.00 BSC.		BODY SIZE
Е		12.00 BSC.		BODY SIZE
D1	7.00 BSC.			MATRIX FOOTPRINT
E1	7.00 BSC.			MATRIX FOOTPRINT
MD	8			MATRIX SIZE D DIRECTION
ME	8			MATRIX SIZE E DIRECTION
N		64		BALL COUNT
φb	0.50 0.60 0.70		0.70	BALL DIAMETER
eD	1.00 BSC.			BALL PITCH - D DIRECTION
eЕ	1.00 BSC.			BALL PITCH - E DIRECTION
SD / SE	0.50 BSC.			SOLDER BALL PLACEMENT
	NONE			DEPOPULATED SOLDER BALLS

### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- BALL POSITION DESIGNATION PER JESD 95-1, SPP-010 (EXCEPT AS NOTED).
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL ROW MATRIX SIZE IN THE "D" DIRECTION.

SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE IN THE "E" DIRECTION.

N IS THE TOTAL NUMBER OF SOLDER BALLS.



6 DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.



SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW PARALLEL TO THE D OR E DIMENSION, RESPECTIVELY, SD OR SE = 0.000.

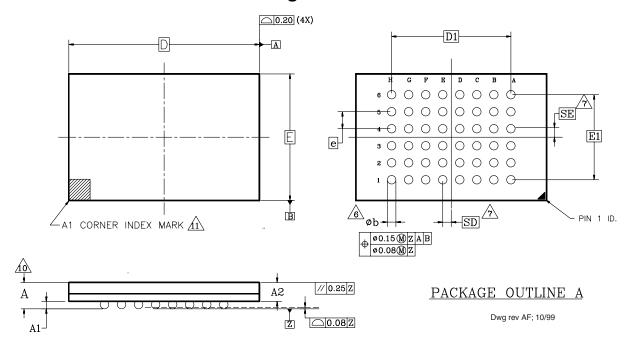
WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = e/2

- "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.

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# FBA048—48-Pin 6.15 x 8.15 mm Package



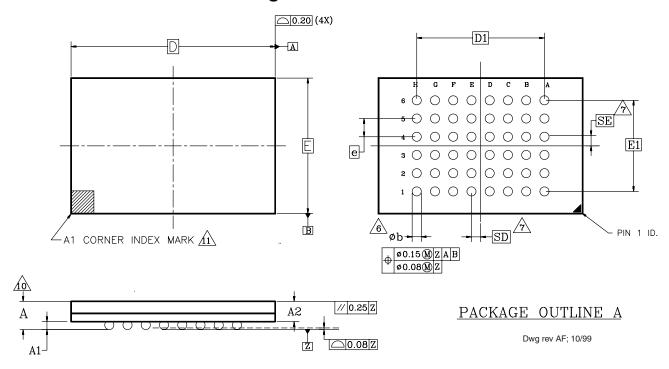
PACKAGE	xFBA 048			
JEDEC	N/A			
		nmx8.15 ACKAGE		
SYMBOL	MIN	МОМ	MAX	NOTE
Α	_	_	1.20	OVERALL THICKNESS
A1	0.20	ı	ı	BALL HEIGHT
A2	0.84	-	0.94	BODY THICKNESS
D	8	.15 BS	C	BODY SIZE
E	6.15 BSC			BODY SIZE
D1	5.60 BSC			BALL FOOTPRINT
E1	4.00 BSC			BALL FOOTPRINT
MD	8			ROW MATRIX SIZE D DIRECTION
ME	6			ROW MATRIX SIZE E DIRECTION
N	48			TOTAL BALL COUNT
b	0.25	0.30	0.35	BALL DIAMETER
е	0.80 BSC			BALL PITCH
SD/SE	0.40 BSC			SOLDER BALL PLACEMENT

### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL ROW MATRIX SIZE IN THE "D"
  DIRECTION. SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE
  IN THE "E" DIRECTION. N IS THE MAXIMUM NUMBER OF SOLDER
  BALLS FOR MATRIX SIZE MD x ME.
- 6 DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM Z.
  - SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW. WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW PARALLEL TO THE D OR E DIMENSION, RESPECTIVELY, SD OR SE = 0.000 WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = e/2
- "X" IN THE PACKAGE VARIATIONS DENOTES PART IS UNDER QUALIFICATION.
- 9. "+" IN THE PACKAGE DRAWING INDICATE THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- 10\ FOR PACKAGE THICKNESS A IS THE CONTROLING DIMENSION.
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, INK MARK, METALLIZED MARKINGS INDENTION OR OTHER MEANS.



# FBC048—48-Pin 8 x 9 mm Package



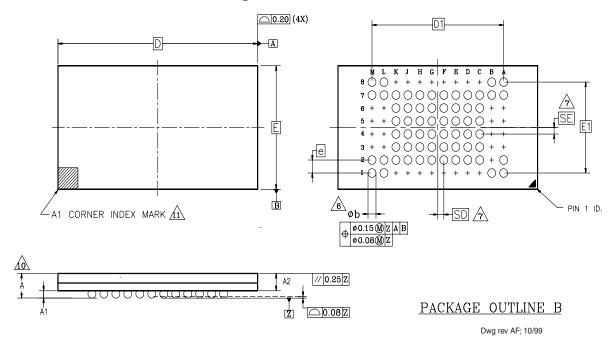
PACKAGE	FBC 048			
JEDEC	N/A			
		nmx9.00 PACKAGE	)mm	
SYMBOL	MIN	NOM	MAX	NOTE
Α	_	-	1.20	OVERALL THICKNESS
A1	0.20	1	1	BALL HEIGHT
A2	0.84	-	0.94	BODY THICKNESS
D	9	.00 BS	С	BODY SIZE
Ε	8	.00 BS	С	BODY SIZE
D1	5	.60 BS	С	BALL FOOTPRINT
E1	4.00 BSC			BALL FOOTPRINT
MD	8			ROW MATRIX SIZE D DIRECTION
ME	6			ROW MATRIX SIZE E DIRECTION
N	48			TOTAL BALL COUNT
b	0.25	0.30	0.35	BALL DIAMETER
е	0.80 BSC			BALL PITCH
SD/SE	0.40 BSC			SOLDER BALL PLACEMENT

### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL ROW MATRIX SIZE IN THE "D"
  DIRECTION. SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE
  IN THE "E" DIRECTION. N IS THE MAXIMUM NUMBER OF SOLDER
  BALLS FOR MATRIX SIZE MD x ME.
- DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM Z.
- SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW. WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW PARALLEL TO THE D OR E DIMENSION, RESPECTIVELY, SD OR SE = 0.000 WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = e/2
- 8. "X" IN THE PACKAGE VARIATIONS DENOTES PART IS UNDER QUALIFICATION.
- "+" IN THE PACKAGE DRAWING INDICATE THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- FOR PACKAGE THICKNESS A IS THE CONTROLING DIMENSION.
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, INK MARK, METALLIZED MARKINGS INDENTION OR OTHER MEANS.



# FBE063—63-Pin I2 x II mm Package



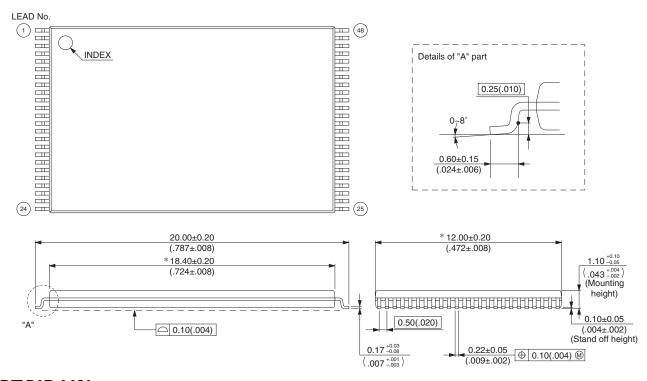
PACKAGE	xFBE 063			
JEDEC	N/A			
		nmx11. PACKAG		
SYMBOL	MIN	NOM	MAX	NOTE
Α	-	ı	1.20	OVERALL THICKNESS
A1	0.20	-	-	BALL HEIGHT
A2	0.84	ı	0.94	BODY THICKNESS
D	12.	.00 BS	С	BODY SIZE
E	11	.00 BS	С	BODY SIZE
D1	8	.80 BS	С	BALL FOOTPRINT
E1	5.60 BSC			BALL FOOTPRINT
MD	12			ROW MATRIX SIZE D DIRECTION
ME	8			ROW MATRIX SIZE E DIRECTION
N		63		TOTAL BALL COUNT
b	0.25	0.30	0.35	BALL DIAMETER
е	0.80 BSC			BALL PITCH
SD/SE	0.40 BSC			SOLDER BALL PLACEMENT
	A3-A6,B2-B6 L3-L6, M3-M6 C1-K1,C8-K8			DEPOPULATED SOLDER BALLS

### NOTES:

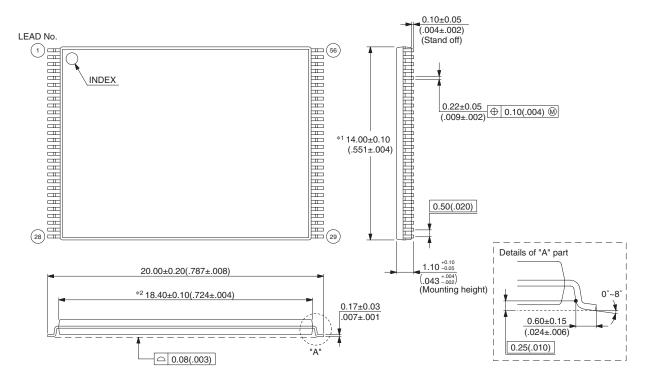
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010.
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL ROW MATRIX SIZE IN THE "D"
  DIRECTION. SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE
  IN THE "E" DIRECTION. N IS THE MAXIMUM NUMBER OF SOLDER
  BALLS FOR MATRIX SIZE MD x ME.
- 6 DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM Z.
- TO SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW. WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW PARALLEL TO THE D OR E DIMENSION, RESPECTIVELY, SD OR SE = 0.000 WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = e/2
- "X" IN THE PACKAGE VARIATIONS DENOTES PART IS UNDER QUALIFICATION.
- "+" IN THE PACKAGE DRAWING INDICATE THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- 10 for package thickness a is the controling dimension.
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, INK MARK, METALLIZED MARKINGS INDENTION OR OTHER MEANS.



### FPT-48P-MI9



### FPT-56P-M0I





# **Revision Summary**

# Revision A (January 29, 2004)

Initial Release.

# Revision AI (February 23, 2004)

### **Connection Diagrams**

Removed 80-ball Fine-pitch BGA pinout.

### **Ordering Information**

Added additional packing type.

Removed frame description from package material set.

Updated valid combinations to reflect the addition of new package type.

Added marking descriptions to all valid combination tables.

# **Word Program Command Sequence and Unlock Bypass Command Sequence**

Added these sections.

# Figure 3, Write Buffer Programming Operation, Figure 4, Program Operation

Updated figure.

# Table 34, "Command Definitions( x16 Mode, BYTE# = $V_{IH}$ )," on page 69

Updated table.

Added note 19.

# Table 35, "Command Definitions (x8 Mode, BYTE# = $V_{IL}$ )," on page 70

Updated table.

Added note 17.

### Figure 7, Data# Polling Algorithm

Updated figure.

## Erase and Program Operations and Alternate CE# Controlled Erase and Program Operations

Updated T<sub>WHWHI</sub> description

Added Note 4.

### Program Operation Timings, Chip/Sector Erase Operation Timings, Toggle Bit Timings (During Embedded Algorithms), Alternate CE# Controlled Write (Erase/ Program) Operation Timings figures

Updated figures.

### **Physical Dimensions**

Removed BGA-63P-M02 and BGA-80P-M01. Added the TS040 package



# Revision A2 (February 25, 2004)

### **Connection Diagrams**

Removed the 40-pin reverse TSOP diagram.

Updated the 48-pin standard TSOP diagram.

Removed the 48-pin reverse TSOP diagram.

Removed the 56-pin reverse TSOP diagram.

### **Ordering Information**

Removed all references to package type R.

### Autoselect Codes, (High Voltage Method)

Updated the R3, R4 column replacing -04 and -03 designators with -R4 and -R3 respectively.

### **Word Program Command Sequence**

Included statements documenting word programming support for backward compatibility with existing Flash drivers.

### **Physical Dimensions**

Removed the BGA-80P-M02 diagram.

# Revision A3 (February 26, 2004)

### **Distinctive Characteristics**

Corrected typo in the Flexible Sector Architecture section.

# Revision A4 (March 24, 2004)

### **CMOS Compatible**

Removed V<sub>CC</sub> from Max for V<sub>OL</sub>.

### Erase and Program Operations-S29GL256M only

Corrected unit typos.

### **Erase and Program Operations-S29GL128M only**

Corrected the minimum Data Setup Time.

Alternate CE# Controlled Erase and Program Operations-S29GL128M

Corrected the minimum CE# Pulse width.

TSOP Pin and BGA Package Capacitance: Pkg types TB, TC, BB, BC

Added C<sub>IN3</sub>

### **Connection Diagrams**

40-pin standard TSOP: Corrected pin 30 to be V<sub>IO</sub>.

48-pin standard TSOP: Added superscripts to designators for pin 9, 13, 14, 15 and 47. Changed pin 13 to A21. Added two notes below illustration.

56-pin standard TSOP: Added superscripts to designators for pin 1, 2 and 12. Changed pin 56 to NC. Added three notes below illustration.

64-ball Fortified BGA: Corrected ball D8 to be  $V_{IO}$ . Added superscripts to designators for ball D8, F7, and F1. Added two notes below illustration.

63-ball Fine-pitch BGA: Added superscript to designator for Ball H7. Added one note below illustration. Added connection diagrams for S29GL064M (model R0) and S29GL032M (model R0).

### Pin Description

Added V<sub>IO</sub> description.

### Logic Symbols

Added V<sub>IO</sub> on all models except R3 and R4.

### **Figure 3 Write Buffer Programming Operation**

Corrected the DQ locations and added callouts to notes one through three.



Corrected test conditions for I<sub>CC6</sub>.

# Revision A5 (April 30, 2004)

### Ordering Information - S29GL032M

Added R5 and R6 model numbers to the breakout table.

Updated the Valid Combinations for BGA packages table to reflect model numbers R5 and R6.

### Ordering Information - S29GL064M

Revised R8 and R9 model numbers on the breakout table.

Updated the Valid Combinations for TSOP packages table.

### Ordering Information - \$29GL0128M

Added R8 and R9 model numbers to the breakout table.

Revised the Package Material Set options on the breakout table.

Updated the Valid Combinations for TSOP packages table.

### Ordering Information - S29GL256M

Revised the Package Material Set options on the breakout table.

### Connection Diagrams (56-Pin TSOP)

Added a callout to Note 3 for pin 15.

### **Device Geometry Definition table**

Revised the data and description information for addresses: 28h/50h and 29h/52h.

### **Primary Vendor Specific Extended Query table**

Revised the data and description information for addresses: 45h/8Ah (x16/x8)

Revised the data information for addresses: 4Ch/98h (x16/x8)

### Erase and Programming Performance table

Revised notes 1 and 2 below the table.

# Revision B0 (May 24, 2004)

### Global

Converted to full datasheet status.

### Figure 17, Autoselect Codes, (High Voltage Method)

Corrected typos in description.

Added values for R5, R6, R7 description for cycle 1-3.

Added R8 and R9 to Model Number.

# Revision BI (August 2, 2004)

### Ordering Information-S29GL032M

Added the following temperature range: " $C = Commercial (0^{\circ}C to +70^{\circ}C)'$ .

Commercial temperature range options added for 90ns speeds.

### **Global Change**

S29GL032M, S29GL064M, S29GL128M, S29GL236M ordering options pages:

Updated note 3 with the following "...TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.

# Revision B2 (September 8, 2004)

### Connection Diagram - 64-ball Fortified BGA

Modified note 4.



### Logic Symbol-S29GL032M (Models R3, R4)

Added models R5 and R6 to the logic symbol.

### Logic Symbol-S29GL064M (Models R1, R2)

Added models R8 & R9 to the logic symbol.

### S29GL032M Valid Combinations

Corrected ordering part numbers for LAA064 packages.

### **Physical Dimensions**

Renamed the BGA-48P-M20 package as the FBG048 package.

### Ordering Information

Added footnotes to indicate TSOP Pb-free leadframe plating.

# Revision B3 (October 9, 2004)

### General

Updated all references to Figures, Tables, and Headings to reflect page number (active link)

Updated tables 20, 21, and 22

Updated tables 24, 25, and 26

### S29GL064M Valid combination

Corrected ordering part numbers for TS056 packages

## S29GL032M Sector Protection/Uprotection Address Tables

Corrected table titles

S29GL064M Sector Protection/Uprotection Address Tables

Corrected table titles

### **Primary Vendor-Specific Extended Query**

Corrected CFI data at address 48h/90h to be 0001h

### **DC Characteristics**

Updated note 2

### Figure 15, Reset Timing

Added t<sub>RH</sub>

# Revision B4 (January 10, 2005)

### **Secured Sector Flash Memory Region**

Updated Secured Silicon Sector address table with addresses in x8-mode

### DC Characteristics, CMOS Compatible

Corrected WP#/ACC input load current footnote

### **Document**

Updated cross-references and format.

### **Valid Combination Tables**

Added notes to the 128 Mb and 256 Mb combination tables.

# Revision B5 (December I3, 2005)

Added Supersession text.

Corrected typos on connection diagrams and in CFI table.



## Revision B6 (October 10, 2006)

### Global

Deleted FBG048 package from S29GL032M device. Added "retired product" status text to cover page, and first page and Ordering Information sections of data sheet.

# Revision B7 (January 22, 2007)

### **AC Characteristics**

Erase/Program Operations table, all devices: Changed t<sub>BUSY</sub> to a maximum specification.

# Revision B8 (February 7, 2007)

### Global

Updated retired product status text.

### Colophon

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